# Solidification orientation relationships in Al and Mg alloys 

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#### Abstract

This thesis explores solidification orientation relationships (ORs) in intermetallic compounds (IMCs) and Al and Mg alloys.


In the $\mathrm{Al}_{3} \mathrm{Ti}-\mathrm{TiB}_{2}$ system, it is found that the nucleation of $\mathrm{Al}_{3} \mathrm{Ti}$ on $\mathrm{TiB}_{2}$ and the pushing and engulfment of $\mathrm{TiB}_{2}$ particles by growing $\mathrm{Al}_{3} \mathrm{Ti}$ crystals both form reproducible ORs during solidification. The nucleation OR is identified by solidifying multiple small $\mathrm{Al}_{3} \mathrm{Ti}$ crystals on one large (0001) facet of $\mathrm{TiB}_{2}$. Pushing and engulfment ORs are investigated by statistical analysis of EBSD measurements, DFT calculations of interface energies, and imaging of $\mathrm{TiB}_{2}$ particles being pushed and engulfed by $\mathrm{Al}_{3} \mathrm{Ti}$ facets. It is shown that the lowest energy OR is formed by nucleation as well as by pushing/engulfment. The higher energy ORs, formed by pushing and engulfment, correspond to local interfacial energy minima and can be explained by rotation of $\mathrm{TiB}_{2}$ particles on $\mathrm{Al}_{3} \mathrm{Ti}$ facets during pushing.

ORs formed by cyclic twinning of low symmetry IMCs is studied in $\mathrm{Al}_{3} \mathrm{Ti}_{\mathrm{I}}, \mathrm{Ag}_{3} \mathrm{Sn}, \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$. It is argued that deeper undercooling induced by higher cooling rate favours the nucleation of metastable phases and/or the formation of short-range order with high symmetry in the melt, which then nucleated/transformed into stable phases with all orientation variants to the higher-symmetry parent phases.

This thesis then applies the new understanding developed in the previous chapters to explore the formation mechanism for the above-random proportion of special grain boundaries in FCC-Al and HCP-Mg after equiaxed solidification. Two main mechanisms are examined and, by combining statistical EBSD analysis and DFT calculations, it is found that the measured preferred grain boundaries with twin ORs correspond to local interfacial energy minima and, for the alloy systems studied here, it is likely due to the rotation and movement between neighbouring grains during solidification instead of nucleation from icosahedral quasicrystals and/or icosahedral short-range order.

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## Declaration of originality

I, Yi Cui, hereby declare that this thesis and associated research are my own work and that all sources I have used or quoted have been indicated and acknowledged by means of complete referencing.

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## Chapter 1 Introduction

### 1.1 Background and industrial motivation

Aluminium and magnesium are two of the lightest structural metals with large abundance in the Earth's crust, being the third most abundant element for aluminium (8.3\%) and seventh for magnesium (2.4\%) [1]. Aluminium alloys are widely used in aerospace, automotive, and construction industries due to their low density, low price, high corrosion resistance and high castability and formability, while magnesium alloys are mainly used as cast alloys for automotive components because of its light weight, excellent machinability and good strength-to-weight ratio. However, compared to Al alloys, low-cost Mg alloys are restricted by a number of limitations including low tensile properties (strength and ductility) and poor workability. High strength Mg alloys exist but are currently confined to military and aerospace applications due to their high cost.

To improve the processability and mechanical properties of Al and Mg products, grain refinement has become one of the most important techniques in the past century [2-5]. Whilst effective grain refiners are available for many Al alloys (e.g. Al-Ti-B, as shown in Figure 1.1 [6]) and Mg alloys that do not contain Al (e.g. Zr [7]), there remain various alloys that cannot be grain refined effectively on an industrial scale and, for these, new understanding of the fundamentals of heterogeneous nucleation and grain refinement are required. Alloy systems that would benefit from such an improved understanding include Al-Si-based [8-10] and Mg-Al-based [11, 12] alloys that make up a majority percentage of shape cast light alloys.

Moreover, new approaches to grain refinement that do not require the addition of hard embrittling compounds (e.g. $\mathrm{TiB}_{2}$ ) would be welcome in industries requiring the highest performance (e.g. the aerospace industry). Similarly, industries using rolled or extruded Al or Mg alloys for aesthetic parts (e.g. smartphone and laptop covers) would prefer not to use hard $\mathrm{TiB}_{2}$ particles (or similar) which can give a poor surface finish.


Figure 1.1 Microstructure of (a) commercial purity AI and (b) commercial purity AI grain refined by 0.2 wt.\% Al-5Ti-1B master alloy. From Ref.[6]

Controlling the morphology of primary intermetallic compounds (IMCs) in recycled light alloys is another approach to improve the mechanical properties. A key reason why recycled Al alloys are not used more widely is the presence of coarse brittle IMCs due to impurity elements such as Fe [13-15]. It is not economical to reduce the impurity level [16], so there is a need to manipulate the size and shape of these IMCs to improve the tensile ductility and fatigue life of final products [17-19]. Figure 1.2 overviews some examples: Al-7Si- 0.4 Mg (wt.\%) contaminated with $0.7 \mathrm{wt} \% \mathrm{Fe}$ solidifies to contain large brittle $\beta-\mathrm{Al}_{5} \mathrm{SiFe}$ plates in (a) [20]. With the dilute addition of Mn , these become less embrittling $\alpha-\mathrm{Al}_{15}\left(\mathrm{Mn}, \mathrm{Fe}_{3}\right)_{3} \mathrm{Si}_{2} \mathrm{IMCs}$ in (b) [21], which significantly improves fatigue life. This is a low-cost approach manipulating phase equilibria and phase transformations during solidification. An alternative approach is to break-up large brittle IMCs by post-solidification deformation processing. In (c) and (e), $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ and $\mathrm{Al}_{13} \mathrm{Cr}_{2}$ (also known as $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ ) respectively, can be made much smaller by hot extrusion in (c) and (f) [22], although this is not applicable to shape cast parts.


Figure 1.2 Microstructure of sand cast (a) Al-7Si-0.4Mg-0.7Fe [20] and (b) Al-9Si-1Fe-0.5Mn [21], cast (c) Al-11Fe and (e) Al-7Fe-4Cr, and hot-extruded (d) Al-11Fe and (f) Al-7Fe-4Cr [22].

### 1.2 Research challenges

There is intensive ongoing research into the grain refinement of alloys by inoculant additions that contain growth restricting solute and numerous heterogeneous nucleant particles. Often, the orientation relationship formed by heterogeneous nucleation and its disregistry are used as a measure of the potency of particles in a grain refiner. However, there can be more than one OR formed and multiple mechanisms can generate ORs during solidification so it is often difficult to assign each orientation relationship to a formation mechanism, and it can be highly challenging to identify the nucleating particle with certainty. Therefore, there is a need to develop new experimental approaches to link ORs to their formation mechanism during solidification, and understand how ORs form between inoculant particles and the matrix.

Research has indicated that FCC alloys may be grain refined by adding small additions that encourage icosahedral short-range order in the melt and/or cause icosahedral quasicrystals (iQCs) to form first during solidification and that the FCC phase then grows from each iQC into ten FCC orientations. Kurtuldu et al. [23-28] reported in Al-Zn-Cr and Au-Ag-Cu-Ir FCC alloys an abnormal fraction of twin, or near-twin, grain boundaries and 5-fold symmetry among neighbouring grains, and significant grain refinement. They attributed this to Cr and $\operatorname{Ir}$ additions promoting icosahedral short-range order in the melt and/or the formation of iQCs prior to FCC nucleation followed by the growth of ten FCC orientations from each iQC due to multiple variants of the OR between these phases. This has shown some exciting promise as it is a new mechanism causing grain refinement without the need for nucleant particles. However, few studies have been performed on this topic and it is unclear if this mechanism can be used to design alloys to harness this phenomenon.

The morphology of primary IMCs is known to strongly affect the extent to which they degrade mechanical properties (tensile ductility and fatigue life) of Al and Mg alloys. However, there is limited understanding of how the morphology of primary IMCs can be manipulated during solidification. Research has suggested that twinning may enable a route to morphology control, but this has not been explored in detail. Recently, Feng et al. [29] studied solidification twinning in primary $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ and
showed that the formation of parallel twin platelets perpendicular to the growth direction promoted thickening of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ and resulted in crystals of a much lower aspect ratio. Such a morphology is desirable as it is less deleterious to mechanical properties. Similarly, Zeng et al. [30, 31] have studied how solidification twinning affects the $\mathrm{Al}_{8} \mathrm{Mn}_{5}$ growth morphology in magnesium alloys. They found that $\mathrm{Al}_{8} \mathrm{Mn}_{5}$ (rhombohedral) grows as equiaxed particles with a cyclic twin forming a combined cubic symmetry due to nucleation with four variants on a small B2-Al(Mn,Fe) (cubic) particle. In contrast, when $\mathrm{Al}_{8} \mathrm{Mn}_{5}$ grows as a single crystal, it forms long hexagonal rods which are likely to degrade tensile ductility and fatigue life. To optimise the potential benefits of solidification twinning in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ and other IMCs in Al and Mg casting alloys, there is now a need to build the understanding of the factors affecting solidification twinning in a range of transition metal aluminides.

### 1.3 Aims

The overall aim of this thesis is to build a deeper understanding of the mechanisms that lead to solidification ORs, solidification twinning and equiaxed solidification textures, using Al and Mg alloys as examples.

To address the research challenges above, a combination of (i) experiments centred around electron backscatter diffraction, and (ii) calculations using density functional theory (DFT), are applied with four specific objectives:

1) To develop experimental approaches that allow ORs formed between inoculant particles and the matrix to be linked with their formation mechanisms.
2) To build the understanding of solidification twinning in IMCs and its influence on growth morphology.
3) To investigate twinning induced by the iQC-mediated nucleation mechanism in FCC alloys by comparing ORs and textures in $\mathrm{Al}(\mathrm{FCC})$ and $\mathrm{Mg}(\mathrm{HCP})$ alloys after equiaxed solidification.
4) To explore the origins of crystallographic texture formed by equiaxed solidification.

### 1.4 Thesis structure

A unifying thread through this thesis is the study of orientation relationships formed during solidification due to the nucleation, growth and rotation of crystals, and the statistics of the interfaces formed. The structure of the thesis is as follows:

Chapter 2 is a broad review of the previous literature including nucleation theory, pushing and engulfment theory, and quasicrystal crystallography. It also reviews the published research work about quasicrystal-induced grain refinement and grain boundary formation. Finally, a brief theoretical background for density functional theory (DFT) calculations is given.

In Chapter 3, one of the most common Al grain refinement systems ( $\mathrm{Al}-\mathrm{Ti}-\mathrm{B}$ ) is used to explore the formation of ORs between $\mathrm{Al}_{3} \mathrm{Ti}$ and small $\mathrm{TiB}_{2}$ platelets. Methods are presented to link ORs to their formation mechanism by combining electron backscatter diffraction (EBSD), droplet nucleation experiments and interface energy calculations.

Chapter 4 investigates solidification twinning in transition metal aluminides with a focus on how IMC nucleation and growth can be manipulated by controlling the cooling rate (undercooling). Two types of IMCs are studied: (i) $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ which are monoclinic approximants of icosahedral and decagonal quasicrystals respectively; and (ii) $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{Ag}_{3} \mathrm{Sn}$ are tetragonal and orthorhombic superlattices derived from the FCC and HCP structures. In all four IMCs, the conditions under which twinning occurs with the symmetry of the higher symmetry parent structure (icosahedral, decagonal cubic and hexagonal, respectively) is studied.

In Chapter 5, the non-random misorientation distribution and crystallographic texture of Al and Mg alloys after equiaxed solidification is investigated. A high fraction of twin boundaries between equiaxed grains are found in cast $\mathrm{Al}\left(\mathrm{Al}-6 \mathrm{Cu}+\mathrm{TiB}_{2}, \mathrm{Al}-15 \mathrm{Cu}\right.$ and $\mathrm{Al}-20 \mathrm{Zn}$, wt\%) and Mg ( $\mathrm{Mg}-9 \mathrm{Al}-$ $\left.0.7 \mathrm{Zn}+\mathrm{FeCl}_{3}, \mathrm{Mg}-9 \mathrm{Zn}-0.7 \mathrm{Zn}+\mathrm{Al}_{4} \mathrm{C}_{3}, \mathrm{wt} \%\right)$ alloys with and without grain refiner additions. Considering the two mechanisms of forming solidification ORs in Chapters 3 and 4, (i) the interaction and movement between two contacting grains and/or (ii) nucleation on atomic clusters with icosahedral short-range order in the melt, could both produce the observed twin boundaries. By detailed grain boundary analysis and interface calculations, the mechanisms that form the high fraction of twin boundaries and equiaxed solidification texture in both Al and Mg alloys are investigated and discussed.

Chapter 6 summarises the main findings of the thesis and provides conclusions for this work. The thesis ends with suggestions for future research.

## Chapter 2 Literature review

### 2.1 Nucleation theories

### 2.1.1 Homogeneous nucleation theory

In classical homogeneous nucleation theory [32-36], a pure homogeneous liquid is considered. It is possible for atoms to form small clusters with a crystalline structure due to random fluctuations. Assuming the formation of a spherical cluster with radius $R$, the Gibbs free energy change of the system can be written as:

$$
\Delta G=\Delta G_{V}+\Delta G_{S}=\frac{4}{3} \pi R^{3} \cdot\left(G_{v}^{S}-G_{v}^{l}\right)+4 \pi R^{2} \cdot \sigma=-\frac{4}{3} \pi R^{3} \cdot \Delta G_{v}+4 \pi R^{2} \cdot \sigma \quad \text { Equation } 2.1
$$ Where $G_{v}^{s}$ and $G_{v}^{s}$ are the Gibbs free energy of the solid and liquid per unit volume, respectively. $\Delta G_{v}$ is the Gibbs free energy change per unit volume and it is defined as $\left(G_{v}^{l}-G_{v}^{S}\right)$, and $\sigma$ is the solid/liquid interfacial energy induced by the formation of the solid cluster. For a small undercooling, $\Delta G_{v}$ can be expressed as:

$$
\Delta G_{v}=\Delta H_{v}-T \Delta s_{v} \cong L_{v}-T \frac{L_{v}}{T_{f}}=L_{v} \frac{\Delta T}{T_{f}}
$$

Equation 2.2

Where $\Delta H_{v}$ is the enthalpy change per unit volume, $\Delta s_{v}$ is the entropy change per unit volume, $T_{f}$ is the melting point of the melt and $\Delta T$ is the undercooling defined as: $\Delta T=T_{f}-T . L_{v}$ is the latent heat of fusion per unit volume which can also be expressed in terms of $\Delta s_{v}: L_{v}=\Delta s_{v} T_{f}$. Thus, Eq. 2.2 can be expressed as:

$$
\Delta G_{v}=\Delta s_{v} \Delta T
$$

Equation 2.3
Substituting Eq. 2.3 into Eq. 2.1 gives:

$$
\Delta G=\Delta G_{V}+\Delta G_{S}=-\frac{4}{3} \pi R^{3} \cdot \Delta s_{v} \Delta T+4 \pi R^{2} \cdot \sigma
$$

Equation 2.4
When $\Delta T<0$, i.e., $T>T_{f}$, both terms on the right hand side of Eq. 2.4 are positive, which means it is energetically unfavourable to form solid clusters with crystalline structure and they will melt back instead of growing. Oppositely, when $\Delta T>0$, i.e., $T<T_{f}$, the first term on the right hand side is negative which corresponds to the energy decrease by solidification of the undercooled liquid. The
second term is positive and corresponds to the energy penalty for the formation of the solid-liquid interface. In this case, the energy change of the system for pure Al is plotted in Figure 2.1. The thermodynamic values for Al are listed in Table 2.1.


Figure 2.1 Surface energy, bulk energy and total free energy change of Al cluster as a function of its radius for homogeneous nucleation. The undercooling is set to be $5^{\circ} \mathrm{C}$. After Ref. [37]

Table 2.1 Thermodynamic properties for Al [37]

| Parameters | Symbol | Value | Units |
| :--- | :--- | :--- | :--- |
| Melting point of AI | $T_{f}$ | 933 | K |
| Solid-liquid interfacial energy | $\sigma$ | 0.1 | $\mathrm{~J} / \mathrm{m}^{2}$ |
| Entropy change per unit volume | $\Delta s_{v}$ | $1.02 \times 10^{6}$ | $\mathrm{~J} /\left(\mathrm{m}^{3} \cdot \mathrm{~K}\right)$ |
| Molar volume of AI | $V^{m}$ | $1.138 \times 10^{-5}$ | $\mathrm{~m}^{3} / \mathrm{mol}$ |
| Atomic vibration frequency at 933K | $v_{0}$ | $10^{13}$ | $\mathrm{~s}^{-1}$ |
| Probability of capturing an atom at the surface | $p_{c}$ | 1 |  |
| Boltzmann constant | $k_{B}$ | $1.38 \times 10^{-23}$ | $\mathrm{~J} / \mathrm{K}$ |
| Avogadro constant | $N_{A}$ | $6.02 \times 10^{23}$ | mol |

In Figure 2.1, the surface energy penalty exceeds the volumetric energy release for small $R$, whereas the energy decrease from the volumetric term dominates at large $R$, creating a maximum value in $\Delta G$ which is called the homogeneous nucleation barrier $\Delta G_{n}^{h o m o}$. The radius $R_{c}$ corresponding to $\Delta G_{n}^{\text {homo }}$ can be determined by differentiating Eq. 2.4 with respect to $R$ and finding the turning point. The result is:

$$
\begin{equation*}
R_{c}=\frac{2 \sigma}{\Delta s_{v} \Delta T} \tag{Equation 2.5}
\end{equation*}
$$

And the homogeneous nucleation barrier can be calculated by:

$$
\Delta G_{n}^{\text {homo }}=\frac{16 \pi}{3} \frac{\sigma^{3}}{\Delta s_{v}^{2} \Delta T^{2}}
$$

It is energetically favourable for clusters with $R<R_{c}$ to melt back, and clusters with $R>R_{c}$ to keep growing. Therefore, embryos with radius $R_{c}$ are called critical nuclei.

In addition, assuming that the energy of atoms in liquid follows a Maxwell-Boltzmann distribution, the density of clusters with radius $R$ can be written as:

$$
\begin{equation*}
n(R)=n_{0} \exp \left(-\frac{\Delta G(R)}{k_{B} T}\right) \tag{Equation 2.7}
\end{equation*}
$$

$n_{0}$ is the total number of atoms per volume in the liquid and equals to $\frac{N_{A}}{V^{m}}$ where $N_{A}$ is the Avogadro constant and $V^{m}$ is the molar volume. $k_{B}$ is the Boltzmann's constant. For clusters with critical size, the number density can be calculated by setting $\Delta G(R)=\Delta G_{n}^{\text {homo }}$ in Eq. 2.7:

$$
n_{c}=n_{0} \exp \left(-\frac{\Delta G_{n}^{\text {homo }}}{k_{B} T}\right)=n_{0} \exp \left(-\frac{16 \pi}{3} \frac{\sigma^{3}}{\left(\Delta s_{v} \Delta T\right)^{2} k_{B} T}\right)
$$

Equation 2.8

A nucleus of critical size $R_{C}$ will grow if it manages to add one more atom, and the occurrence rate of this is proportional to the atomic vibration frequency $v_{0}$ and the probability of capturing an atom at the surface $p_{c}$. Therefore, the rate to form homogeneous nucleai, $I^{\text {homo }}$, is:

$$
\begin{equation*}
I^{\text {homo }}=v_{0} p_{c} n_{c}=v_{0} p_{c} n_{0} \exp \left(-\frac{16 \pi}{3} \frac{\sigma^{3}}{\left(\Delta s_{v} \Delta T\right)^{2} k_{B} T}\right) \tag{Equation 2.9}
\end{equation*}
$$

It is clear that the homogeneous nucleation rate depends strongly on temperature: on one hand an increasing undercooling lowers the nucleation barrier, $\Delta G_{n}^{\text {homo }}$, but on the other hand decreased
temperature leads to the decreasing mobility of atoms. Therefore, the two competing factors lead to a maximum nucleation rate at a certain temperature. The change of $I^{\text {homo }}$ for pure Al with respect to temperature is plotted in Figure 2.2: the homogeneous nucleation rate reaches the maximum value around 300 K with $\sim 700 \mathrm{~K}$ undercooling, which is much deeper than the measured undercooling for Al alloys. Therefore, other nucleation process happens in real situations before the homogeneous nucleation is triggered.


Figure 2.2 The homogeneous nucleation rate of $\alpha$-Al as a function of temperature.

### 2.1.2 Heterogeneous nucleation theory

In real situation, there are always some solid phases like oxide layers, impurity particles, added grain refiners and even container walls that share interfaces with liquid where heterogeneous nucleation can happen [38-40]. Assuming the critical nucleus forming on the flat existing solid surface is a spherical cap, the geometry of the heterogeneous nucleation process is shown in Figure 2.3.

Considering the equilibrium state of the surface energy [41]:

$$
\begin{equation*}
\gamma_{f l}=\gamma_{f s}+\gamma_{s l} \cos \theta \tag{Equation 2.10}
\end{equation*}
$$

Where $\gamma_{f l}$ is the interfacial energy between the foreign substrate and the liquid, $\gamma_{f s}$ is the interfacial energy between the foreign substrate and the newly formed solid, $\gamma_{s l}$ is the interfacial energy between the solid and the liquid, and $\theta$ is the contact angle (also known as wetting angle).


Figure 2.3 The nucleation of a spherical solid cap on a foreign substrate. After Ref. [41]

In this case, the Gibbs energy change of the system due to the formation of the solid spherical cap is given by:

$$
\Delta G=\Delta G_{V}+\Delta G_{S}=V_{s} \cdot\left(G_{v}^{s}-G_{v}^{l}\right)+A_{s l} \cdot \gamma_{s l}+A_{f s}\left(\gamma_{f s}-\gamma_{f l}\right) \quad \text { Equation } 2.11
$$

Where $V_{s}$ is the volume of the solid nucleus, $A_{s l}$ is the area of the newly formed solid-liquid interface, and $A_{f s}$ is the area of the interface between the solid and foreign substrate. For a spherical cap with radius $R, V_{s}, A_{s l}$ and $A_{f s}$ can be written as:

$$
\begin{gather*}
V_{s}=\frac{\pi R^{3}}{3}(2+\cos \theta)(1-\cos \theta)^{2}  \tag{Equation 2.12}\\
A_{s l}=2 \pi R^{2}(1-\cos \theta) \\
A_{f s}=\pi R^{2}\left(1-\cos ^{2} \theta\right)
\end{gather*}
$$

Equation 2.13
Equation 2.14
Substituting Eq. 2.10, Eq. 2.12, Eq. 2.13 and Eq. 2.14 into Eq. 2.11, and applying $\Delta G_{v}=\Delta s_{v} \Delta T$, the equation can be written as:

$$
\Delta G=\left(-\frac{4}{3} \pi R^{3} \cdot \Delta s_{v} \Delta T+4 \pi R^{2} \cdot \gamma_{s l}\right) f(\theta)
$$

Equation 2.15
Where $f(\theta)$ is a geometry factor given by:

$$
\begin{equation*}
f(\theta)=\frac{V_{s}}{4 \pi R^{3} / 3}=\frac{(2+\cos \theta)(1-\cos \theta)^{2}}{4} \tag{Equation 2.16}
\end{equation*}
$$

Comparing Eq. 2.15 (heterogeneous nucleation) with Eq. 2.4 (homogeneous nucleation), the Gibbs energy change appears in the same form except multiplied by the $f(\theta)$ factor in heterogeneous nucleation. The critical radius can be derived by differentiating Eq. 2.15 with respect to $R$ and setting it to zero, and yields the same result as in homogeneous nucleation:

$$
\begin{equation*}
R_{C}=\frac{2 \gamma_{s l}}{\Delta s_{v} \Delta T} \tag{Equation 2.17}
\end{equation*}
$$

And the heterogeneous nucleation energy barrier can be calculated by:

$$
\begin{equation*}
\Delta G_{n}^{\text {hetero }}=\frac{16 \pi}{3} \frac{\gamma_{s l}^{3}}{\Delta s_{v}^{2} \Delta T^{2}} f(\theta)=\Delta G_{n}^{\text {homo }} f(\theta) \tag{Equation 2.18}
\end{equation*}
$$

The range of the geometry factor $f(\theta)$ with respect to the contact angle $\theta$ is plotted in Figure 2.4. For $\theta=0^{\circ}$, the function $f(\theta)=0$, which means complete wetting of solid phase on substrate and there is no nucleation barrier in this case. For $0^{\circ}<\theta<180^{\circ}$, the function $f(\theta)$ is between 0 and 1 , indicating that the energy barrier for heterogeneous nucleation is lower than homogeneous nucleation. With wetting angle increasing, the compatibility between the solid phase and the substrate decreases. For non-wetting conditions $\left(\theta=180^{\circ}\right): f(\theta)=1$, the energy changes are the
same for heterogeneous and homogeneous nucleation because in this situation solid nuclei form from liquid instead of substrate.


Figure 2.4 The range of $f(\theta)$ with respect to the wetting angle

Considering the heterogeneous nucleation rate, with the knowledge of the free energy barrier, Eq. 2.9 can be rewritten as:

$$
\begin{equation*}
I^{\text {hetero }}=v_{0} p_{c} n_{p} \exp \left(-\frac{16 \pi}{3} \frac{\gamma_{s l}^{3}}{\left(\Delta s_{v} \Delta T\right)^{2} k_{B} T} f(\theta)\right) \tag{Equation 2.19}
\end{equation*}
$$

Where $n_{p}$ is the density of inoculants in the melt for heterogeneous nucleation. Compared to homogeneous nucleation, we expect $n_{p} \ll n_{0}$. Now assuming $n_{p}=10^{9} \mathrm{~m}^{-3}$ with $v_{0}$ and $p_{c}$ being the same as in homogeneous nucleation, the change of heterogeneous nucleation rate with respect to temperature and wetting angle in Al melt is plotted in Figure 2.5. The nucleation rate for homogeneous nucleation is also plotted for comparison. For most metallurgical process the undercooling of melt is less than 100K, which would trigger a large amount of heterogeneous nucleation with wetting angle less than $60^{\circ}$. Therefore, even though the pre-exponential term for heterogeneous nucleation is much smaller than homogeneous nucleation, the $f(\theta)$ factor appearing in the nucleation barrier makes heterogeneous nucleation much more favourable.


Figure 2.5 The nucleation rate as a function of temperature and wetting angle for Al. After Ref. [37]

### 2.1.3 Nucleant potency

### 2.1.3.1 Lattice matching theory

The classical nucleation theory implies little about the atomic mechanism of heterogeneous nucleation. In order to examine how nucleant potency is affected by its orientation relationship with the forming solid, the lattice coherency between the substrate and the growing solid is considered in various models that quantify the disregistry. Three major approaches are discussed here: (i) the Turnbull-Vonnegut linear disregistry [42], (ii) the Bramfitt planar disregistry [43] and (iii) the ZhangKelly edge-to-edge model [44-46].

According to Turnbull and Vonnegut, the nucleant potency is in the order of the reciprocal of the disregistry $(\delta)$ between the nucleant and forming solid on their low index planes with similar atomic arrangement [42]:

$$
\delta=\Delta a_{0} / a_{0}
$$

Equation 2.20
Where $\Delta a_{0}$ is the difference between the lattice parameters for the nucleant and the forming solid on a low index plane, and $a_{0}$ is the lattice parameter for the forming solid. Through experiment, the linear disregistry model successfully explained the measured undercooling for various nucleants (nitrides and carbides) that share the same crystal structure as the forming phase ( $\delta \mathrm{Fe}$ ). But for nucleants with different atomic arrangement, the prediction from linear disregistry is not consistent with experiments. Bramfitt proposed a more accurate model to describe the lattice mismatching between the substrate and forming solid, known as planar disregistry model, by averaging the linear disregistry in the three lowest-index directions and considering the adjustment of angular difference between the matched directions [43]. The form of the planar disregistry can be written as:

$$
\delta_{(h k l)_{n}}^{(h k l)_{s}}=\frac{1}{3} \cdot \sum_{i=1}^{3} \frac{\left|\left(d_{[u v w]_{s}}^{i} \cos \theta\right)-d_{[u v w]_{n}^{i}}\right|}{d_{[u v w]_{n}}^{i}} \times 100 \%
$$

Equation 2.21

Where $(h k l)_{s}$ and $(h k l)_{n}$ are low index planes of the substrate and nucleated solid, $[u v w]_{s}$ and $[u v w]_{n}$ are low index directions in $(h k l)_{s}$ and $(h k l)_{n}, d_{[u v w]_{s}}$ and $d_{[u v w]_{n}}$ the interatomic spacing along $[u v w]_{s}$ and $[u v w]_{n}$, and $\theta$ is the angle between $[u v w]_{s}$ and $[u v w]_{n}$.

In Al casting, $\mathrm{TiB}_{2}$ is considered as a potent nucleant for $\mathrm{Al}_{3} \mathrm{Ti}$ [47-53]. Figure 2.6 plots the atomic matching between these two compounds at the interface with the orientation relationship reported in previous literature [50-52]:

$$
\{112\}_{\mathrm{Al}_{3} \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB}_{2}} \text {, with }<\overline{2} 01>_{\mathrm{Al}_{3} \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB}_{2}}
$$



Figure 2.6 Bramfitt planar lattice matching between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ at the interface

Table 2.2 lists the calculated results of the Bramfitt planar disregistry for the orientation relationship between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ in Eq. 2.22. With consideration of the linear disregistry in three directions and taking the angular difference into account, Bramfitt planar disregistry makes a better prediction than the linear disregistry model. Bramfitt used a similar argument to show that the planar disregistry gives a better prediction of nucleant potency for WC to nucleate $\delta$ Fe [43].

Table 2.2 Bramfitt planar disregistry between $\mathrm{Al}_{3}$ Ti and TiB $_{2}$ in the (112)||(0001) interface plane

| Directions | Angular difference $\theta$ | Linear disregistry $\delta_{i}$ | Planar disregistry $\delta$ |
| :---: | :---: | :---: | :---: |
| $[\overline{2} 01]_{\mathrm{Al}_{3} \mathrm{Ti}} \\|[11 \overline{2} 0]_{\mathrm{TiB}_{2}}$ | 0 | $5.03 \%$ |  |
| $[0 \overline{2} 1]_{\mathrm{Al}_{3} \mathrm{Ti}} \\|[11 \overline{2} 0]_{\mathrm{TiB}_{2}}$ | $3.6^{\circ}$ | $4.82 \%$ | $6.98 \%$ |
| $[\overline{1} 10]_{\mathrm{Al}_{3} \mathrm{Ti}} \\|[11 \overline{2} 0]_{\mathrm{TiB}_{2}}$ | $1.8^{\circ}$ | $11.10 \%$ |  |

More recently a new model has been developed by Kelly and Zhang considering the matching of close packed or nearly close packed atomic rows along the edge of the planes meeting at the interface [44]. Therefore, this model is termed the edge-to-edge matching theory. Figure 2.7 schematically plots the edge-to-edge matching and planar matching models. For plane-on-plane matching, the coherent or partially coherent interface between $A$ and $B$ are normally close packed or nearly close packed planes, while for edge-to-edge matching, the interface is the intersection plane of the matching planes containing the close packed or nearly close packed directions being the 'edges'.


Figure 2.7 Schematically illustration of the edge-to-edge matching and plane-on-plane matching. From Ref. [45]

Through the application of this matching model, not only can it make good predictions for the effectiveness of the known nucleant in Al and Mg -Al based alloys [45, 46], but also it has given an explanation on the poisoning effect of Si on $\mathrm{Al}-\mathrm{Ti}-\mathrm{B}$ grain refiners [54]. In Al-Si casting practice it has been known that excess Si solute (>2 wt.\%) poisons the potency of Al-Ti-B grain refiners. Using the edge-to-edge matching model this is likely due to the formation of a shell of $\mathrm{Ti}_{5} \mathrm{Si}_{3}$ on $\mathrm{Al}_{3} \mathrm{Ti}$, which prevents the highly potent $\mathrm{Al}_{3}$ Ti substrate from nucleating $\alpha-\mathrm{Al}$ and thus causing the poisoning of the $\mathrm{Al}-\mathrm{Ti}-\mathrm{B}$ grain refiners.

### 2.1.3.2 Free growth model

The free growth model was first proposed by Quested and Greer [55-57] which demonstrated that the potency of grain refiners is also determined by its size distribution. In this model the undercooling temperature depends on the size and geometry of the foreign particles. In classical nucleation theory an embryo could grow into stable nucleus at any temperature as if the thermal fluctuation could overcome the corresponding energy barrier. But in the free growth model, the morphology of the particles completely dictates the undercooling temperature at which the stable embryo will grow out of it. The stable grain will not form until the critical temperature is reached. Therefore foreign particles with different size and geometry will have different potency.

As shown in Figure 2.8(a), the initial growth of $\alpha-\mathrm{Al}$ on the $\{0001\}$ facet of $\mathrm{TiB}_{2}$ continuously reduces its radius of curvature until it reaches the critical hemispherical cap with minimum radius (d/2), after which the radius of curvature start to increase with further growth. According to classical nucleation theory, the undercooling required to form an embryo with radius $R$ can be calculated:

$$
\begin{equation*}
\Delta T=\frac{2 \gamma_{s l}}{\Delta s_{v} R} \tag{Equation 2.23}
\end{equation*}
$$

Therefore, for a $\mathrm{TiB}_{2}$ particle with diameter $d$, the critical undercooling above which $\alpha$-Al can grow freely is fully determined by its size and can be expressed as following:

$$
\begin{equation*}
\Delta T_{c}=\frac{4 \gamma_{s l}}{\Delta s_{v} d} \tag{Equation 2.24}
\end{equation*}
$$

Figure $2.8(\mathrm{~b})$ plots the size distribution of $\mathrm{TiB}_{2}$ particles in $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ master alloy measured by the image analysis of SEM [57]. The distribution can be well fitted to a log normal function with most TiB ${ }_{2}$ particles at small diameter side. However, as discussed above, it is the $\mathrm{TiB}_{2}$ particles with larger diameter (shaded black in Figure 2.8(b)) that correspond to lower critical undercooling and are likely to be activated during practical casting while the rest will be stifled due to recalescence.


Figure 2.8 (a) $\alpha-A l$ growth on the $\{0001\}$ facet of $\mathrm{TiB}_{2}$ particles. Thickening of the growing crystal reduces the radius of curvature of its interface with the liquid. (b) Size distribution of $\mathrm{TiB}_{2}$ particles in Al-5Ti-B master alloy determined by the image analysis of SEM. From Ref. [57]

### 2.2 Nucleation mechanism in $\mathrm{TiB}_{2}-\mathrm{Al}_{3} \mathrm{Ti}-\mathrm{Al}$ system

Grain refinement of Al alloys has been widely studied for over half a century [58-62]. One of the most commonly used grain refiners is the Al-Ti-B master alloy. Although the addition of heterogeneous nuclei to achieve significant grain refinement in this case was first proposed by Cibula in 1949 [63], the exact refinement mechanism of the Al-Ti-B grain refiners is still debated and many theories have been proposed.

### 2.2.1 Nucleant-Particle theory

The nucleant-particle theory was first postulated by Cibula who attributed the grain refinement from the master alloys to the nucleation on borides $\left(\mathrm{TiB}_{2}\right.$ and $\left.\mathrm{AlB}_{2}\right)$ [58, 63]. Normally when the Al-Ti-B master alloy is added in practice, the Ti content is at hypoperitectic level ( $<0.13 \mathrm{wt} \%$ ) and most particles in the melt are borides. Figure 2.9 plots the Al-Ti phase diagram at Al-rich side. Examination shows that some boride particles, or more commonly, boride clusters or agglomerates, can be located in the centre of $\alpha$-Al grains [64, 65], suggesting that nucleation is likely to happen on these particles. However, calculations made by the lattice matching models show that there is large lattice disregistry between the borides and $\alpha-\mathrm{Al}$ [45], and it has been observed that most borides are pushed to the grain boundaries [47, 66-68], suggesting that borides are poor nucleants. More importantly, it has been confirmed that no grain refinement is observed when there is no excess Ti in the solute [47], indicating that borides alone do not cause the grain refinement.


Figure 2.9 Al-rich side of the AI-Ti phase diagram from Thermo-Calc database TCTI2 version 2.0.

### 2.2.2 Phase-Diagram theory

Compared to $\mathrm{TiB}_{2}, \mathrm{Al}_{3} \mathrm{Ti}$ is known as a highly potent nucleant for $\alpha-\mathrm{Al}$ and phase-diagram theories were developed to explain how $\mathrm{Al}_{3}$ Ti could be active at hypoperitectic concentrations. It has been suggested that with the addition of boron, the peritectic point moves to low titanium concentration [69-71]. Marcantonio and Mondolfo suggested that there is a ternary eutectic ( $\mathrm{Al}-(\mathrm{Al}, \mathrm{Ti}) \mathrm{B}_{2}-\mathrm{Al} \mathrm{I}_{3} \mathrm{Ti}$ ) at the Al corner of the $\mathrm{Al}-\mathrm{Ti}-\mathrm{B}$ equilibrium phase diagram at $0.05 \mathrm{wt} \% \mathrm{Ti}$ and $0.01 \mathrm{wt} \% \mathrm{~B}$ around $659.5^{\circ} \mathrm{C}$ [69]. The grain refinement occurred due to the formation of primary $\mathrm{Al}_{3} \mathrm{Ti}$ crystals which triggered the nucleation of $\alpha-\mathrm{Al}$. However, there is no reported observation of the same phenomenon by other researchers and theoretical thermodynamic calculations show that boron has virtually no effect on the Al-Ti peritectic point $[60,72,73]$. It appears that the phase-diagram theories cannot be used to explain the observed grain refinement.

### 2.2.3 The Peritectic hulk theory

This theory was proposed by Backerud and Dong [74, 75] and supported by Vader et al.[76]. It accepts that $\mathrm{Al}_{3} \mathrm{Ti}$ is a more powerful nucleant, and instead of forming primary $\mathrm{Al}_{3} \mathrm{Ti}$ crystals, $\mathrm{Al}_{3} \mathrm{Ti}$ particles may remain undissolved in the melt when the master alloy is added. The peritectic hulk theory suggests that the borides form a shell around $\mathrm{Al}_{3} \mathrm{Ti}$ and slow down the dissolution due to the difficulty of diffusion through the borides shell. When $\mathrm{Al}_{3}$ Ti finally dissolve, there is Ti-rich liquid left inside the shell and when temperature drops the peritectic reaction takes place to form $\alpha$-Al. Although this theory seems to be consistent with some of the experiment evidence, one of its major problems is the assumption that the borides dissolve in the melt and reprecipitate to form the boride shell. In reality, however, borides are much more stable in the melt than $\mathrm{Al}_{3} \mathrm{Ti}$ [77]. Normally $\mathrm{Al}_{3} \mathrm{Ti}$ can dissolve within minutes at high temperature even with borides present in the master alloy. Furthermore, Johnsson et al. [78] found that the grain refinement efficiency does not change after a number of cycles of melting and solidifying, which in theory should decrease if the peritectic hulk theory is operative as Ti would diffuse out of the hulk. Therefore, the peritectic hulk theory is not likely to be the main refinement mechanism.

### 2.2.4 The Duplex nucleation theory

Of all the grain refinement theory proposed so far, the duplex nucleation theory is the most promising. It was first proposed by Mohanty et al. [47, 68, 79, 80] and strongly supported by Schumacher and Greer [48-51, 81]. The theory postulates that a thin layer of $\mathrm{Al}_{3} \mathrm{Ti}$ forms on the surface of $\mathrm{TiB}_{2}$ particles which nucleates $\alpha$-Al. By adding the master alloy into an $\mathrm{Al}_{85} \mathrm{Y}_{8} \mathrm{Ni}_{5} \mathrm{Co}_{2}$ glassy matrix and then rapidly quenching, Schumacher et al. found the $\mathrm{TiB}_{2}$ basal plane was covered by a thin layer of $\mathrm{Al}_{3} \mathrm{Ti}$ which was surrounded by $\alpha-A l$, which demonstrated the same sequence as that proposed during nucleation [81]. The close packed planes and directions of $\mathrm{TiB}_{2}, \mathrm{Al}_{3} \mathrm{Ti}$ and $\alpha-\mathrm{Al}$ are parallel and highlighted in Figure 2.10. The orientation relationship can be written as:


Figure 2.10 The orientation relationships between $T i B_{2}, A l_{3} T i$ and $\alpha-A l$. Their close packed planes and directions are highlighted in red and blue, respectively.

Mohanty et al. suggested that the formation of the $\mathrm{Al}_{3}$ Ti layer is caused by a concentration gradient of Ti towards the $\mathrm{TiB}_{2}$ particles. Considering the local equilibrium near the $\mathrm{TiB}_{2}$ particles, the $\mathrm{Al}_{3} \mathrm{Ti}$ might be stable and thus nucleate $\alpha$-Al. Similarly, the hypernucleation theory proposed by Jones [82, 83] suggested that the Ti solute can segregate to the melt-TiB $\mathrm{TB}_{2}$ interface and form a stable pseudocrystals which nucleate $\alpha$-AI.

Recently, with high resolution TEM, a Ti-rich monolayer has been observed on the $\mathrm{TiB}_{2}\{0001\}$ surface and the same $O R$ is suggested between $\mathrm{TiB}_{2}$ particles and this $\mathrm{Al}_{3} \mathrm{Ti}$ two-dimensional compound (2DC) [52]. Atomic level simulations on the stability of this thin $\mathrm{Al}_{3} \mathrm{Ti}$ layer have been performed through density functional theory (DFT) calculations and molecular dynamics (MD) simulations. Through DFT calculations there is a high interfacial energy between $\mathrm{TiB}_{2}$ and $\alpha-\mathrm{Al}$, suggesting that $\mathrm{TiB}_{2}$ is a poor nucleant for $\alpha-\mathrm{Al}$, while an $\mathrm{Al}_{3} \mathrm{Ti}$-like thin layer could be thermodynamically stable on the $\mathrm{TiB}_{2}$ surface [84]. However, according to Wearing et al. [85], $\alpha-\mathrm{Al}$ nucleation directly on a Ti terminated $\mathrm{TiB}_{2}$ substrate is a more favoured mechanism and a thin $\mathrm{Al}_{3} \mathrm{Ti}$ layer appears to be more stable on B terminated $\mathrm{TiB}_{2}$. MD simulations show a considerable degree of FCC-like ordering at the Ti terminated $\mathrm{TiB}_{2}$-liquid interface, but the thin ordering layer is also possible to be strained Al atoms with lattice parameters similar to $\mathrm{Al}_{3} \mathrm{Ti}[86,87]$.

### 2.3 Particle pushing and engulfment in solidification

Mohanty et.al. found that $\mathrm{TiB}_{2}$ particles were pushed to the $\alpha-\mathrm{Al}$ grain boundaries when there was no excess Ti solute in the melt [47], suggesting a high interfacial energy between $\mathrm{TiB}_{2}$ and $\alpha$-Al. According to the prediction of the free growth model, only a small percentage (1-10\%) of $\mathrm{TiB}_{2}$ particles from the grain refiner can trigger nucleation events $[88,89]$. The remaining $\mathrm{TiB}_{2}$ particles are either pushed to the grain boundaries or engulfed and retained within $\alpha-A l$ grains during solidification. The crystallographic analysis performed by Schaffer et al. [90] showed that very few $\mathrm{TiB}_{2}$ particles pushed to the grain boundaries share any reproducible orientation relationships with surrounding $\alpha$-AI, while $70 \%$ of the engulfed particles showed one of two simple ORs, indicating that the formation of low energy interfaces assists engulfment.

Multiple models have been developed in order to study pushing and engulfment of second-phase particles in the growth front [91-97]. It was first observed by Uhlmann in 1964 [91] that there is a critical velocity of the growing front below which the particles are rejected and continuously pushed by the interface, and above which they are engulfed and trapped in the solid. In 1976 Omenyi and Neumann [98] proposed the thermodynamic criterion for pushing-engulfment transition that when the interface moves slowly (a few micrometres per second), the thermodynamic (equilibrium) conditions will predominate at the interface and the pushing/engulfment process is solely dependent on the net change in free energies of the system:

$$
\Delta \sigma=\sigma_{S P}-\left(\sigma_{L P}+\sigma_{S L}\right)
$$

Equation 2.26
Where $\sigma_{S P}$ is the solid-particle interfacial energy, $\sigma_{L P}$ is the liquid -particle interfacial energy and $\sigma_{S L}$ is the solid-liquid interfacial energy. For $\Delta \sigma<0$, the particles are engulfed by the interface, while for $\Delta \sigma>0$ the pushing-engulfment transition then depends on the growth velocity of the interface.

The expression format of the critical velocity has been continuously adapted by taking different factors into account including: the thermal gradient in the liquid [99], the roughness of particles [92], the shape/curvature of the interface [92, 100-102], and the effect of agglomeration [103]. The effect of
the interface shape was first investigated by Bolling and Cisse [92]. The growing front was treated as a flat planar interface in previous models but they provided the rigorous mathematical proof that near the particles the interface must be a smooth shallow indentation. The same morphology was applied in later models and numerical simulations [101, 102, 104-106]. Figure 2.11 shows a numerical model for the SiC particle engulfment during silicon solidification [107].


Figure 2.11 (a) A schematic depiction of particle pushing and engulfment during solidification. (b) The numerical model of a SiC particle being pushed by a silicon growth front (The temperature isotherms are plotted on the left and the finite element mesh are plotted on the right). From Ref. [107]

However, most traditional pushing and engulfment models are built based on the assumption that the second-phase particles are inert, while in most metallurgical processes many of the foreign particles are active inoculants that can interact with the growing solid. Analysis for $\mathrm{TiB}_{2}$ particles engulfed inside equiaxed $\alpha$-Al grains by Schaffer et al. [90] revealed two preferred ORs, which they attributed to the interaction between $\mathrm{TiB}_{2}$ particles and the $\alpha-\mathrm{Al}$ growth front. Therefore, apart from the factors studied in traditional pushing and engulfment theory, it is important to consider such interaction between active particles and the growth front, which affects the relative orientation and distribution of the second-phase particles, and furthermore the mechanical properties of the alloy.

### 2.4 Quasicrystalline symmetry and icosahedral short-range order in supercooled melt

### 2.4.1 Quasicrystal symmetry

It has been well known in crystallography that fivefold symmetry cannot exist in crystals considering the three-dimensional translation operation. But it is first found by Shechtman in 1984 [108] that a metallic solid from the rapidly quenched Al- 14 at.\%Mn alloy showed the icosahedral symmetry ( $m \overline{3} \overline{5}$ ) [109], which is inconsistent with lattice translations and thus aperiodic in space. It was later proposed by Pauling [110-112] that the material is actually an 'icosatwin', which is a composite of twenty identical crystalline particles twinned together forming a combined icosahedral symmetry. However, that hypothesis was not consistent with analysis of the $X$-ray [113, 114], electron [115, 116] and neutron $[117,118]$ diffraction data, and it was postulated that the metallic phase is quasicrystalline and atoms are arranged with icosahedral symmetry [119]. Polyhedrons with standard icosahedral symmetry contains twofold (15), threefold (10) and fivefold (6) symmetry axes in each hemisphere, as shown in Figure 2.12 [120] using three polyhedrons with icosahedral symmetry as examples.


$\mathrm{E}=\mathrm{i}(2)$







Figure 2.12 Polyhedrons with icosahedral symmetry: icosahedron, pentagonal dodecahedron and rhombic triacontahedron. The twofold, threefold and fivefold axes are highlighted in the polyhedrons and corresponding pole figures. E means edges, $F$ means faces and $V$ means vertices.

After the first observation of the icosahedral quasicrystal in rapidly quenched Al-Mn alloys [108], other similar quasicrystals have been found in many Al-transition metal element (TM) alloys [114, 121-124]. For example, in a rapidly solidified $\mathrm{Al}_{7} \mathrm{Cr}$ alloy, the icosahedral quasicrystal was found to coexist with the monoclinic $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ intermetallic phase, with a definite orientation relationship linking the icosahedral quasicrystals and the pseudo-icosahedral building blocks in $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ [125]. Many stable crystalline Al (rich)-TM intermetallics contain icosahedral units in their crystal structure, and such icosahedral quasicrystal approximant nature indicates the short-range icosahedral symmetry of the atomic arrangement in the undercooled liquid. Figure 2.13 plots the icosahedral atomic clusters in three AI-TM intermetallic compounds: $\mathrm{Al}_{45} \mathrm{Cr}_{7}, \mathrm{HT}-\mathrm{Al}_{11} \mathrm{Mn}_{4}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$; the distorted icosahedral clusters are all centred with TM atoms. Their crystal structure and lattice parameters are listed in Table 2.3.


Figure 2.13 The TM-centred icosahedral atomic clusters in three AI-TM intermetallic compounds: $\mathrm{Al}_{45} \mathrm{Cr}_{7}, \mathrm{HT}-\mathrm{Al}_{11} \mathrm{Mn}_{4}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$.

Table 2.3 The crystal structure of $\mathrm{Al}_{45} \mathrm{Cr}_{7}, \mathrm{HT}-\mathrm{Al}_{11} \mathrm{Mn}_{4}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$

| Intermetallic | Crystal <br> system | Space group | Lattice parameters |  |  |  |  |  | Ref |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | a(Å) | b(Å) | c( $\AA$ ) | $\alpha\left({ }^{\circ}\right)$ | $\beta\left({ }^{\circ}\right)$ | $\gamma\left({ }^{\circ}\right)$ |  |
| $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ | Monoclinic | C2/m | 25.2 | 7.6 | 11.0 | 90 | 128 | 90 | [126] |
| $\mathrm{HT}-\mathrm{Al}_{11} \mathrm{Mn}_{4}$ | Orthorhombic | Pnma | 14.8 | 12.3 | 12.5 | 90 | 90 | 90 | [127] |
| $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ | Monoclinic | C2/m | 15.5 | 8.0 | 12.5 | 90 | 108 | 90 | [128] |

Decagonal quasicrystals are another main group of the quasicrystals, which are aperiodic on the tenfold plane, but periodic along the decagonal axis $(10 / \mathrm{mmm})$ [109]. It has been found that decagonal quasicrystals are common in the rapidly cooled Al -Fe system, together with the monoclinic $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ tenfold twins $[129,130]$. The tenfold axis of the decagonal quasicrystal is parallel to the pseudotenfold [010] twin axis. The $\{010\}$ plane of the monoclinic $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ is shown in Figure 2.14: there are local pentagonal rings formed by Fe atoms, and there is twofold rotational symmetry coincident with the <010> in monoclinic structure, which gives $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ a pseudo-tenfold symmetry around <010> [131, 132]. This intermetallic compound is also known as a decagonal-quasicrystal approximant.


Figure 2.14 The local pentagonal atomic rings in \{010\} plane in $A l_{13} F e_{4}$

### 2.4.2 Icosahedral short-range order in supercooled melt

It has been known for over a half century that substantial undercooling ( $\sim 0.2 T_{m}$ ) can be achieved in small metallic droplets in the absence of catalytic inclusions [34]. Frank [133] postulated icosahedral short-range order (ISRO) in the melt and performed topological calculation showing such geometry has lower energy (8.4\%) than other close packed FCC or HCP structures, considering the atomic interactions following a Lennard-Jones potential. More recently, combining containerless processing of high purity melts with electromagnetic levitation, ISRO was proved to be prevailing in supercooled $\mathrm{Fe}, \mathrm{Zr}, \mathrm{Ni}$ and Co pure metal melts by neutron diffraction and synchrotron radiation [134, 135]. Moreover, in these experiments such ISRO was revealed already above $T_{m}$ and became more pronounced with deeper undercooling.

Although the ISRO was initially proposed for the monoatomic liquid, it was also observed in alloy systems. Topologically the interatomic distance between first-neighbour atoms on the icosahedron surface is $5 \%$ larger than the distance from the centre to the surface [136]. Combining with the chemical affinities, the ISRO may even be favoured by a small concentration of slightly smaller or larger atoms. In an undercooled AI-Fe-Co melt, ISRO was measured with significant chemical order in which the first coordinate shell of the icosahedron tends to be Al atoms centred with TM atom [137]. Similar to the pure metal liquid, the topological and chemical short-range order was enhanced with increasing undercooling. Molecular dynamics simulation of a supercooled $\mathrm{Cu}_{64.5} \mathrm{Zr}_{35.5}$ melt shows that the icosahedral clusters grow into larger shells with deeper undercooling [138]. For the alloys that form quasicrystals and approximants, the same tendency for the ISRO was observed in the liquid above and below $\mathrm{T}_{\mathrm{L}}$ for $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ [139], $\mathrm{Al}_{74} \mathrm{CO}_{26}$ [139], $\mathrm{Al}_{88.5}\left(\mathrm{Mn}_{x} \mathrm{Cr}_{1-x}\right)_{11.5}$ [140] and $\mathrm{Al}_{72.1} \mathrm{Pd}_{20.7} \mathrm{Mn}_{7.2}$ [141] melts. Furthermore, a metastable icosahedral quasicrystal phase was observed through in-situ X-ray diffraction by Kelton et al. in deeply undercooled $\mathrm{Ti}_{39.5} \mathrm{Zr}_{39.5} \mathrm{Ni}_{21}$ melt for a few seconds before it transformed into the stable C14 Laves phase [142].

### 2.4.3 Nucleation from icosahedron quasicrystals and/or icosahedral short-range order

It has been known for over half a century that Ir can cause strong grain refinement in yellow gold alloys [143-145], but the mechanism remained unclear. Recently it was proposed by Kurtuldu et al. [24] that icosahedral quasicrystals and/or icosahedral short-range order forming in the undercooled melt act as a potent nucleant for FCC-Au. The iQC-mediated nucleation mechanism is illustrated in Figure 2.15 from their work.
(a)

Liquid
(b)

Liquid+iQC
(c)

Liquid+iQC+FCC
(d)


Liquid+FCC

Figure 2.15 iQC-mediated nucleation mechanism: (a) Frank's icosahedral short-range order of atoms in the liquid; (b) formation of iQC in the liquid; (c) heteroepitaxy of the FCC phase on the iQC facets; (d) growth of the FCC phase and dissolution of the iQC during cooling due to the peritectic nature of the phase diagram. From Ref. [24]

A significant above-random proportion of $60^{\circ}\{111\}$ twinned boundaries was measured by Kurtuldu et al.[24] between neighbouring Au grains, which was proposed to result from the FCC variants of the reported OR between the FCC unit cell and iQC: $\{111\}|\mid i(3)$ with three in-plane $<110>| | i(5)$, as shown in Figure 2.16. The same OR was also suggested between FCC AI and Cr -induced iQC in Al - Zn alloys [23].


Figure 2.16 The crystallographic orientation relationship between FCC unit cell and icosahedral quasicrystals. From Ref. [24]

The crystallographic orientation relationships between icosahedral quasicrystals and a metal matrix have been studied extensively. Singh and Tsai reported the epitaxial orientation relationships between $\alpha-\mathrm{Mg}$ and $\mathrm{Mg}-\mathrm{Zn}-\mathrm{Y}$ iQC precipitates, as well as between $\mathrm{Pb}, \mathrm{Bi}$ and Sn particles embedded in an icosahedral Al-Cu-Fe matrix [146]. According to Bolliger and Luscher [147, 148], the vapor-deposited Al films on the fivefold symmetry surface of the $\mathrm{Al}-\mathrm{Pd}-\mathrm{Mn}$ icosahedral quasicrystals exhibit an epitaxial orientation relationship between the FCC phase and iQCs, which is the same as in Figure 2.16: one of the FCC <111> direction parallel to one of the icosahedral threefold axes.

Apart from the most commonly observed OR (OR1) between FCC phase and icosahedral quasicrystals, four more ORs have been reported between the iQC and aluminium matrix, as OR2-OR5 listed in Table 2.4. OR1-OR3 were found between the Al-Mn iQC and Al matrix by Beeli et al.[149], and OR1-OR4 were reported in the Al-Li-Cu-Mg system by Loisseau and Lapasset [150, 151]. OR5 was originally observed between an iQC and cubic rational approximants [119, 152-154], but it has also been found between the dodecahedron shaped AI-Mn icosahedral precipitates and the aluminium matrix [155]. Among all five ORs, OR1 is the best fit between the FCC phase and iQC, according to Singh and Tsai [156], as most of the major axes and planes of these two phases match to each other.

Table 2.4 Orientation relationships between icosahedral quasicrystal and FCC AI

| OR | Icosahedron axes/planes | Corresponding FCC Al directions/planes |
| :--- | :--- | :--- |
| 1 | Twofold | $<111>(3),<110>(3),<112>(3)$ |
|  | Fivefold | $<110>(3),<113>(3)$ |
| 2 | Twofold | $<100>(2),<111>(1),<110>(1),<112>(1)$ |
|  | Fivefold | $<100>(1),<112>(2),<315>(2),<221>(1)$ |
| 3 | Twofold | $<100>(1),<110>(2),<112>(4)$ |
|  | Fivefold | $<111>(2),<112>(2),<113>(2)$ |
| 4 | Twofold | $<110>(1),<112>(4),<221>(1)$ |
|  | Fivefold | $<111>(1),<112>(2)$ |
| 5 | Twofold | $<100>(3),<112>(3),<123>(3)$ |
|  | Fivefold | $<012>(3)$ |

### 2.5 Grain boundary formation in equiaxed solidification

### 2.5.1 Grain coalescence and grain boundary migration

At the last stage of solidification, with thin liquid films left, grains start to impinge and form grain boundaries. This process is termed 'coalescence'. The thermodynamic criterion for grain coalescence to happen was deduced by Rappaz et al. [157]:

$$
\begin{equation*}
\Delta T=\frac{\Delta \Gamma}{\delta}=\frac{\gamma_{g b}-2 \gamma_{s l}}{\Delta s_{f}} \cdot \frac{1}{\delta} \tag{Equation 2.27}
\end{equation*}
$$

Where $\Delta T$ is the undercooling for approaching planar liquid/solid interfaces to coalesce into a grain boundary. $\Delta \Gamma$ is the difference between the grain boundary energy, $\gamma_{g b}$, and twice the solid-liquid interfacial energy, $2 \gamma_{s l}$, divided by the entropy of fusion, $\Delta s_{f}$. $\delta$ is a measure of diffuse interface thickness (typically $\sim 2 n m$ ). If $\gamma_{g b}<2 \gamma_{s l}, \Delta T<0$ and the liquid film is unstable. The two liquid-solid interfaces coalesce into grain boundaries immediately as they get close enough (at a distance on the order of $\delta$ ). This situation is referred to as 'attractive', typically for two dendritic arms belonging to the same grain $\left(\gamma_{g b}=0\right)$ or grains that form low angle grain boundaries, as shown in Figure 2.17 [158]. If $\gamma_{g b}=2 \gamma_{s l}, \Delta T=0$ and this situation is referred to as 'neutral'. If $\gamma_{g b}>2 \gamma_{s l}, \Delta T>0$ and the liquid film is stable between the neighbouring grains until the undercooling exceeds $\Delta T$. Although the value of $\gamma_{g b}$ depends strongly on the misorientation between the impinging grains, this 'repulsive' situation applies to the coalescence of most high angle grain boundaries (Figure 2.17(b)) as Miller and Chadwick [159] indicated the average grain boundary energy $\gamma_{g b, a v e} \approx 2.2 \gamma_{s l}$.


Figure 2.17 (a) The measured relative grain boundary energy for symmetric interface of $A l<100>$ tilting. Note that 1.0 on the $y$-axis corresponds to $0.324 \mathrm{~J} / \mathrm{m}^{2}$, and the 'misorientation' on $x$-axis means tilting angle, not necessarily the real misorientation between two FCC unit cell [160]. (b) The simplified grain boundary energy distribution used for Mathier's coalescence model [158], where the attractive region corresponds to low angle grain boundaries and repulsive region corresponds to high angle grain boundaries.

A detailed model of an equiaxed mushy zone was developed to describe the transition from a continuous liquid film network into a fully coherent solid by Vernede et al. [161, 162]. The model assumes the simultaneous nucleation of grains at random nucleation centres with random orientations, and the smooth grain boundaries between adjacent grains are approximated into straight line segments. Complete diffusion was assumed in the liquid while back-diffusion in the solid was computed according to a Landau transformation. The undercooling for coalescence was calculated based on Eq. 2.25 and the grain boundary energy was simplified into Read-Shockley distribution [163]. Figure 2.18 shows the result for the directional solidification of $\mathrm{Al}-1 \mathrm{wt} \% \mathrm{Cu}$ [161]. On the left are simulated local microstructures from the four black rectangles. The black areas between grains are liquid channel and grains with 'dry' interface (no liquid) are coloured with the same grey scale. On the right are the changes of temperature and solid fraction across the sample. For (a) and (b) $\left(0<g_{S}<0.97\right)$, most of the grains are isolated, and for (c) $\left(0.97<g_{S}<0.99\right)$, large grain clusters/aggregates are formed. Final continuous solid is formed in (d) when $g_{s}>0.99$.


Figure 2.18 Calculated mushy zone for an Al-1 wt. \% Cu alloy cooled at $1 \mathrm{~K} / \mathrm{s}$ in a gradient of $6000 \mathrm{~K} / \mathrm{m}$. Liquid channels are coloured in black, and grain clusters (no liquid film) are shaded with the same grey level. On the left: $a, b, c, d$ are the close views of the black square areas from the simulated result in the middle. From Ref. [161]

Moreover, after grain coalescence, in some alloys grain boundaries can migrate in the very last-stage of solidification. It was first proposed by Biloni in 1961 [164] that solidification grain boundary migration in Al changed its grain structures. Subsequently more observations of grain boundary migration during solidification were reported in Al-0.28wt\% Fe [165], Al-0.2wt\% Cu [166], Ti-6 wt\% Cr [167] and AM50 (Mg-4.9wt\% Al-0.34wt\% Mn) [168]. It was suggested that the migration occurs rapidly
near the solidus temperature of the alloy [169-171], and after migration the grain boundary energy decreases [172, 173]. A proposed grain boundary migration model during solidification is plotted in Figure 2.19(a) [167]. Atoms in part of grain 2 (blue) change their orientation into grain 1 (yellow), and the initial grain 2 is divided into 3 separate grains at the final state. The dendritic segregation profile is retained through this process, which can be directly observed from the optical image of the as-cast Ti-6 wt.\% Cr in Figure 2.19(b) and (c) [167].


Figure 2.19 (A) A theorised grain boundary migration pathway. (B) Optical image of as-cast Ti-6wt\% Cr after etching, revealing the dendritic segregation due to chemical composition. (C) Microstructure of B superimposed with the highlighted grain boundaries (green). From Ref. [167]

### 2.5.2 Grain collision and movement under external shear/forced convection

In high pressure die casting (HPDC) of Al and Mg alloys, agglomeration and bending of grains caused by grain collisions under external mechanical stress can produce a texture different to the theoretical prediction for a random orientated microstructure [174]. Compared to statically cooled AlSi 4 MgMn , HPDC produces a higher frequency of grain boundaries at low angle $\left(5^{\circ}-10^{\circ}\right)$ and high angle $\left(55^{\circ}-60^{\circ}\right)$. For Mg alloys, HPDC AM50 alloy has higher fraction of $\alpha-\mathrm{Mg}$ grain boundaries at various angles from $0^{\circ}$ to $90^{\circ}$ compared to the statically cooled sample. Moreover, for Al-6.5wt.\% Si alloy that has been sheared in the semi-solid state with 0.2 solid fraction and quenched, the investigation of the orientation relationships between the neighbouring $\alpha$-Al grains in agglomerates revealed that the $\alpha$ Al grains were related either by low angle grain boundaries with misorientation less than $10^{\circ}$ or by misorientation of near $60^{\circ}$ about $\{111\}$ which corresponding to a coherent twin [175]. Therefore, it appears that, under external shear in the mushy zone, collisions between grains can form certain preferred boundaries and produce a texture which is different to the theoretical prediction for total random microstructure.

More recently, with the help of 3D X-ray diffraction microscopy, direct observation of grain rotation to form preferred boundaries was made during the annealing of semisolid Al-Cu alloy with 0.7 solid fraction [176, 177]. Without any external force, grains were found to rotate to lower the grain boundary energy, and the final texture depends on the grain boundary energy landscape. Figure 2.20 shows the rotations of two reconstructed grains before (a) and after (b) annealing, and a computed tomography (CT) slice across the two grains. After rotation the misorientation between the two grains decreases from $10.1^{\circ}$ to $7.4^{\circ}$. As indicated in the CT slice, the crystal lattice of the two grains were in direct contact, and there is no visible liquid film between them.


Figure 2.20 The rotation of AI grains in AI-5wt\% Cu holding at $630^{\circ} \mathrm{C}$ for 30 min . (A) Initial and (B) final $3 D$ reconstructed morphology of two grains. (C) X-ray computed tomography image of the two grains showing 'dry' interface. From Ref. [176]

### 2.5.3 Grain boundary defects

From microscopic perspective, there are three parameters which are represented by a vector characterising a rigid body translation from one grain to the other [178]. The translations are independent of the macroscopic parameters which will be discussed in the next section, but are controlled by the minimisation of grain boundary energy to generate the atomic structure of the grain boundary under actual external conditions such as temperature, pressure and chemical compositions [179].

As mentioned above, individual atoms at grain boundaries are likely to be rearranged and shifted from their regular crystal positions. For the grain boundary between two different phases (nucleant and growing solid), Turnbull and Vonnegut proposed different interface structure according to the disregistry ( $\delta$ ) between the two lattice, as shown in Figure 2.21. For small disregistry the atoms of growing solid can precisely fit the atoms of nucleant with a certain amount of strain ( $\varepsilon$ ). In this situation, the interface form coherently between the two crystals. For larger disregistry some regions in the interface are in good fit, while in other regions the atoms cannot perfectly match through a certain amount of strain. Therefore, there will be dislocations forming at grain boundary to release the accumulated stress. The interface could be pictured as good fit regions separated by a dislocation gridwork and the dislocation density is proportional to ( $(\delta-\varepsilon)$.


Figure 2.21. The grain boundaries between nucleant and growing solid with different lattice matching.

### 2.6 Grain boundary plane distribution \& Grain boundary character distribution

### 2.6.1 Five macroscopic parameters characterisation

A grain boundary segment can be seen as a function of lattice misorientation and grain boundary plane orientation, $\lambda(\Delta \mathrm{g}, \vec{n})$, and therefore it requires five macroscopic parameters (three for the lattice misorientation and two for the grain boundary plane orientation) to fully describe the character of grain boundaries [180-182]. The definition of the five parameters is plotted in Figure 2.22. The first three angles $\left(\varphi_{1}, \Phi, \varphi_{2}\right)$ makes the transfer matrix to rotate from orientation A to B :

$$
g\left(\varphi_{1}, \Phi, \varphi_{2}\right)=\left(\begin{array}{ccc}
c \varphi_{1} c \varphi_{2}-s \varphi_{1} \varphi_{2} c \Phi & s \varphi_{1} c \varphi_{2}+c \varphi_{1} s \varphi_{2} c \Phi & s \varphi_{2} s \Phi \\
-c \varphi_{1} s \varphi_{2}-s \varphi_{1} c \varphi_{2} c \Phi & -s \varphi_{1} s \varphi_{2}+c \varphi_{1} c \varphi_{2} c \Phi & c \varphi_{2} s \Phi \\
s \varphi_{1} s \Phi & -c \varphi_{1} s \Phi & c \Phi
\end{array}\right) \quad \text { Equation 2.28 }
$$

Where c and s means cosine and sine, respectively. The last two angles describe the grain boundary plane normal, $\vec{n}(\phi, \theta)$, which is shown in Figure 2.22 (b). The first angle, $\phi$, is the angle between the grain boundary trace normal and x-axis on the cross section, and the second angle, $\theta$, is the angle between the plane normal and the z-axis in 3D space.


Figure 2.22 Definition of the five macroscopic parameters for grain boundaries characterisation. From Ref.[183]

The first four parameters out of five can be precisely obtained through the analysis of an EBSD dataset, while for the last one, the precise value can be determined through 3D EBSD analysis, or it can be assessed by considering the probability from 2D EBSD mapping, as illustrated in Figure 2.22(c). For a sectioned grain boundary trace $l$, all possible grain boundary planes must contain this segment, i.e. all possible planes must be in the zone of $l$. For all these possible grain boundary planes, the plane perpendicular to the sectioned plane has the highest probability, while the plane parallel to the sectioned plane has the lowest probability. The probability of these planes is proportional to $\sin (\theta)$ ( $\theta$ is the angle between the grain boundary plane normal and $z$-axis). For every grain boundary segment observed, it corresponds to a set of possible planes, containing a true interfacial plane with a set of incorrect planes. The probability of the true plane in the set is always 1 while the probability of any incorrect planes in the set is less than 1. After considering a large enough grain boundary dataset, the frequency of true grain boundary planes will greatly exceed other incorrect ones, and provide useful information about the real interface between neighbouring grains.

Considering the distribution of interfacial planes at all grain boundaries, $\lambda(\vec{n})$, gives us a grain boundary plane distribution (GBPD), while considering the distribution of interfacial planes at the grain boundaries with certain misorientation, or more precisely, with certain orientation relationships between the neighbour lattice, gives us a grain boundary character distribution (GBCD), $\lambda(\Delta g, \vec{n})$. For example, in FCC alloys, the $\lambda\left(\vec{n} \mid 60^{\circ} /[111]\right)$ describes the distribution of interfacial planes at all $60^{\circ}$ [111] twin grain boundaries.

### 2.6.2 GBPD and GBCD in Al and Mg alloys

The GBPD and GBCD analysis has been carried out on polycrystalline specimen from various materials [184-194]. In cold rolled and annealed CP-Al alloy, the grain boundary plane distribution (Figure 2.23(a)) shows that the $\{111\}$ planes are preferred to be the grain boundary plane [195]. The peak is $25 \%$ higher than the random distribution. Figure $2.23(b)$ and (c) are the grain boundary character distributions for two special grain boundaries: the $60^{\circ}\{111\}$ twin and $50^{\circ}<110>$ twin. For the $60^{\circ}\{111\}$ twinning boundaries, the $\{111\}$ common plane is highly preferred ( $\sim 28$ times higher than random) to be the interfacial plane due to the perfect atomic matching at the interface. The same for $50^{\circ}<110>$ twinning boundaries with $\{113\}$ common plane to be the interface. In cast and annealed $\mathrm{Mg}-3 \mathrm{Al}-1 \mathrm{Zn}$ (AZ31) alloy, there is a high preference for $56^{\circ}$ and $64^{\circ}$ grain boundaries between Mg grains [196]. With further GBCD analysis, twinned grain boundaries with preferred coherent interfaces that correspond to low interfacial energy were identified at these two misorientation angle: $56^{\circ}$ $[11 \overline{2} 0]\{1 \overline{1} 01\}$ and $64^{\circ}[11 \overline{2} 0]\{1 \overline{1} 03\}$.


Figure 2.23 (a) GBPD of the cold rolled and annealed CP Al. (b) GBCD for $60^{\circ}\{111\}$ twin grain boundaries showing the $\{111\}$ plane to be the interface. (c) GBCD for $50^{\circ}<110>$ twin grain boundaries showing the \{113\} plane to be the interface. [195]

As indicated above, in order to form low energy boundaries during annealing, two mechanisms are likely to happen between grains: (i) rotation of grains which involves the first three parameters and; (ii) the motion of the interface (straightening and rotation) which involves the last two parameters. A more direct result is plotted in Figure 2.24 showing that the lower the interfacial energy the higher
frequency it is observed for symmetric boundaries tilting along <110> in annealed CP-AI [197]. Note that the 'misorientation' angle in the $x$-axis means the tilt angle along the $<110>$ direction, not the misorientation between two unit cells. For $60^{\circ}\{111\}$ twinning, it corresponds to $70.5^{\circ}$ tilt along the common <110> direction, while $50^{\circ}\{113\}$ twinning corresponds to $129.5^{\circ}$ tilt along the common <110> direction. These two low energy interfaces, together with the low angle boundaries, are preferred to form during CP AI annealing.


Figure 2.24 Comparison of measured energies (dashed line) to populations (solid line) for symmetric [110] tilt boundaries. The misorientation angle is the tilting angle along the common [110] direction. [197]

### 2.7 Density Functional Theory (DFT)

Crystals are formed by a collection of well-defined atoms, and each atom contains two parts: the nucleus and electrons. The atomic nuclei are much heavier than electrons, which means the electrons are highly mobile and respond much faster to the change of surroundings than nuclei. In order to compute the energy of atoms, the question is split into two parts: first the atomic nuclei position is fixed and the ground state energy for electrons moving in the field of the fixed nuclei needs to be calculated. The ground state energy is a function of the nuclei positions: $E\left(\vec{R}_{1}, \vec{R}_{2}, \ldots, \vec{R}_{M}\right)$. After we obtain this energy function, we can know the energy change when we move atoms, and find the lowest energy configuration [198].

### 2.7.1 The Schrodinger Equation

In quantum mechanics [199], one simple form of the time-independent Schrodinger equation [200] that describes the states of quantum particles can be written as:

$$
\begin{equation*}
H \psi=E \psi \tag{Equation 2.29}
\end{equation*}
$$

Where $H$ is the Hamiltonian operator, $\psi$ is the wave functions of the quantum particles and $E$ is the energy. There is a set of solutions, known as eigenstates, $\psi_{n}$, and each $\psi_{n}$ has a corresponding $E_{n}$ value which is an eigenvalue. When $n=0, E_{0}$ is known as the ground state energy. The detailed expression of the Hamiltonian depends on the physical system. For a collection of well-defined atoms in a crystal, multiple electrons are interacting with multiple nuclei and the Schrodinger equation is in a more complicated form:

$$
\begin{equation*}
\left[-\frac{\hbar^{2}}{2 m} \sum_{i=1}^{N} \nabla_{i}^{2}+\sum_{i=1}^{N} V\left(\vec{r}_{i}\right)+\sum_{i=1}^{N} \sum_{j<i} U\left(\vec{r}_{i}, \vec{r}_{j}\right)\right] \psi=E \psi \tag{Equation 2.30}
\end{equation*}
$$

Here, $\hbar$ is the reduced Planck constant and $m$ is the electron mass. The three terms in the brackets correspond to the kinetic energy of each electron, the interaction energy between each electron and the whole collection of nuclei, and the interaction energy between electrons. $\psi$ is the electron wave
function which describes the spatial positions of the $N$ electrons: $\psi=\psi\left(\vec{r}_{1}, \vec{r}_{2}, \ldots, \vec{r}_{N}\right)=$ $\psi_{1}(\vec{r}) \psi_{2}(\vec{r}) \ldots \psi_{N}(\vec{r})$.

Considering the definition of the Hamiltonian above, the electron-electron interaction term is the most critical one in terms of solving the equation. The wave function of an individual electron $\psi_{i}(\vec{r})$ cannot be determined without simultaneously considering the wave functions of other electrons. Therefore, the Schrodinger equation is a many-body problem and it is extremely difficulty to solve the equation considering $N$ can be huge in real problems.

### 2.7.2 Electron density

According to quantum mechanics, the electron wave functions at certain position cannot be observed directly. The quantity that can be measured in principle is the probability of finding electrons at a certain position, i.e., the electron density:

$$
\begin{equation*}
n(\vec{r})=2 \sum_{i} \psi_{i}^{*}(\vec{r}) \psi_{i}(\vec{r}) \tag{Equation 2.31}
\end{equation*}
$$

The term inside the summation refers to the probability of finding an electron in an individual wave function $\psi_{i}$ at position $\vec{r}$, and the summation covers all the individual electron wave functions that are occupied by electrons. The factor 2 comes from the spin of electrons and the Pauli exclusion principle points out that each electron wave function can only be occupied by two electrons with different spins. From Eq. 2.29 it is clear that the electron density that contains a great amount of information is a function of only three coordinates, which is much simpler compared to the full wave function solution of the many-body Schrodinger equation in Eq. 2.28. If we sum the electron density throughout the whole material, we have the total number of electrons, $N$ :

$$
\begin{equation*}
\int n(\vec{r}) d \vec{r}=N \tag{Equation 2.32}
\end{equation*}
$$

### 2.7.3 Density functional theory

The entire density functional theory is built on two fundamental theorems that were proved by Hohenberg and Kohn in 1964 [201]. The first theorem is: The ground-state energy from the Schordinger equation is a unique functional of the electron density. That is to say, the electron density uniquely determines all properties, including the energy and the wave function, of the ground state. The second Hohenberg-Kohn theorem is: The electron density that minimises the energy of the overall functional is the true electron density corresponding to the full solution of the Schrodinger equation. Therefore, instead of solving the Schrodinger equation by finding the wave functions of $3 N$ variables, the ground-state energy can be obtained by finding the corresponding electron density which only contains 3 spatial variables.

The Hohenberg-Kohn theorem shows that the ground-state energy of many electrons is a functional of the electron density, but it does not give any forms of this functional. Kohn and Sham incorporated the electron density to modify the single electron Schrodinger equation, which is the Kohn-Sham equation [202]:

$$
\begin{equation*}
\left[-\frac{\hbar^{2}}{2 m} \nabla^{2}+V(\vec{r})+V_{H}(\vec{r})+V_{X C}(\vec{r})\right] \psi_{i}(\vec{r})=\varepsilon_{i} \psi_{i}(\vec{r}) \tag{Equation 2.33}
\end{equation*}
$$

In the brackets, the four terms are, in order, the kinetic energy of the single electron, the interaction energy of the single electron with the whole collection of atomic nuclei, the interaction energy between the single electron with the whole collection of electrons, and the exchange-correlation energy. The third term, $V_{H}(\vec{r})$, which is called the Hartree potential, is defined as:

$$
\begin{equation*}
V_{H}(\vec{r})=e^{2} \int \frac{n\left(\vec{r}^{\prime}\right)}{\left|\vec{r}-\vec{r}^{\prime}\right|} d \vec{r}^{\prime} \tag{Equation 2.34}
\end{equation*}
$$

This potential represents the Coulomb repulsion between the single electron and the total electron density. But there is a self-interaction contribution in the Hartree potential because the single electron described in the Kohn-Sham equation is also part of the total electron density. This self-interaction is unphysical, and the correction for it, together with other effects, is included into the last term $V_{X C}(\vec{r})$ in Eq. 2.31, which describes the exchange and correlation contribution.

The fundamental principle of density functional theory calculation to find the ground-state electron density and corresponding energy is based on an iterative algorithm:

1. Define an initial trial electron density, $n(\vec{r})$;
2. Solve the Kohn-Sham equation (Eq. 2.31) with the trial electron density to find the single electron wave function, $\psi_{i}(\vec{r})$;
3. Calculate the electron density with the Kohn-Sham single electron wave function from step 2: $n^{\prime}(\vec{r})=2 \sum_{i} \psi_{i}^{*}(\vec{r}) \psi_{i}(\vec{r})($ Eq. 2.29);
4. Compare the calculated electron density, $n^{\prime}(\vec{r})$, with the initial electron density, $n(\vec{r})$. If they are the same, then this is the ground-state electron density, and use it to calculate the groundstate energy. Otherwise, update the trial electron density and repeat from step 2.

There are many detailed operations in this process, e.g., how to define the initial trial electron density, what is the approximation form of the exchange-correlation term, to what extent the two electron density can be considered the same, how to update the trial electron density etc. These details are out of the scope of the research, and thus are not presented here.

## Chapter 3 Solidification orientation relationships between $\mathrm{Al}_{3} \mathrm{Ti}_{\text {\& }} \mathrm{TiB}_{2}$

### 3.1 Introduction

Orientation relationships (ORs) can form during solidification by a variety of mechanisms. Often, the OR formed by heterogeneous nucleation and its disregistry are used as a measure of the potency of particles in a grain refiner. However, there can be more than one OR formed and multiple mechanisms can generate ORs during solidification so it is often difficult to assign each orientation relationship to a formation mechanism, and it can be highly challenging to identify the nucleating particle with certainty. To build a deeper understanding of the mechanisms that lead to solidification ORs, here new approaches are presented to link ORs to their formation mechanism using a model system containing numerous potent nucleant particles. In this Chapter, $\mathrm{TiB}_{2}$ and $\mathrm{Al}_{3} \mathrm{Ti}$ were selected to study OR formation for the following reasons:

1. Both are faceted phases with simple growth facets which simplifies the interpretation of pushing and engulfment processes;
2. There are crystallographic similarities between these hexagonal and tetragonal phases [203,204] which allows low energy interfaces and multiple ORs to form;
3. These phases are important in the grain refinement of Al alloys, where a thin layer of $\mathrm{Al}_{3} \mathrm{Ti}$ forms on $\mathrm{TiB}_{2}$ particles followed by the nucleation of $\alpha-\mathrm{Al}$.

As shown in Equation 2.22 in the Literature Review, the reported OR between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ can be written as:

$$
\{112\}_{\mathrm{Al3Ti}} \|\{0001\}_{\mathrm{TiB} 2}, \text { with }<\overline{2} 01>_{\mathrm{Al3Ti}}\left(\text { or }<1 \overline{1} 0>_{\mathrm{Al3Ti}}\right) \|<11 \overline{2} 0>_{\mathrm{TiB} 2}(\text { OR1 })
$$

In this Chapter, analytical SEM studies and DFT calculations are combined to study the solidification ORs between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ with three main aims: (i) identify the preferred ORs between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$; (ii) distinguish ORs formed by different mechanisms and (iii) understand the active interactions between $\mathrm{TiB}_{2}$ particles and the growing $\mathrm{Al}_{3} \mathrm{Ti}$ front.

### 3.2 Methods

### 3.2.1 Sample preparation

Orientation relationships between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ were studied in three types of sample. First, in commercial Al-5Ti-1B and Al-3Ti-1B (wt\%) grain refiner rods containing $\sim 0.2-0.8 \mu \mathrm{~m} \mathrm{TiB} 2$ particles. Second, in samples of remelted and solidified master alloy. Third, in samples of Al-0.8wt\%Ti with added $\sim 50-100 \mu \mathrm{~m} \mathrm{TiB}_{2}$ particles in which numerous $\mathrm{Al}_{3}$ Ti particles had solidified on each large $\mathrm{TiB}_{2}$ particle.

The $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ and $\mathrm{Al}-3 \mathrm{Ti}-1 \mathrm{~B}$ rods were supplied by the London and Scandinavian Metallurgical Company. For the partial-remelting and casting of the $\mathrm{Al}-3 \mathrm{Ti}-1 \mathrm{~B}$ rod, the alloy was re-heated to $980^{\circ} \mathrm{C}$ in a BN-coated clay-bonded graphite crucible in a resistance furnace. After holding for 4 hours, the melt was stirred with an $\mathrm{Al}_{2} \mathrm{O}_{3}$ rod and then poured into a $300^{\circ} \mathrm{C} \mathrm{BN}$-coated steel mould of inner height 60 mm and inner diameter 50 mm .

To make $\mathrm{Al}-0.8 \mathrm{wt} \% \mathrm{Ti}$ with large $\mathrm{TiB}_{2}$ particles, a procedure to grow $\mathrm{TiB}_{2}$ particles was developed, exploiting the relatively low melting point of the $\mathrm{Fe}-\mathrm{TiB}_{2}$ eutectic. First, 400 g of $\mathrm{Fe}-10.10 \mathrm{Ti}-3.86 \mathrm{~B}$ ( $\mathrm{wt} \%$ ) alloy was made by arc melting 99.9\% Fe flake, 99\% B pellets and 99.99\% Ti ingot. Arc melting was conducted in 30 mTorr vacuum, back-filled with Ar on a water-cooled Cu plate. The alloy was melted, flipped, remelted and then cast into a rectangular copper mould. The casting consisted of primary $\mathrm{TiB}_{2}$ (~20\% vol\%) in a matrix of $\mathrm{Fe}+\mathrm{TiB}_{2}$ eutectic similar to Ref. [205]. The Fe was then dissolved in $37 \% \mathrm{HCl}$ at $50^{\circ} \mathrm{C}$ to release the $50-100 \mu \mathrm{~m}$ primary $\mathrm{TiB}_{2}$ crystals. 50 g of $\mathrm{Al}-0.8 \mathrm{wt} \% \mathrm{Ti}$ alloy was then arc-melted using CP 99.6\% Al ingots and 99.99\% Ti ingot with the $\mathrm{TiB}_{2}$ particles extracted from the Fe-10.10Ti3.86B alloy made above. The alloy was melted, flipped three times, and then the power was stopped and the alloy solidified on the water-cooled Cu plate.

To prepare cross-sections, samples were mounted in Struers VersoCit acrylic cold mounting resin and then ground to 4000 grit with SiC paper followed by polishing with colloidal silica on a nap cloth for 5 minutes.

To study the 3D morphology of the intermetallic compounds, the $\alpha$-Al phase was selectively etched in anhydrous 1-butanol under an Ar atmosphere at $117^{\circ} \mathrm{C}$ for approximately 4 hours to remove the Al matrix. Intermetallic crystals were collected and placed on a stub for further study by analytical scanning electron microscopy (SEM).

For crystallographic investigation on both cross-sections and extracted crystals, a Zeiss Auriga field emission gun SEM fitted with a Bruker e-FlashHR electron backscatter diffraction (EBSD) detector was used. Bruker Esprit 2.0 software, combined with MTEX 4.4 toolbox within MATLAB ${ }^{\text {TM }} 9.2$ (Mathworks, USA) [206], were applied to analyse and plot the orientation relationships between different phases. The Orientation Imaging Microscopy ( $\mathrm{OIM}^{\mathrm{TM}}$ ) Data Analysis software were used to index the Kikuchi pattern. Throughout this thesis, all unit cell wireframes in figures were plotted from Euler angles $\left(\phi_{1}, \Phi, \phi_{2}\right)$ measured by Bruker Esprit 2.0 software. With the Euler angles under Bunge convention (ZXZ), the orientation matrix for a crystal to rotate from the reference crystal frame into the sample frame is:

$$
\begin{equation*}
O=R_{Z}\left(\phi_{2}\right) R_{X}(\Phi) R_{Z}\left(\phi_{1}\right) \tag{Equation 3.1}
\end{equation*}
$$

Where $R_{z}$ and $R_{X}$ are two rotation matrices of rotating along $Z$ and $X$ axis, respectively:

$$
\begin{aligned}
& R_{Z}(\theta)=\left(\begin{array}{ccc}
\cos \theta & \sin \theta & 0 \\
-\sin \theta & \cos \theta & 0 \\
0 & 0 & 1
\end{array}\right) \\
& R_{X}(\theta)=\left(\begin{array}{ccc}
1 & 0 & 0 \\
0 & \cos \theta & \sin \theta \\
0 & -\sin \theta & \cos \theta
\end{array}\right)
\end{aligned}
$$

Equation 3.3

### 3.2.2 DFT calculation

In order to compare the interfacial energy corresponding to each OR measured in this work, DFT calculations were performed using the Vienna Ab Initio Simulation Package (VASP) framework [207]. A planewave basis set and projector augmented wave (PAW) pseudopotentials [208] were used. The generalised gradient approximation (GGA) in the formalism of Perdew-Burke-Ernzerhof (PBE) was chosen for the exchange and correlation energy functional [209]. All parameters were converged to satisfy a criterion of $10^{-4} \mathrm{eV}$ for each element: $\mathrm{B}, \mathrm{Al}$ and Ti , in their pure form, where $2 \mathrm{~s}^{2} 2 \mathrm{p}^{1}, 3 s^{2} 3 \mathrm{p}^{1}$ and $3 p^{6} 3 d^{2} 4 s^{2}$ electrons respectively were treated explicitly (they are not included in the core when forming the pseudopotentials). It was determined that an energy cutoff of $350 \mathrm{eV}, k$ point density of ${ }^{\sim} 0.025 \AA^{-1}$ and Methfessel Paxton smearing width of 0.1 eV [210] were sufficient for all species and were kept consistent for the calculations.

The bulk simulations were performed under constant pressure conditions in the most stable forms at OK for all phases, and the results are listed in Table 3.1, with comparison to previous studies [85, 203, 204, 211-217]. The lattice parameters (neglecting zero point motion) match well with experiments, with all differences being less than $1 \%$. The calculated formation energies for $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ (for $\mathrm{Al}, \mathrm{Ti}$ and $B$ in their pure bulk phases it is defined as zero) are in good agreement with previous calculations and experiment results, with differences less than 5\%.

Table 3.1 The lattice parameters and formation energies from DFT calculations and experiments

| Phase | Crystal structure | Lattice parameter (Å) |  | Formation energy (kJ/mol) |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  |  | Calculated | Experimental | Calculated | Experimental |
| Al | Cubic | $a=4.045$ | $\mathrm{c}=4.045$ [211] | - | - |
| Ti | Hexagonal | $\begin{aligned} & a=2.932 \\ & c=4.651 \end{aligned}$ | $\begin{aligned} & a=2.951[212] \\ & c=4.684 \end{aligned}$ | - | - |
| B | Trigonal | $\begin{aligned} & a=4.894 \\ & c=12.539 \end{aligned}$ | $\begin{aligned} & a=4.908[213] \\ & c=12.559 \end{aligned}$ | - | - |
| $\mathrm{Al}_{3} \mathrm{Ti}$ | Tetragonal | $\begin{aligned} & a=3.846 \\ & c=8.600 \end{aligned}$ | $\begin{aligned} & a=3.854[204] \\ & c=8.584 \end{aligned}$ | $\begin{aligned} & \hline-154 \\ & -155[85] \\ & -153[214] \\ & \hline \end{aligned}$ | $\begin{aligned} & -150[215] \\ & -157[216] \end{aligned}$ |
| $\mathrm{TiB}_{2}$ | Hexagonal | $\begin{aligned} & a=3.033 \\ & c=3.231 \end{aligned}$ | $\begin{aligned} & a=3.024[203] \\ & c=3.220 \end{aligned}$ | $\begin{aligned} & -306 \\ & -310[85] \end{aligned}$ | -322[217] |

For surface calculations, constant volume simulations were performed to preserve the vacuum. Two methods are used to calculate the surface energy. The first is the traditional method of subtracting the bulk energy from the internal energy and then dividing by the surface area. Four surfaces were simulated in this study. The supercells were converged at 8 layers for the $\mathrm{Al}_{3} \mathrm{Ti}\{112\}$ surface ( 32 atoms) and 7 layers for the $\mathrm{Al}_{3} \mathrm{Ti}\{100\},\{001\}$ and $\mathrm{TiB}_{2}\{0001\}$ surfaces ( 28,14 and 20 atoms, respectively) to maintain bulk properties in the centre, and the vacuum added between the slabs was as thick as the slab itself to prevent interaction between surfaces. For $\mathrm{TiB}_{2}\{0001\}$ and $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ surfaces, there are two different possible terminations (as shown in Figure 3.1(a) and (c)), indicating their surface energies are functions of the chemical potential of the relevant element. Using the methodology described in previous literature [218], the surface energy was obtained using Eq. 3.1, where $\mathrm{TiB}_{2}$ has been used as an example:

$$
\sigma_{T i B_{2}}=\frac{1}{2 A}\left[E_{s l a b}-\frac{N_{B}}{2} E_{T i B_{2}}^{m}-\left(N_{T i}-\frac{N_{B}}{2}\right) \mu_{T i}^{s l a b}\right]
$$

Equation 3.4

Here $\sigma$ is the surface energy, $A$ is the surface area, $E_{\text {slab }}$ is the internal energy of a fully relaxed slab, $E_{T i B_{2}}^{m}$ is the calculated bulk energy for a $\mathrm{TiB}_{2}$ unit, $N_{T i}$ and $N_{B}$ are the numbers of Ti and B atoms in the slab, and $\mu_{T i}^{s l a b}$ is the chemical potential of Ti in the slab. Figure 3.1 shows the results for $\mathrm{TiB}_{2}\{0001\}$ (Figure 3.1(b)) and $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ (Figure 3.1(d)) surfaces, in comparison with other published work [85, 214].


Figure 3.1 (a) Slab model for Ti terminated and B terminated TiB $_{2}$ (0001) surface. (b) Surface energies for $T i B_{2}$ (0001) surface from DFT calculation. (c) Slab model for Al terminated and Al+Ti terminated $\mathrm{Al}_{3} \mathrm{Ti}$ (001) surface. (d) Surface energies for $\mathrm{Al}_{3}$ Ti (001) surface after DFT calculation. The formation energies, $\Delta H_{f}{ }^{\circ}$, for $\mathrm{TiB}_{2}, A I_{3} T i$ and pure Ti are shown by the vertical dotted lines. Calculations from past work [85, 214] are shown for comparison.

The second method is an average of the calculation results at various thickness for each surface. In simple cases like $\mathrm{Al}_{3} \mathrm{Ti}\{112\}$ and $\{100\}$ surfaces, the internal energy of a slab model consists of two parts: the bulk energy and the surface energy:

$$
\begin{equation*}
E_{\text {slab }}=n_{A l_{3} T i} \cdot E_{A l_{3} T i}^{m}+E_{\text {surface }} \tag{Equation 3.5}
\end{equation*}
$$

Here $E_{\text {slab }}$ is the internal energy of a fully relaxed slab, $E_{A l_{3} T i}^{m}$ is the bulk energy for an $\mathrm{Al}_{3} \mathrm{Ti}$ unit, $n_{A l_{3} T i}$ is the number of $\mathrm{Al}_{3}$ Ti units in the slab, and $E_{\text {surface }}$ is the surface energy. The bulk energy was
calculated from the slope of the straight line fit to the internal energy $E_{s l a b}$ as a function of $n_{A l_{3} T i}$ and the surface energy corresponds to the intercept (Figure 3.2(a)). For $\mathrm{TiB}_{2}\{0001\}$ and $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ surfaces, different terminations correspond to different fitting lines (Figure 3.2(b)), and the intercept now consists of the surface energy and the chemical potential from the extra atoms. Taking the Ti terminated $\mathrm{TiB}_{2}\{0001\}$ surface as an example, the internal energy can be written as:

$$
\begin{equation*}
E_{\text {slab }}=n_{T i B_{2}} \cdot E_{T i B_{2}}^{m}+\left(E_{\text {surface }}+2 \cdot \mu_{T i}^{\text {slab }}\right) \tag{Equation 3.6}
\end{equation*}
$$

Here $E_{\text {slab }}$ is the internal energy of a fully relaxed slab, $E_{T i B_{2}}^{m}$ is the bulk energy for a $\mathrm{TiB}_{2}$ unit, $n_{T i B_{2}}$ is the number of $\mathrm{TiB}_{2}$ units in the slab, $E_{\text {surface }}$ is the surface energy and $\mu_{T i}^{s l a b}$ is the chemical potential of Ti in the slab.
(a)



Figure 3.2. Second method for surface energy calculation. (a) The internal energy of $\mathrm{Al}_{3} \mathrm{Ti}$ (112) surface model versus number of $\mathrm{Al}_{3} \mathrm{Ti}$ units where the intercept is the $\mathrm{Al}_{3} \mathrm{Ti}$ (112) surface energy. (b) The internal energy of $\mathrm{TiB}_{2}$ (0001) surface model versus number of $\mathrm{TiB}_{2}$ units where the intercept include the surface energy and the chemical potential of extra Ti atoms in the slab.

The slopes of the straight lines correspond to the bulk energy for $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ according to Eq. 3.2 and 3.3. The slopes in Figure 3.2(a) and (b) give the same results as the constant pressure bulk simulation where the calculated bulk energy for $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ are $-20.62 \mathrm{eV} /$ unit and $-24.38 \mathrm{eV} /$ unit. The surface energies calculated using these two methods are listed in Table 3.2, together with results from past work. It can be seen that the values are very close using these two methods for all four surfaces, and they are all in good agreement with previous work where available. The interfacial
energies were then calculated by the common method [84,219,220] of subtracting the bulk energy, dividing by the area, and then subtracting away any surface energy. Overall, the bulk and surface energy calculations are in good agreement with previous work and, together, they form the basis of the interfacial calculations performed in this study.

For the $\mathrm{Al}-\mathrm{Ti}-\mathrm{B}$ master alloys, excess Ti becomes solute in the liquid ( $2.88 \mathrm{wt} \%$ for $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ ) before $\mathrm{Al}_{3} \mathrm{Ti}$ solidification, and raises the Ti chemical potential. The range of Ti chemical potential during $\mathrm{Al}_{3} \mathrm{Ti}$ solidification is calculated in section 3.3.2, from which we can determine the stable terminations for the $\mathrm{TiB}_{2}\{0001\}$ and $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ in interface slabs.

Table 3.2 DFT calculated surface energy with comparison to published work

| Surface | Relaxed surface energy $\sigma\left(\mathrm{J} / \mathrm{m}^{2}\right)$ |  |  |  |
| :--- | :--- | :--- | :--- | :--- |
|  |  | First method | Second method | Published work |
| $\mathrm{Al}_{3} \mathrm{Ti}(112)$ | 1.48 | 1.49 | $1.563[214]$ |  |
| $\mathrm{Al}_{3} \mathrm{Ti}(100)$ | 1.80 | 1.79 | - |  |
| $\mathrm{Al}_{3} \mathrm{Ti}(001)$ | Al termination | $1.20-1.78$ | $1.22-1.79$ | $1.22-1.78[214]$ |
|  | Al+Ti termination | $2.36-1.79$ | $2.37-1.80$ | $2.41-1.83[214]$ |
| $\mathrm{TiB}_{2}(0001)$ | Ti termination | $5.39-2.19$ | $5.39-2.20$ | $5.47-2.23[85]$ |
|  | B termination | $2.95-6.14$ | $2.94-6.13$ | $2.99-6.23[85]$ |

### 3.3 Results and discussion

### 3.3.1 Three preferred ORs between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$

$\mathrm{Al}_{3} \mathrm{Ti}$ crystals extracted by selective etching of the Al-5Ti-1B master alloy are shown in Figure 3.3(a) and (b). They have the same morphology as in Ref [65]. The unit cell wireframe in Figure 3.3(a) was plotted using the Euler angles from EBSD performed directly on the facets of the extracted crystal, and confirms that the main facets are $\{001\}$ and $\{101\}$. Figure 3.3 (c) shows typical small $\mathrm{TiB}_{2}$ hexagonal plates with $\{0001\}$ and $\{1 \overline{1} 00\}$ facets on the $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ facets with $\mathrm{Al}_{3} \mathrm{Ti}$ ledges surrounding them. Similar $\mathrm{Al}_{3} \mathrm{Ti}^{\text {and }} \mathrm{TiB}_{2}$ crystals were also found in the Al-3Ti-1B master alloy. Figure 3.3(d)-(f) are crystals etched out from the re-cast $\mathrm{Al}-3 \mathrm{Ti}-1 \mathrm{~B}$ alloy. The $\mathrm{Al}_{3} \mathrm{Ti}$ crystal now has a faceted dendritic morphology similar to Ref. [65] with a major $\{001\}$ facet and $\{100\}$ edges. On the $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ surface, $\mathrm{Al}_{3} \mathrm{Ti}$ growth ledges can be seen around the hexagonal $\mathrm{TiB}_{2}$ platelets (Figure 3.3(f)).


Figure 3.3 Typical $\mathrm{Al}_{3}$ Ti and $\mathrm{TiB}_{2}$ crystal morphologies after selective etching of the $\alpha$-Al matrix. (a)-(c) were extracted from the Al-5Ti-1B master alloy. (d)-(f) were extracted from the re-cast Al-3Ti-1B master alloy. Kikuchi patterns were obtained from EBSD directly on the extracted crystals from which the facets, directions and unit cell wireframes were plotted.

Figure 3.4(a)-(g) and (h)-(n) show the same OR measured between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ in $\mathrm{Al}-3 \mathrm{Ti}-1 \mathrm{~B}$ master alloy and re-cast Al-3Ti-1B alloy. In Figure 3.4(a) and (h) $\mathrm{TiB}_{2}$ particles are on the $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ surfaces, with similar growth ledges as in Figure 3.3(c) and (f). EBSD patterns from these two phases are shown in Figure 3.4(b)-(c) and (i)-(j), and selected parallel planes and directions are indexed in Figure 3.4(d)-
(e) and (k)-(I), respectively. Pole figures for these parallel planes and directions of these two crystals are superimposed in Figure $3.4(\mathrm{f})$ and $(\mathrm{m})$. It can be seen that the $\{001\}_{\mathrm{Al} 3 \mathrm{Ti}}$ is near-parallel with $\{0001\}_{\text {TiB2 }}$ and one of the $\langle 110\rangle_{\text {Al3тi }}$ is near-parallel with one of the $\langle 11 \overline{2} 0\rangle_{\text {TiB2 }}$. The OR can be written as:

$$
\{001\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB} 2}, \text { with }<110>_{\mathrm{Al} 3 \mathrm{Ti}} \|<11 \overline{2}_{0}>_{\mathrm{TiB} 2} \text { (OR2) } \quad \text { Equation } 3.7
$$



Figure 3.4 Typical TiB2 particles on the $A I_{3} T i\{001\}$ surface with OR2. (a)-(g) are from the AI-3Ti-1B master alloy. (h)-(n) are from re-cast Al-3Ti-1B. The two phases are marked in red and blue. (b)-(c) and (i)-(j) are Kikuchi patterns from the $\mathrm{TiB}_{2}$ and $\mathrm{Al}_{3} T i$ crystals in (a) and (h). In (d)-(e) and (k)-(l) selected parallel planes and directions are indexed on the Kikuchi patterns. ( $f$ ) and ( $m$ ) are superimposed pole figures of parallel planes and directions of these two phases. $(g)$ and ( $n$ ) show unit cell wireframes of the two crystals with highlighted parallel planes and directions.

Note that this OR is different from OR1 in the introduction. EBSD analysis of $580 \mathrm{TiB}_{2}$ particles sharing an interface with $\mathrm{Al}_{3} \mathrm{Ti}$ in the $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ and $\mathrm{Al}-3 \mathrm{Ti}-1 \mathrm{~B}$ master alloys identified three preferred ORs between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$. Figure 3.5 is an example of a single $\mathrm{Al}_{3} \mathrm{Ti}_{\text {c crystal with multiple } \mathrm{TiB}_{2} \text { inside where }}$ all three ORs are present. In Figure 3.5 there are two $\mathrm{TiB}_{2}$ particles having each OR with the $\mathrm{Al}_{3} \mathrm{Ti}$ in this cross section, where each OR is marked as a triangle(OR1), diamond(OR2) and rectangle(OR3) in Figure 3.5(b), respectively. Pole figures showing parallel planes and directions in each OR are plotted in Figure 3.5(c)-(e), together with the unit cell wireframes below. In addition to OR1 and OR2 written previously, the third OR can be written as:

$$
\{100\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB} 2}, \text { with }<010>_{\mathrm{Al} 3 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB} 2}(O R 3) \quad \text { Equation } 3.8
$$



Figure 3.5. Multiple TiB2 particles sharing different ORs with an $\mathrm{Al}_{3}$ Ti crystal. (a) Backscattered electron image of a typical $\mathrm{Al}_{3} \mathrm{Ti}$ crystal in Al-5Ti-1B with multiple TiB ${ }_{2}$ particles embedded inside. (b) EBSD phase map of the $\mathrm{Al}_{3}$ Ti crystal in (a). Blue is $\mathrm{Al}_{3}$ Ti. Red is $\mathrm{TiB}_{2}$. (c) Two $\mathrm{TiB}_{2}$ particles marked with triangles in (b) sharing OR1 with the $\mathrm{Al}_{3}$ Ti. (d) Two TiB2 particles in diamonds in (b) sharing OR2 with the $\mathrm{Al}_{3} T \mathrm{Ti}$. (e) Two TiB2 particles in rectangles in (b) sharing OR3 with the $\mathrm{Al}_{3} \mathrm{Ti}$.

Among all $580 \mathrm{TiB}_{2}$ particles analysed in the Al-5Ti-1B and Al-3Ti-1B master alloys, 33 had OR1, 49 had OR2 and 9 had OR3 when the maximum deviation for parallelism was set as $5^{\circ}$. The ORs between these $\mathrm{TiB}_{2}$ and $\mathrm{Al}_{3} \mathrm{Ti}$ are projected into pole figures in Figure 3.6. In each OR , because there are three different $\langle 11 \overline{2} 0\rangle$ directions in $\mathrm{TiB}_{2}$ with $120^{\circ}$ between them, the three corresponding $\mathrm{Al}_{3}$ Ti directions cannot be strictly parallel to the three $<11 \overline{2} 0>$ at the same time. However, the angle between these three $\mathrm{Al}_{3} \mathrm{Ti}$ directions are close to $120^{\circ}$ (the difference is $<5^{\circ}$ ), so it is reasonable to compare their deviations in pole figures in this way. The standard deviations from the three ORs are small and closer examination indicates that the parallelism of the interfacial planes is tighter than the directions at the
interface for all three ORs. The relative geometry of the two crystals in terms of unit cells and crystal morphology (habit) for the three ORs are plotted at the bottom of Figure 3.6 for clarity.

For simplicity through the whole analysis in this chapter we set the deviation angle between the parallel planes and directions to be less than $5^{\circ}$ as the threshold for the 3ORs. A more rigorous criterion is to characterise ORs using a deviation from the ideal OR based misorientation matrix. This can be written in terms of an axis-angle, and from this the OR can be tested using an angular tolerance. In this case, the number of OR2 changes slightly from 49 to 45 , while the number of OR1 and OR3 stay the same.


Figure 3.6. Summary of the three ORs between $580 \mathrm{TiB}_{2}$ particles and $132 \mathrm{Al}_{3} \mathrm{Ti}$ crystals. Orientations of $\mathrm{Al}_{3} \mathrm{Ti}$ are projected onto pole figures with respect to the orientations of TiB $\mathrm{B}_{2}$ for (a) OR1, (b) OR2 and (c) OR3. Red circles are $\{0001\}_{\text {TiB2 }}$, red triangles are $\left\langle 11 \overline{2} 0>_{\text {TiB2 }}\right.$ and equivalent blue symbols are the corresponding planes and directions of $\mathrm{Al}_{3}$ Ti in each OR. The relative geometry of the unit cells and the
crystal morphology of the two crystals in each OR are plotted underneath, with parallel planes and directions highlighted.

Considering the thin plate-like hexagonal shape of $\mathrm{TiB}_{2}$ in the master alloy rods, the $\{0001\}$ is the main facet that forms interfaces with $\mathrm{Al}_{3} \mathrm{Ti}$ crystals. To explore the reproducibility of interfaces between $\mathrm{Al}_{3} \mathrm{Ti}$ and the $\mathrm{TiB}_{2}\{0001\}$ facet, the direction of $\{0001\}$ is projected into an $\mathrm{Al}_{3} \mathrm{Ti}$ inverse pole figure in Figure 3.7(a) for $278 \mathrm{TiB}_{2}$ particles in the $\mathrm{Al}_{3} \mathrm{Ti}$ interior and $302 \mathrm{TiB}_{2}$ particles on the $\mathrm{Al}_{3} \mathrm{Ti}$ surface. For $\mathrm{TiB}_{2}$ that was totally engulfed inside, three planes in $\mathrm{Al}_{3} \mathrm{Ti}:\{112\},\{001\}$ and $\{100\}$, are preferred to form contact planes with the $\mathrm{TiB}_{2}\{0001\}$ facet, corresponding to the three ORs we discovered above. While for $\mathrm{TiB}_{2}$ on the $\mathrm{Al}_{3} \mathrm{Ti}$ surface, according to the contour figure, only one of the three contact planes is preferred: $\{001\}_{\text {Al3ті }}| |\{0001\}_{\text {TiB2 }}$. The percentage of these three contact planes and ORs are plotted for interior $\mathrm{TiB}_{2}$ and surface $\mathrm{TiB}_{2}$ in Figure 3.7(b) and the statistical data is listed in Table 3.3. In Figure 3.7(b), note that cross-hatched regions refer to the full OR (parallel plane and parallel direction) whereas coloured regions refer only to the contact plane (parallel plane only).


Figure 3.7. (a) Projection of $\{0001\}_{\text {TiB2 }}$ into the inverse pole figure of $\mathrm{Al}_{3}$ Ti for $278 \mathrm{TiB}_{2}$ particles fully embedded inside and $302 \mathrm{TiB}_{2}$ particles on the $\mathrm{Al}_{3}$ Ti surface. (b) Percentage of different $\mathrm{Al}_{3} \mathrm{Ti}$-TiB $\mathrm{B}_{2}$ interfaces for $\mathrm{TiB}_{2}$ particles embedded inside and on the surface $\mathrm{Al}_{3}$ Ti. Note that cross-hatched regions are for orientation relationships (parallel plane and direction) whereas colour-only regions are for parallel planes only.

In Figure $3.7(\mathrm{~b})$, for $\mathrm{TiB}_{2}$ inside $\mathrm{Al}_{3} \mathrm{Ti}$, the $\{112\}_{\mathrm{Al3} \mathrm{Ti}}| |\{0001\}_{\mathrm{TiB2} 2}$ contact plane (the grey region) and the related OR1 (the grey cross-hatched region) are dominant. The third contact plane $\{100\}_{\text {Al3тi }} \|$ $\{0001\}_{\text {TiB2 }}$ (the orange region) has higher occurrence frequency than the second one $\{001\}_{\text {Al3тi }} \|$ $\{0001\}_{\text {TiB2 }}$ (the blue region) when $\mathrm{TiB}_{2}$ is fully embedded inside $\mathrm{Al}_{3} \mathrm{Ti}$. On the contrary, for $\mathrm{TiB}_{2}$ on the $\mathrm{Al}_{3} \mathrm{Ti}$ surface, the second contact plane (blue), together with OR2 (the blue cross-hatched region),
becomes significantly preferred, and only few $\mathrm{TiB}_{2}$ with OR1 (the grey cross-hatched region) and none with OR3 (the orange cross-hatched region) were observed.

Table 3.3 The statistical data for the parallelism between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ particles within $5^{\circ}$

| Interior $\mathrm{TiB}_{2}$ | Number of $\mathrm{Al}_{3} \mathrm{Ti}$ | Number of TiB ${ }_{2}$ | $\{112\}_{\text {A\|3Ti }} \mid$ \| 00001$\}_{\text {TiB2 }}$ | $\{001\}_{\text {A\|3Ti }} \mid$ \| 00001$\}_{\text {TiB2 }}$ | $\{100\}_{\text {Alıit }} \mid$ [ 00001$\}_{\text {Tiв2 }}$ | Other |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  |  |  | 57 (20.5\%) | 11 (4.0\%) | 23 (8.3\%) |  |
|  | 100 | 278 | $\langle 1 \overline{1} 0\rangle_{\text {A\|3тi }}\|<11 \overline{2} 0\rangle_{\text {TiB2 }}$ (OR1) | $\left.<110>_{\text {A } 13 \text { Ti }}\| \|<11 \overline{2} 0\right\rangle_{\text {TiB2 }}$ (OR2) | $\left.<010\rangle_{\mathrm{A} \mid 3 \mathrm{Ti}}\| \|<11 \overline{2} 0\right\rangle_{\text {TiB2 }}$ (OR3) | 67.2\% |
|  |  |  | 30 (10.8\%) | 5 (1.8\%) | 9 (3.2\%) |  |
| Surface $\mathrm{TiB}_{2}$ | Number of $\mathrm{Al}_{3} \mathrm{Ti}$ | Number of TiB ${ }_{2}$ | $\{112\}_{\text {A\|BTi }} \mid$ \| 00001$\}_{\text {TiB2 }}$ | $\{001\}_{\text {A\|3Ti }} \mid$ \| 00001$\}_{\text {TiB2 }}$ | $\{100\}_{\text {Al3T }} \mid$ \| 00001$\}_{\text {TiB2 }}$ | Other |
|  |  |  | 11 (3.6\%) | 79 (26.2\%) | 3 (1.0\%) | 69.2\% |
|  | 32 | 302 | $\left\langle 1 \overline{1} 0>_{\text {A13ті }}\right\| \mid<11 \overline{2} 0>_{\text {TiB2 }}$ (OR1) | $<110>_{\text {A } 13 \text { Ti }}\| \|<11 \overline{2} 0>_{\text {TiB2 }}$ (OR2) | $\left.<010>_{\text {AI3Ti }}\| \|<11 \overline{2} 0\right\rangle_{\text {TiB2 }}$ (OR3) |  |
|  |  |  | 3 (1\%) | 44 (14.6\%) | 0 |  |

### 3.3.2 DFT calculations of interfacial energy for 3ORs

In DFT calculations, the surface and interfacial energies are usually related to the chemical potential of the relevant element in the melt [84, 214, 218-220]. To determine the Ti chemical potential corresponding to the composition in Al-5Ti-1B master alloy, thermodynamic calculations were performed in Thermo-Calc using the Ti database and the results are shown in Figure 3.8. Figure 3.8(a) is the Al-Ti phase diagram at the Al rich side. For the Al-5Ti-1B master alloy, the Ti concentration in the melt is $2.88 \mathrm{wt} \%\left(1005^{\circ} \mathrm{C}\right)$ before $\mathrm{Al}_{3} \mathrm{Ti}$ nucleates if we consider $\mathrm{TiB}_{2}$ to be insoluble in liquid Al . With the nucleation and growth of $\mathrm{Al}_{3} \mathrm{Ti}$, the Ti content within the liquid decreases along the liquidus line until it reaches the minimum level, $0.13 \mathrm{wt} \%$, at the peritectic temperature $\left(665^{\circ} \mathrm{C}\right)$. Figure $3.8(\mathrm{~b})$ shows the change of Ti chemical potential along the liquidus line from $1005^{\circ} \mathrm{C}$ to $665^{\circ} \mathrm{C}$ : the range of $\left(\mu_{T i}^{s l a b}-\mu_{T i}^{b u l k}\right)$ lies between $-88 \mathrm{~kJ} / \mathrm{mol}$ and $-115 \mathrm{~kJ} / \mathrm{mol}$. The value of $\left(\mu_{T i}^{s l a b}-\mu_{T i}^{b u l k}\right)$ is calculated from Thermo-Calc through chemical activity:

$$
\begin{equation*}
a_{T i}=\exp \left(-\frac{\mu_{T i}^{S l a b}-\mu_{T i}^{b u l k}}{R T}\right) \tag{Equation 3.9}
\end{equation*}
$$

Therefore, when $\mathrm{Al}_{3} \mathrm{Ti}$ is first stable, $\left(\mu_{T i}^{\text {slab }}-\mu_{T i}^{\text {bulk }}\right)$ is $-88 \mathrm{~kJ} / \mathrm{mol}$, and the value decreases on cooling with Ti depletion in the melt. After applying this chemical potential range to the calculated surface energies in Figure 3.1, the Ti terminated $\mathrm{TiB}_{2}\{0001\}$ and Al terminated $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ are energetically favourable during $\mathrm{Al}_{3} \mathrm{Ti}$ solidification, and we will only consider these two terminations for $\mathrm{TiB}_{2}\{0001\}$ and $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ when performing interface calculations.


Figure 3.8. (a) Al-rich side of the AI-Ti phase diagram from the Thermo-Calc database TCTI2 version 2.0. (b) Chemical potential of Ti in the AI-Ti melt along the $\mathrm{Al}_{3}$ Ti liquidus line.

Figure $3.9(\mathrm{a})$ shows the interface slab model for OR1 $\left((112)_{\mathrm{Al} 3 \mathrm{Ti}}| |(0001)_{\mathrm{TiB2} 2}\right.$ with $\left.[1 \overline{1} 0]_{\mathrm{A} \mid 3 \mathrm{Ti}}| |[11 \overline{2} 0]_{\mathrm{TiB2} 2}\right)$. The calculated interfacial energy for OR1 as a function of chemical potential is plotted in grey line in Figure 3.9(b). Due to the different DFT codes used for the calculation, the current result of OR1 is about $0.14 \mathrm{~J} / \mathrm{m}^{2}$ lower than Wearing's study [85]. This is a typical difference magnitude between DFT studies; for example Wearing's study has a difference of $0.13-0.21 \mathrm{~J} / \mathrm{m}^{2}$ in $\mathrm{Al} / \mathrm{TiB}_{2}$ interfacial energy with Ref.[84]. The DFT results for the other two ORs are also plotted in blue and orange lines in Figure 3.9(b). At the early stage of solidification, OR1 has the lowest energy, and it has the highest frequency for the interior $\mathrm{TiB}_{2}$ particles in Figure 3.7(b), while OR3 has much higher interfacial energy than OR1 and OR2 and yet was commonly observed for the interior $\mathrm{TiB}_{2}$. Moreover, there is a significant preference of OR2 when $\mathrm{TiB}_{2}$ is on the $\mathrm{Al}_{3}$ Ti surface (Figure $3.7(\mathrm{~b})$ ), despite OR1 having the lowest
interfacial energy over most of the $\mathrm{Al}_{3} \mathrm{Ti}$ solidification range. This shows that factors in addition to interfacial energy play a key role in the formation of ORs and contact planes between $\mathrm{TiB}_{2}$ particles and $\mathrm{Al}_{3} \mathrm{Ti}$ during $\mathrm{Al}_{3} \mathrm{Ti}$ nucleation and growth.


Figure 3.9. DFT calculations on $\mathrm{Al}_{3}$ Ti-TiB $B_{2}$ interfaces. (a) Interface slab model for OR1. (b) Interfacial energy of the three ORs versus Ti chemical potential. (c) Interface projection of the three ORs: unstrained, strained before DFT calculation (the strain is calculated referred to OK), and relaxed after DFT calculation. Red triangles are Ti atoms in $\mathrm{TiB}_{2}$, blue triangles and circles are Ti and Al atoms in $\mathrm{Al}_{3} \mathrm{Ti}$.

Figure 3.9(c) are plots of the atomic positions in the interface projection of the slab models for the three ORs before and after relaxation using DFT. The first row shows the unstrained lattice matching, and OR1 has the best atomic matching in the three ORs. In order to apply periodic boundary conditions, $\mathrm{Al}_{3} \mathrm{Ti}$ has been strained to match the unit cell parameters of the stiffer $\mathrm{TiB}_{2}$ phase at the interface in each case, as shown in second row. For OR1 before atomic relaxation, the Al and Ti atoms in $\mathrm{Al}_{3} \mathrm{Ti}$ are sitting on top of Ti atoms in $\mathrm{TiB}_{2}$, while after the calculation all atoms in $\mathrm{Al}_{3} \mathrm{Ti}$ moved to the vacant centre of Ti atoms in $\mathrm{TiB}_{2}$, which is the expected stacking sequence for close packing. For OR2 before the calculation, Al atoms sit on top of or in the vacant centre between Ti atoms of $\mathrm{TiB}_{2}\{0001\}$, and their positions do not change after the calculation, indicating the input arrangement is very close to the lowest energy geometry for this interface. For OR3, a large input model was required due to the relatively poor lattice matching at the interface, which partially explains its high interfacial energy compared to the other two ORs. After DFT calculation of this interface the overall movement of atoms in $\mathrm{Al}_{3} \mathrm{Ti}$ seems to have the tendency to fill the vacant gaps between the Ti atoms in $\mathrm{TiB}_{2}$.

We note that the DFT interfacial energy values refer to OK which will not be identical to the values at elevated temperatures. However, experimentally measured interfacial energies have been shown to follow the same trend as the OK DFT calculated energies [221]. Moreover, thermal expansion at elevated temperature (e.g. 800K) changes the lattice parameters for $\mathrm{Al}_{3} \mathrm{Ti}$ [222] and $\mathrm{TiB}_{2}$ [203] by less than $1 \%$, and the changes of strain at the calculated interfaces are less than $0.8 \%$. Therefore, the 0 K calculated interfacial energy can be used as a useful approximant to the real value in this work, especially since our main goal here is a comparison between different ORs.

### 3.4 Identification of OR formation mechanisms

To understand the mechanisms that lead to the formation of the preferred contact planes and OR1, OR2 and OR3, we next study OR formation by (1) characterising small $\mathrm{Al}_{3} \mathrm{Ti}$ crystals that solidified on the facets of large $\mathrm{TiB}_{2}$, (2) examining the microstructures (similar to Figure 3.3-Figure 3.5) around $\mathrm{TiB}_{2}$ particles on the $\mathrm{Al}_{3} \mathrm{Ti}$ surfaces and embedded within $\mathrm{Al}_{3} \mathrm{Ti}$, and (3) calculating the interfacial energy at different rotation angles on the three contact planes and comparing the results with the measured occurrence frequencies.

### 3.4.1 Nucleation OR between $\mathrm{TiB}_{2}$ and $\mathrm{Al}_{3} \mathrm{Ti}$

 of each $\mathrm{TiB}_{2}$ plate, as shown in the example in Figure 3.10(a). EBSD orientation map is shown in Figure 3.10(b), where the 11 labelled $\mathrm{Al}_{3} \mathrm{Ti}$ crystals attached to a single $\mathrm{TiB}_{2}$ crystal have six different orientations which correspond to the six crystallographic variants of OR1 with the $\mathrm{TiB}_{2}$ plate. Their Kikuchi patterns, plotted in Figure 3.10(c), share many similarities, especially between $1 \& 4 \& 6(2 \& 3 \& 5)$, but there are also some clear differences in terms of the relative intensity and angle between certain bands which enable correct indexing of the orientations. The presence of six variants of OR1 can be seen in the pole figures by noting that, for each of the $\mathrm{Al}_{3} \mathrm{Ti}$ grains, one of the $\{112\}_{\text {Al3тi }}$ planes is parallel to the $\{0001\}_{\text {TiB2 }}$ plane and one of the $\langle 110\rangle_{\text {Al3Ti }}$ directions is parallel to one of the $\langle 11 \overline{2} 0\rangle_{\text {TiB2 }}$, and all permutations are present.

Figure $3.10(\mathrm{~d})$ shows a typical $\mathrm{TiB}_{2}$ plate with multiple small $\mathrm{Al}_{3} \mathrm{Ti}$ on the $\{0001\}_{\mathrm{TiB2}}$ surface after selectively etching the $\alpha$-Al matrix. Their unit cells are plotted in Figure 3.10(e) from the measured Euler angles and there are in total six different orientations of the $\mathrm{Al}_{3} \mathrm{Ti}$ crystals, each corresponding to a variant of OR1. In Figure $3.10(f)$ all six orientations share a common $\{112\}_{\text {AI3Ti }}$ plane that is parallel to the $\{0001\}_{\text {Tiв2. }}$. Every two orientations share a common $\langle 110\rangle_{\text {Al3тi }}$ direction, and all three shared $\langle 110\rangle_{\text {Al3Ti }}$ directions are parallel to three $\langle 11 \overline{2} 0\rangle_{\text {TiB2 }}$. The other $\langle 110\rangle_{\text {Al3тi }}$ direction from each orientation forms a combined 6 -fold symmetry around the common $\{112\}_{\text {AI3ті }}$ plane. The small angle
between the other $\{112\}_{\text {AI3тi }}$ planes is because there is no threefold symmetry on the $\{112\}_{\text {Al3тi }}$ plane since $c / a \neq 2$ for $\mathrm{Al}_{3} \mathrm{Ti}$. The six $\mathrm{Al}_{3} \mathrm{Ti}$ unit cells are plotted with the $\mathrm{TiB}_{2}$ unit cell in Figure 3.10(g) using the measured Euler angles, where the combined 6-fold symmetry of $\mathrm{Al}_{3}$ Ti comes from the hexagonal $\mathrm{TiB}_{2}$ basal plane.

(g)


Figure 3.10. Nucleation of small $\mathrm{Al}_{3}$ Ti on large $\mathrm{TiB}_{2}$ crystals (a) SEM image of multiple $\mathrm{Al}_{3}$ Ti crystals on a cross sectioned $T i B_{2}$ (0001) surface. (b) EBSD orientation map of the $A l_{3} T i$ and $T i B_{2}$ crystals in (a). (c) Kikuchi patterns and Euler angles for the $\mathrm{TiB}_{2}$ and six $\mathrm{Al}_{3} \mathrm{Ti}$ orientations in (b), together with pole figures showing $\{0001\}_{\text {TiB2 }}$ || $\{112\}_{A 13 T i}$ with $<11 \overline{2} 0>| |<1 \overline{1} 0>$ (OR1) for all six $\mathrm{Al}_{3}$ Ti orientations. (d) Another $\mathrm{TiB}_{2}$ particle with multiple $\mathrm{Al}_{3}$ Ti crystals on the \{0001\} facet after selective etching of $\alpha-A I$. (e) Magnified region from (d), with $\mathrm{TiB}_{2}$ and $A l_{3}$ Ti unit cell wireframes plotted showing six different $A l_{3}$ Ti orientations.
(f) $\{0001\}$ and $<11 \overline{2} 0>$ pole figures of $T i B_{2}$ and superimposed $\{112\}$ and $<110>$ pole figures of all six $\mathrm{Al} \mathrm{I}_{3} \mathrm{Ti}$ orientations in (e) showing all $\mathrm{Al}_{3}$ Ti have OR1. (g) All six $\mathrm{Al}_{3}$ Ti unit cell wireframes plotted with the $\mathrm{TiB}_{2}$ unit cell wireframe in (e), with parallel planes and directions highlighted.

From Figure 3.10 it is known that $\mathrm{Al}_{3} \mathrm{Ti}$ crystals on the $\mathrm{TiB}_{2}\{0001\}$ surface can have six different orientations, each a variant of OR1 with the $\mathrm{TiB}_{2}$ plate, and many $\mathrm{Al}_{3} \mathrm{Ti}$ crystals have the same orientation even when they are geometrically far away, strongly indicating that they each nucleate on the $\mathrm{TiB}_{2}\{0001\}$ surface independently. 27 out of $28 \mathrm{Al}_{3} \mathrm{Ti}$ crystals that shared an interface with large $\mathrm{TiB}_{2}$ crystals had OR1 and none had OR2 or OR3. These combined findings prove that OR1 is the $\mathrm{Al}_{3} \mathrm{Ti}-$ $\mathrm{TiB}_{2}$ nucleation OR. This is consistent with OR1 having the lowest interfacial energy when $\left(\mu_{T i}^{s l a b}-\right.$ $\mu_{T i}^{b u l k}$ ) is $-101 \mathrm{~kJ} / \mathrm{mol}$ at $846^{\circ} \mathrm{C}$ (the $\mathrm{Al}_{3} \mathrm{Ti}$ liquidus temperature of $\mathrm{Al}-0.8 \mathrm{Ti}$ ) as shown in Figure 3.9 (b). The other $\mathrm{Al}_{3} \mathrm{Ti}$ crystals without OR1 are the grey coloured $\mathrm{Al}_{3} \mathrm{Ti}$ crystals at the top of Figure $3.10(\mathrm{~b})$. Most of them (7 out of 8) do not share an interface with the $\mathrm{TiB}_{2}$ plate, and none of them have a simple or reproducible OR with the $\mathrm{TiB}_{2}$, indicating they may be $\mathrm{Al}_{3} \mathrm{Ti}$ crystals that fell (settled) into the surface during solidification.

In Figure 3.5 more than one $\mathrm{TiB}_{2}$ particle has OR1 with the same $\mathrm{Al}_{3}$ Ti single crystal, which indicates that measuring a simple OR to a particle within a crystal does not equate to identifying a nucleant particle or a nucleation OR. The nucleation experiment presented here of growing a $\mathrm{TiB}_{2}$ particle to a large size and solidifying small droplets of $\mathrm{Al}_{3} \mathrm{Ti}$ on a large $\mathrm{TiB}_{2}$ particle made the nucleant clear and isolated the nucleation OR from other mechanisms.

In order to estimate the probability of sectioning the $\mathrm{TiB}_{2}$ nucleant particle on an $\mathrm{Al}_{3} \mathrm{Ti} 2 \mathrm{D}$ random surface, a digital sectioning calculation was performed. As shown in Figure $3.11(\mathrm{a}), \mathrm{Al}_{3} \mathrm{Ti}$ is set to be a $50 * 50 * 20 \mu \mathrm{~m}$ plate while $\mathrm{TiB}_{2}$ is designated to be a hexagonal plate with side 500 nm and thickness

200 nm , similar to our experiments. A stochastic point O in $\mathrm{Al}_{3} \mathrm{Ti}$ is set to be the origin of the Cartesian coordinate system and $\mathrm{O}^{\prime}$ is the geometric centre of the $\mathrm{TiB}_{2}$ particle. $\mathrm{O}^{\prime}$ is limited in the $10^{*} 10^{*} 10 \mu \mathrm{~m}$ blue cubic space located at the centre of the $\mathrm{Al}_{3} \mathrm{Ti}$ because the nucleant is usually near the centre of the growing crystal. The XY plane is set to be the sectioning plane. In Figure 3.11(b), $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ are rotated under the stochastic Euler angles and by examining the coordinates of the $12 \mathrm{TiB}_{2}$ corners, it can be determined if the $\mathrm{TiB}_{2}$ is crossed by the sectioning plane.

Table 3.4 shows the number of sectioning planes and how many of them contain the $\mathrm{TiB}_{2}$ nucleant. With increasing the number of sectioning planes, the probability of sectioning the nucleant becomes stable at about $2.5 \%$. Thus, for the $100 \mathrm{Al}_{3} \mathrm{Ti} 2 \mathrm{D}$ cross sections we studied (Table 3.3), the $\mathrm{TiB}_{2}$ nucleant particle is only likely to have been sectioned in 2-3 $\mathrm{Al}_{3} \mathrm{Ti}$ crystals and the remaining 28-27 (out of 30) $\mathrm{TiB}_{2}$ particles in Table 3.3 are likely to have developed OR1 by other mechanisms (discussed in the next section). Therefore, there is an underlying difficulty of identifying the particle that triggered nucleation or determining the nucleation $O R$ in a random 2 D cross section.


Figure 3.11. Model for the digital sectioning experiment (a) before rotation and (b) after rotation.
Table 3.4 The chances of sectioning $T i B_{2}$ nucleant

| Number of sections | Number of section planes containing TiB ${ }_{2}$ | Chances of sectioning TiB B $_{2}$ nucleant (\%) |
| :---: | :---: | :---: |
| 100 | 0 | 0 |
| 1000 | 26 | $2.6 \%$ |
| 10,000 | 256 | $2.56 \%$ |
| 100,000 | 2486 | $2.48 \%$ |
| 1000,000 | 25148 | $2.51 \%$ |

### 3.4.2 Pushing \& Engulfment on contact planes during $\mathrm{Al}_{3} \mathrm{Ti}$ growth

Since $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ are both significantly denser than the liquid and will have different settling rates due to their different sizes and densities, $\mathrm{TiB}_{2}$ particles are likely to come into contact with growing $\mathrm{Al}_{3} \mathrm{Ti}$ crystals as they both settle in the melt. From the relative crystal morphology (habit) of these two crystals drawn at the bottom of Figure 3.6 , the basal plane of $\mathrm{TiB}_{2}$ is likely to land on and then be continuously pushed by $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ facets. Figure $3.7(\mathrm{~b})$ shows that, the second contact plane $\{001\}_{\mathrm{Al} 3 \mathrm{Ti}}$ || $\{0001\}_{\text {TiB2 }}$ (blue) is most common (26.2\%) on the $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ surface, and less common (4.0\%) inside $\mathrm{Al}_{3}$ Ti crystals. Micrographs of both situations are shown in Figure 3.12(a) and (b) respectively. It can be seen in the cross-section of Figure $3.12(\mathrm{a})$ that the growth front of $\mathrm{Al}_{3} \mathrm{Ti}$ is curved and has a depression containing the $\mathrm{TiB}_{2}$ particles. The view from above after selective etching of $\alpha$ - Al in Figure 3.12(c) shows that this depression consists of multiple $\mathrm{Al}_{3} \mathrm{Ti}$ ledges around the $\mathrm{TiB}_{2}$ particles, the same as observed in Figure 3.3 and Figure 3.4.


Figure 3.12. Pushing and engulfment of $\mathrm{TiB}_{2}$ on the $\{001\}_{A I 3 T i}$ facet. (a) $\mathrm{TiB}_{2}$ particle on an $\mathrm{Al}_{3} \mathrm{Ti}$ surface with $\{001\}_{A 13 T i}$ | $\{0001\}_{T i B 2}$ in cross section, superimposed with the unit cell wireframes from EBSD. (b) $\mathrm{TiB}_{2}$ particle fully embedded underneath the $\mathrm{Al}_{3} T \mathrm{Ti}\{001\}$ surface with $\{001\}_{\text {Al3Ti }}$ || \{0001\} $\}_{\text {TiB2 }}$ in cross section, superimposed with the unit cell frames from EBSD. (c)-(e) TiB particles on the $\mathrm{Al}_{3} T i\{001\}$ facet being gradually engulfed. (f) Schematic illustration of the pushing and engulfment process of a TiB2 particle leading to $\{001\}_{\text {A13тi }}$ || \{0001 $\}_{\text {TiB2 }}$ contact planes and OR2.

The concave $\mathrm{Al}_{3} \mathrm{Ti}$ interface around $\mathrm{TiB}_{2}$ particles is expected to be promoted by impeded solute diffusion since, when the flat $\mathrm{Al}_{3}$ Ti facet grows and starts to push a $\mathrm{TiB}_{2}$ plate, there will be a thin gap (several to tens of atomic radii $[91,92,223,224]$ ) between them where it is difficult for the rejected Al solute from the $\mathrm{Al}_{3} \mathrm{Ti}$ growth front to diffuse away, causing the $\mathrm{Al}_{3} \mathrm{Ti}$ growth rate behind the $\mathrm{TiB}_{2}$ to be slower than the $\mathrm{Al}_{3} \mathrm{Ti}$ region around it. Consequently, the $\mathrm{Al}_{3} \mathrm{Ti}$ front is depressed near the pushed $\mathrm{TiB}_{2}$ particle and the ledges are formed due to its faceted growth mechanism. At some point, if the growth rate of the $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ facet exceeds a certain value, it will grow out over the $\mathrm{TiB}_{2}$ particle and engulf it gradually, as shown from Figure 3.12(c)-(e), and that critical velocity corresponds to the pushing-engulfment transition [224]. Eventually some $\mathrm{TiB}_{2}$ particles will be totally engulfed and a small amount of liquid Al is likely to be sealed in front of $\mathrm{TiB}_{2}$ plates and become $\alpha-\mathrm{Al}$ islands after solidification, as shown in Figure 3.12(b). Figure 3.12(f) illustrates the whole process from pushing to engulfment, together with the formation of $\mathrm{Al}_{3} \mathrm{Ti}$ ledges around $\mathrm{TiB}_{2}$ at the beginning and the formation of an $\alpha-\mathrm{Al}$ island at the end. The $\mathrm{Al}_{3}$ Ti growth ledges surrounding $\mathrm{TiB}_{2}$ particles in $\mathrm{Al}-3 \mathrm{Ti}-\mathrm{B}$ (Figure 3.4(a)) and Al-5Ti-B (Figure 3.12(a)) master alloys and re-cast Al-3Ti-B (Figure 3.4(h)) provide new information of the pushing process. Such a concave growth front has been mathematically expected in past pushing and engulfment theories and models [92, 104, 106, 107, 225, 226], and our imaging provides direct proof of this. For $\mathrm{TiB}_{2}$ particles that have been engulfed, the $\alpha$-Al island at one side is another proof for the engulfment process. A similar liquid pool has also been proposed in the previous literature $[225,226]$, and it is clear through our imaging that it was formed during engulfment.

Figure 3.13 (a) shows a similar $\alpha$-Al island in front of a $\mathrm{TiB}_{2}$ plate with the third contact plane: $\{100\}_{\mathrm{A} 13 \mathrm{Ti}}$ || \{0001\} $\}_{\text {тiB2 }}$, suggesting it can be created by the same pushing and engulfment mechanism. However,
different from the second contact plane, the final shape of $\mathrm{Al}_{3} \mathrm{Ti}$ in the master alloy did not usually include $\{100\}$ facets. Examples of rare $\{100\}_{\text {Al3тi }}$ facets are given in Figure $3.13(b)$ and (c). To explore the dependence of the third contact plane frequency on position within $\mathrm{Al}_{3} \mathrm{Ti}$ crystals, Figure 3.13 (d) projects the relative position of 23 interior $\mathrm{TiB}_{2}$ particles in Table 3.3 with the third contact plane into a normalised $\mathrm{Al}_{3} \mathrm{Ti}$ cross section. In order to separate different distances to the origin, ellipses with various values from 0.2 to 1.0 of function $(x / a)^{2}+(y / b)^{2}$ are drawn in Figure 3.13(d). The origin represents the growth centre and the closer the $\mathrm{TiB}_{2}$ is located to the origin, the earlier it was engulfed during $\mathrm{Al}_{3} \mathrm{Ti}$ growth. It can be seen that most of the $\mathrm{TiB}_{2}$ (over 80\%) in Figure 3.13(d) are located inside the first two ellipses and the percentage of $\mathrm{TiB}_{2}$ particles located at different distances to the growth centre are plotted in Figure $3.13(\mathrm{e})$, confirming that most TiB ${ }_{2}$ particles with $\{100\}_{\text {Al3Ti }}| |\{0001\}_{\text {TiB2 }}$ contact plane were engulfed by $\mathrm{Al}_{3} \mathrm{Ti}\{100\}$ facets in the early stages of $\mathrm{Al}_{3} \mathrm{Ti}$ growth. From this result, it might be that the $\{100\}$ facet was more common during early growth of $\mathrm{Al}_{3} \mathrm{Ti}$.


Figure 3.13. (a) Cross section of a TiB $B_{2}$ particle fully embedded inside $A l_{3} T i$ with $\{100\}_{A \mid 3 T i}| |\{0001\}_{\text {TiB2 }}$. Contact planes are highlighted in the unit cell wireframes. (b) A rare cross section of an $\mathrm{Al}_{3} \mathrm{Ti}$ crystal with (100), (001) and (101) facets, with unit cell wireframe from EBSD superimposed. (c) Extracted $\mathrm{Al}_{3} \mathrm{Ti}$ from Al-5Ti-1B with a (100) facet. (d) Relative positions of $23 \mathrm{TiB}_{2}$ particles embedded in $\mathrm{Al}_{3} \mathrm{Ti}$ with $\{100\}_{\text {Alзтi }}$ || \{0001\} $\}_{\text {TiB2. }}$. Ellipses with various radius represent different distances from the $\mathrm{Al}_{3}$ Ti growth centre. (e) Percentage of $\mathrm{TiB}_{2}$ particles at different distances to the $\mathrm{Al}_{3}$ Ti centre in (d).

Other factors such as liquid flow and the thermal gradient are also likely to play a role. For example, Stefanescu et al. [96] have discussed how melt flow affects pushing and engulfment: for low convection, flow into the interface generated by solidification produces a drag force to push the particle into the interface, whereas flow parallel to the interface induced by natural convection produces a lift force to push the particle away from the interface. In these cases, engulfment occurs when the S-L interface velocity exceeds a critical value whereas, when there is significant melt
convection, no engulfment occurs. For the low melt convection condition studied here, melt flow effects are expected to be small. Figure 3.7 shows that the third contact plane, $\{100\}_{\mathrm{AlBTi}}| |\{0001\}_{\mathrm{TiB} 2}$, was mainly observed inside $\mathrm{Al}_{3} \mathrm{Ti}$ crystals while the second one, $\{001\}_{\mathrm{AI} 3 \mathrm{Ti}}| |\{0001\}_{\mathrm{TiB2}}$, was mainly on the $\mathrm{Al}_{3} \mathrm{Ti}$ surface. From Figure 3.3 it is clear that $\mathrm{Al}_{3} \mathrm{Ti}$ crystals grow faster in the $<100>$ direction than the <001> direction, which means during pushing the $\{100\}$ facet is more likely to exceed the critical velocity and cause engulfment than the $\{001\}$ facet. Therefore, for the third contact plane, $\{100\}_{\text {Al3 }}$
 $\{0001\}_{\mathrm{TiB2}}, \mathrm{TiB}_{2}$ is more likely to be pushed by the advancing $\mathrm{Al}_{3} \mathrm{Ti}$ facet (26.2\%).

### 3.4.3 Rotation on contact planes during pushing

For the three types of contact plane in Figure 3.7(b), only some of them also have the preferred parallel directions in the three ORs. To explore the frequency of the angular arrangement, the orientations on three contact planes are plotted as histograms at the top of Figure 3.14(a)-(c), using interior $\mathrm{TiB}_{2}$ for contact planes $1 \& 3$, and surface $\mathrm{TiB}_{2}$ for contact plane 2 because most $\mathrm{TiB}_{2}$ particles with contact plane 2 remained on the surface due to the low growth rate of $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ facet. Because of the sixfold symmetry of the $\mathrm{TiB}_{2}\{0001\}$ plane and the fourfold symmetry of the $\mathrm{Al}_{3} \mathrm{Ti}\{001\}$ plane, the invariant rotation range is $30^{\circ}$ for contact planes $1 \& 3$ and $15^{\circ}$ for contact plane 2 , as indicated by the green and purple arrows in Figure 3.14(b).

For all three contact planes, $0^{\circ}$ away from the 3ORs was the most commonly measured deviation angle. When the deviation angle increases, the frequency continuously decreases as it reaches $15^{\circ}\left(15^{\circ}\right.$ away from the OR on the contact plane). For contact plane 2, the situation between $15^{\circ}$ and $30^{\circ}$ is symmetric to $15^{\circ}$ and $0^{\circ}$, while for the other two, the frequency rises again from $15^{\circ}$ to $30^{\circ}$ but eventually it does not reach the same level as $0^{\circ}$.

It has also been simulated that between 10000 totally random $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ orientations only a very small fraction have the parallel planes: $1.2 \%$ for contact plane $1,0.35 \%$ for contact plane 2 and $0.71 \%$ for contact plane 3, which is much smaller compared to our measurement in Table 3.3. As for the deviation angle on the parallel planes, the difference is less than $0.15 \%$. Therefore, the contribution from random orientation background can be ignored through our analysis.

The interfacial energy for the three preferred contact planes at various deviation angles was calculated by DFT and the results are plotted at the bottom of Figure 3.14(a)-(c) for $\left(\mu_{T i B 2}^{s l a b}-\mu_{T i B 2}^{\text {bulk }}\right)=-88 \mathrm{~kJ} / \mathrm{mol}$ (for each contact plane the shape of the curve is almost the same for the $\left(\mu_{T i B 2}^{s l a b}-\mu_{T i B 2}^{\text {bulk }}\right)$ range from $-88 \mathrm{~kJ} / \mathrm{mol}$ to $-115 \mathrm{~kJ} / \mathrm{mol})$. It can be seen that, generally, the geometry with highest frequency in the experiments is energetically favoured. For each contact plane, the lowest energy happens at $0^{\circ}$, which corresponds to the three ORs observed in section 3.3.1, and the change of frequency matches the
energy trend along the deviation angle very well, confirming that the 3ORs are local energy minima and $\mathrm{TiB}_{2}$ particles can rotate towards the 3ORs to lower the interfacial energy when it is being pushed.

We argue that the measured deviation angles are highly likely to have been created by rotation of the $\mathrm{TiB}_{2}$ particles on the relevant $\mathrm{Al}_{3} \mathrm{Ti}$ facet to minimise their interfacial energy since it is improbable that they would form this distribution of deviation angles by randomly falling onto the $\mathrm{Al}_{3}$ Ti facet, and such in-plane rotation preference during pushing can be explained from an energy perspective. In the traditional pushing and engulfment theory, the pushing particle is treated as inert and it is passively pushed by the growth front. But in this study, the foreign particles are active inoculants that can interact with the growing $\mathrm{Al}_{3} \mathrm{Ti}$. With the combination of statistical experimental data and theoretical calculations, it can be seen that $\mathrm{TiB}_{2}$ particles can have the degree of freedom to rotate with respect to the growth front during pushing to lower the energy and produces simple ORs.


Figure 3.14. In-plane rotation (restricted rotation on the contact plane) of $\mathrm{TiB}_{2}$ with respect to $\mathrm{Al}_{3} \mathrm{Ti}$ on three contact planes. (Top) The frequency of different rotation angles measured by EBSD. (Bottom) The corresponding interfacial energies calculated by DFT when $\left(\mu_{T i B 2}^{s l a b}-\mu_{T i B 2}^{b u l k}\right)=-88 \mathrm{~kJ} / \mathrm{mol}$. (a) $\{112\}_{A 13 T i}$ || $\{0001\}_{\text {TiB2 }}$, (b) $\{001\}_{\text {AI3Ti }}$ || $\{0001\}_{\text {TiB2 }}$ and (c) $\{100\}_{A \mid 3 T i}$ || \{0001 $\}_{\text {TiB2 }}$.

### 3.4.4 Out-of-plane rotation and interface optimisation

From the shape of $\mathrm{Al}_{3} \mathrm{Ti}$ crystals, there is another facet, $\{101\}$ (Figure 3.3(a)), and if pushing and engulfment of $\mathrm{TiB}_{2}$ particles happen on this facet we should expect to observe another preferred contact plane: $\{101\}_{\mathrm{Al\mid 3Ti}}| |\{0001\}_{\mathrm{TiB2} 2}$. However, this was never measured in this work as highlighted in the contour inverse pole figures in Figure 3.7. Therefore, along with planar rotation during pushing and engulfment, there should be another active process to change the orientation of $\mathrm{TiB}_{2}$.

Figure $3.15(\mathrm{a})$ shows a case where $\mathrm{TiB}_{2}$ with OR 3 is close to a $\{101\}$ surface of $\mathrm{Al}_{3} \mathrm{Ti}$, indicating this $\mathrm{TiB}_{2}$ was possibly pushed and engulfed on the $\{101\}$ facet at a late stage of growth. Instead of $\{101\}_{\text {Al3тi }}| |$ $\{0001\}_{\mathrm{Ti} 22}$, the contact plane $\{100\}_{\mathrm{A} 13 \mathrm{Ti}}| |\{0001\}_{\mathrm{T} і \mathrm{~B} 2}$ was produced (i.e. OR3), which suggests a nonuniform growth of $\mathrm{Al}_{3} \mathrm{Ti}$ happened as it pushed the $\mathrm{TiB}_{2}$ particle, forcing an out-of-plane rotation of this $\mathrm{TiB}_{2}$ particle. Figure $3.15(\mathrm{~b})$ illustrates schematically the combined processes of continuous pushing, rotation and engulfment due to $\mathrm{Al}_{3} \mathrm{Ti}$ growth that could cause the formation of OR 3 in this case. As in Figure 3.12, this mechanism also creates a small $\alpha$-Al island left behind by the growth front. Similar to the in-plane rotation in section 3.4.3, this out-of-plane rotation is also believed to be driven by interfacial energy minimisation, where $\mathrm{TiB}_{2}$ rotation caused by $\mathrm{Al}_{3} \mathrm{Ti}$ growth optimises the interface.

(b) $\mathrm{Al}_{3} \mathrm{Ti}[100]$ growth direction $\longrightarrow$


Figure 3.15. Out-of-plane rotation during the pushing and engulfment process for contact plane 3: $\{100\}_{\text {AI3Ti }}$ || $\{0001\}_{\text {TiB2. }}$ (a) TiB Th $_{2}$ particle fully embedded underneath the $A I_{3} T i\{101\}$ facet with $\{100\}_{\text {AIBTi }}$ |/ \{0001\} $\}_{\text {TiB2 }}$ in cross section. The parallel planes are highlighted in the unit cell frames from EBSD. (b) Schematic illustration of out-of-plane rotation during the pushing and engulfment of a TiB2 particle on a $A l_{3} T i\{101\}$ facet forming $\{100\}_{A 13 T i}$ || $\{0001\}_{\text {Tів2 }}$.

Similarly, $\mathrm{TiB}_{2}$ particles with OR1 in Figure $3.5(\mathrm{~b})(1 \& 2)$ are also very close to the $\{101\}$ facets, and since there can only be one $\mathrm{TiB}_{2}$ nucleant for a single $\mathrm{Al}_{3} \mathrm{Ti}$ crystal, not all OR1 interfaces we measured were caused by nucleation. In Figure $3.14(\mathrm{a}) \mathrm{TiB}_{2}$ particles have varying rotation angle on contact plane 1 with respect to OR1, indicating the planar rotation can happen on contact plane 1 during the pushing and engulfment process. Since the $\{112\}$ facet is never observed in $\mathrm{Al}_{3} T i$ crystals, the out-of-plane rotation process is required to orientate $\{0001\}_{\text {TiB2 }}$ parallel to $\{112\}_{\text {Al3тi }}$ followed by in-plane rotation to OR1 which gives the lowest interfacial energy. The rotation angle required from $\{101\}_{\text {Al3тi }}| |$ $\{0001\}_{\text {TiB2 }}$ to contact plane 1,2 and 3 are $40.17^{\circ}, 65.8^{\circ}$ and $24.2^{\circ}$ respectively, indicating a possible preference for $\mathrm{TiB}_{2}$ to reorient to contact plane $1 \& 3$ followed by in-plane rotation to OR1 and OR3.

In Al grain refinement, it is widely accepted that the largest $\mathrm{TiB}_{2}$ particles trigger nucleation first and that recalescence then stifles nucleation on smaller $\mathrm{TiB}_{2}$ particles [227, 228]. It is likely that similar phenomena happen with the nucleation of $\mathrm{Al}_{3} \mathrm{Ti}$, although this could not be studied here since the size of $\mathrm{TiB}_{2}$ could not be determined with confidence in 2D sections, and particles with OR1 could have formed by nucleation or by pushing/engulfment.

Figure $3.7(\mathrm{~b})$ also shows that about $70 \%$ of $\mathrm{TiB}_{2}$ particles did not have any of these three contact planes. They are likely to be clustered or trapped in other less favoured local energy minima and engulfed before there was enough uneven $\mathrm{Al}_{3} \mathrm{Ti}$ growth to help reach an orientation relationship with lower interfacial energy. From this, it can be seen that while pushing and engulfment can generate preferred orientation relationships, engulfment can also occur when a higher energy interface is present.

### 3.5 Conclusions

A detailed study of the solidification orientation relationships between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ in the $\mathrm{Al}-\mathrm{Ti}-\mathrm{B}$ master alloys and in $\mathrm{Al}-0.8 \mathrm{Ti}$ containing large $\mathrm{TiB}_{2}$ crystals has been conducted, combining experiment (EBSD) and simulation (DFT calculation). The following main conclusions can be drawn:

- Three reproducible ORs were measured between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ in $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ and $\mathrm{Al}-3 \mathrm{Ti}-1 \mathrm{~B}$, both in master alloy rods and in remelted and cast samples:

$$
\begin{aligned}
& \{112\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB2} 2} \text { with }<\overline{2} 01>_{\mathrm{Al} 3 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB2}} \\
& \{001\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB} 2} \text { with }<110>_{\mathrm{Al} 3 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB2}} \\
& \{100\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB} 2} \text { with }<010>_{\mathrm{Al} 3 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB} 2} \quad \text { (OR2) }
\end{aligned}
$$

- DFT calculation shows OR1 has the lowest interfacial energy, OR2 has a slightly higher energy, and OR3 has a substantially higher interfacial energy, consistent with a simple lattice matching analysis.
- OR1 was most frequent (10.8\%) inside $\mathrm{Al}_{3}$ Ti while OR2 was common (14.6\%) on the $\mathrm{Al}_{3} \mathrm{Ti}$ (001) facet. OR3 only existed inside $\mathrm{Al}_{3}$ Ti. Multiple $\mathrm{TiB}_{2}$ particles were found to share all three ORs within a single $\mathrm{Al}_{3} \mathrm{Ti}$ crystal; only one $\mathrm{TiB}_{2}$ particle can have nucleated the $\mathrm{Al}_{3} \mathrm{Ti}$ crystal and the other particles formed ORs by pushing/engulfment.
- By solidifying small $\mathrm{Al}_{3} \mathrm{Ti}$ crystals on the (0001) facet of large $\mathrm{TiB}_{2}$ crystals, OR1 was confirmed to be the nucleation OR between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$. All six variants of OR1 were measured for multiple $\mathrm{Al}_{3} \mathrm{Ti}$ crystals nucleating on the $\mathrm{TiB}_{2}(0001)$ facet. OR2 and OR3 were never measured in these nucleation experiments.
- Micrographs of $\mathrm{TiB}_{2}$ particles at different stages of pushing and engulfment by $\mathrm{Al}_{3} \mathrm{Ti}$ growth facets, showed that $\mathrm{TiB}_{2}$ plates lie with their (0001) on the $\mathrm{Al}_{3} \mathrm{Ti}$ facet and cause a depression in the surrounding $\mathrm{Al}_{3} \mathrm{Ti}$ growth front. Engulfment occurred by $\mathrm{Al}_{3} \mathrm{Ti}$ ledges overgrowing a $\mathrm{TiB}_{2}$ particle, leaving an $\alpha-A l$ island adjacent to the $\mathrm{TiB}_{2}$ particle.
- A statistical analysis of EBSD data from $580 \mathrm{TiB}_{2}$ particles indicated that $\mathrm{TiB}_{2}$ can rotate with respect to $\mathrm{Al}_{3} \mathrm{Ti}$ during pushing. The frequency of the in-plane rotation angle measured by EBSD matched well with the interfacial energy calculated by DFT, showing that the rotation occurs to minimise the interfacial energy. This is the main origin of OR2 on (001) $\mathrm{Al}_{3} \mathrm{Ti}$ facets, and occasionally of OR3 on rare (100) $\mathrm{Al}_{3} \mathrm{Ti}$ facets.
- OR1 also occurred by a pushing and engulfment mechanism. However, unlike OR2, out-ofplane rotation is required to form OR1 (and OR3 on $\{101\}$ facets) during pushing by the main $\mathrm{Al}_{3}$ Ti growth facets. Thus, combined in-plane and out-of-plane rotations during the pushing and engulfment process are required to optimise the interface and create OR1 and OR3 in most cases.
- More broadly it can be concluded that, for a faceted intermetallic ( $\mathrm{Al}_{3} \mathrm{Ti}$ ) solidifying in the presence of numerous particles of a potent nucleant $\left(\mathrm{TiB}_{2}\right)$, the great majority of particles develop a simple OR by pushing/engulfment and the minority develop their OR by nucleation.


## Chapter 4 Solidification twinning in IMCs: metastable nucleation in

## undercooled melts

### 4.1 Introduction

In Chapter 3, it was seen that six $\mathrm{Al}_{3} \mathrm{Ti}$ orientations nucleated and grew from a single $\mathrm{TiB}_{2}$ nucleant crystal; these were the six variants of OR1 and the combined six $\mathrm{Al}_{3} \mathrm{Ti}$ orientations inherited an overall hexagonal symmetry from the $\mathrm{TiB}_{2}$ nucleant (Figure 3.10). More generally, during solidification, when heterogeneous nucleation occurs on a nucleant phase with higher symmetry than the new solid, multiple variants of the nucleation OR exist and the resulting multiple orientations have a twinning relationship with each other. For example, the nucleation OR of FCC-AI on hexagonal TiB ${ }_{2}$ has two variants and FCC-AI grains that nucleated with these two orientations have a twin OR with each other, a $60^{\circ}$ rotation around a common $\{111\}[229]$. In another example, the nucleation OR of rhombohedral $\mathrm{Al}_{8} \mathrm{Mn}_{5}$ on cubic $\mathrm{B} 2-\mathrm{Al}(\mathrm{Fe}, \mathrm{Mn})$ has eight variants and the resulting $\mathrm{Al}_{8} \mathrm{Mn}_{5}$ form cyclic twins with overall cubic symmetry [31]. Similar behaviour has been reported where the nucleant phase is a metastable precursor. For example, in electrostatically levitated NiZr droplets, a metastable decagonal quasicrystal formed in an undercooled melt and growth of the stable orthorhombic NiZr phase from this had a tenfold cyclic twinned structure [230]. There are many other examples of cyclic twinning in IMCs where the mechanism is not well understood. This chapter explores the solidification conditions under which cyclic twinning occurs in four IMCs where previous work has shown signs of cyclic twinning. The IMCs were selected using the following criteria:

1. There should be a low volume fraction of the primary IMCs to enable growth with their preferred morphology without interference from their neighbours.
2. After solidification, the remaining volume should mostly contain a simple metallic phase (e.g. $\alpha-$ AI or $\beta-\mathrm{Sn}$ ) that is well-suited to selective etching to extract the primary IMCs for 3D SEM studies.
3. They should be either (i) ordered superstructures derived from simple close packed disordered phases, where the superstructure is from a different crystal system to the parent phase (e.g. orthorhombic $\leftrightarrow \mathrm{HCP}$, or tetragonal $\leftrightarrow \mathrm{FCC}$ ).
4. Or (ii) low symmetry IMCs that are quasicrystal approximants.
5. The selected IMCs should span a wide range of crystal structures and pseudo-symmetries.

Based on these criteria, the selected IMCs were: $\mathrm{DO}_{22}-\mathrm{Al}_{3} \mathrm{Ti}$, a tetragonal superstructure derived from FCC; $\mathrm{DO}_{\mathrm{a}}-\mathrm{Ag}_{3} \mathrm{Sn}$, an orthorhombic superstructure derived from HCP ; monoclinic $\mathrm{Al}_{45} \mathrm{Cr}_{7}$, an icosahedral quasicrystal approximant; and monoclinic $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, a decagonal quasicrystal approximant. The phase diagrams of the four systems are plotted in Figure 4.1 at the Al-rich (from the Thermo-Calc TCTI2 database) or Sn-rich (from the Thermo-Calc TCSLD3.2 database) sides, with the compositions used in this study highlighted. The structure and lattice parameters of the four IMCs are listed in Table 4.1.


Figure 4.1 Phase diagram for (a) Al-Ti, (b) Sn-Ag, (b) Al-Cr and (d) Al-Fe system at Al (Sn for Sn-Ag) rich side.

Table 4.1 Crystal structures of the four IMCs

| Crystals | Space group | Pearson symbol | Lattice parameters | Ref. |
| :--- | :---: | :---: | :--- | :---: |
| $\mathrm{Al}_{3} \mathrm{Ti}$ | $14 / \mathrm{mmm}$ | $t / 8$ | $\mathrm{a}=3.8537 \AA, \mathrm{c}=8.5839 \AA$ | $[204]$ |
| $\mathrm{Ag}_{3} \mathrm{Sn}$ | PmmnZ | $o P 8$ | $\mathrm{a}=4.7823 \AA, \mathrm{~b}=5.9975 \AA, \mathrm{c}=5.1639 \AA$ | $[231]$ |
| $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ | $\mathrm{C} 2 / \mathrm{m}$ | $m S 104$ | $\mathrm{a}=25.196 \AA, \mathrm{~b}=7.574 \AA, \mathrm{c}=10.949 \AA, \beta=128.72^{\circ}$ | $[126]$ |
| $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ | $\mathrm{C} 2 / \mathrm{m}$ | $m S 102$ | $\mathrm{a}=15.492 \AA, \mathrm{~b}=8.078 \AA, \mathrm{c}=12.471 \AA, \beta=107.69^{\circ}$ | $[128]$ |

Past solidification studies on $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ and $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ sometimes report (untwinned) single crystals, single twins and multiple twins [29, 125, 232-234]. One aim of this work was to explore the effect of cooling rate and melt undercooling on the types and number of twins, to help us understand the origin of solidification twinning in these crystals. By studying four IMCs with significantly different symmetries, the aim was to further build the understanding of the factors affecting cyclic twinning rather than the specific behaviour of one crystal structure.

### 4.2 Methods

### 4.2.1 Sample preparation

160 g of $\mathrm{Sn}-5 \mathrm{Ag}$ alloy was made by melting $99.999 \% \mathrm{Sn}$ with $99.9 \% \mathrm{Ag}$. The mixture was heated to $300^{\circ} \mathrm{C}$ in a clay-bonded graphite crucible in a resistance furnace. After holding for 2 hours, the melt was stirred with an $\mathrm{Al}_{2} \mathrm{O}_{3}$ rod and then poured into the steel mould. The alloy was rolled to $\sim 30 \mu \mathrm{~m}$ foils, punched into $\emptyset 1.6 \mathrm{~mm}$ discs and reflowed in a ROL-1 tacky flux on a hotplate at $280^{\circ} \mathrm{C}$ to form $500 \mu \mathrm{~m}$ diameter spheres due to surface tension. The balls were then reflowed in a Mettler Toledo DSC in aluminium pans under a nitrogen atmosphere. The heating rate was $20 \mathrm{~K} / \mathrm{min}$ and the peak temperature was $280^{\circ} \mathrm{C}$. After holding at the peak temperature for 10 minutes, solder balls were then cooled at one of five cooling rates: $0.05,0.2,1.2,5$ and $20 \mathrm{~K} / \mathrm{min}\left(8.3 \times 10^{-4}, 3.3 \times 10^{-3}, 2.0 \times 10^{-2}, 8.3 \times 10^{-2}\right.$ and $3.3 \times 10^{-1} \mathrm{~K} / \mathrm{s}$ ).

50 g of $\mathrm{Al}-1 \mathrm{wt} \% \mathrm{Cr}, \mathrm{Al}-0.8 \mathrm{wt} \% \mathrm{Ti}$ and $\mathrm{Al}-3 \mathrm{wt} \%$ Fe alloys were made by arc melting CP Al ingots (Table 4.2) with $99.9 \% \mathrm{Cr}$ pellets, $99.99 \% \mathrm{Ti}$ sponge and $\mathrm{Al}-10 \mathrm{Fe}$ master alloy respectively. Arc melting was conducted in 30 mTorr vacuum, back-filled with Ar on a water-cooled Cu plate. The alloys were melted, flipped three times, and then the power was stopped and the alloy solidified on the water-cooled Cu plate. The cooling rate has been estimated to be approximately $5 \mathrm{~K} / \mathrm{s}$ from thermal imaging after switching off the arc [235]. For comparison, 15 g of these three alloys were re-melted at $980^{\circ} \mathrm{C}$ in an alumina boat coated with a layer of boron nitride in a resistance furnace. After holding for 6 hours, the power was turned off and the melt cooled down slowly inside the furnace resulting in a cooling rate of $1.2 \mathrm{~K} / \mathrm{min}(0.02 \mathrm{~K} / \mathrm{s})$, measured by an immersed K -type thermocouple in a separate experiment.

Table 4.2 The composition of commercial purity (CP) Al used in this work

| Elements | Al | Fe | Si | Mn | Mg | Ni | Ti | Cu | Zn |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Composition (wt. \%) | Bal. | 0.229 | 0.015 | 0.0039 | 0.0023 | 0.0158 | 0.0043 | 0.0015 | 0.0007 |

All alloys were mounted in Struers VersoCit acrylic cold mounting resin and then ground to 4000 grit with SiC paper followed by polishing with colloidal silica on a nap cloth for 6 minutes. For
crystallographic investigation, a Zeiss Sigma field emission gun SEM fitted with a Bruker e-FlashHR electron backscatter diffraction (EBSD) detector was used. Bruker Esprit 2.0 software, combined with the MTEX 4.4 Toolbox within MATLAB ${ }^{\text {TM }} 9.2$ (Mathworks, USA) [206], were applied to analyse the growth habits of single crystal intermetallics, and the orientation relationships in twinned crystals. Throughout this chapter, all unit cell wireframes in Figures were plotted based on the Euler angles measured by EBSD.

To study the 3D morphology of the intermetallic compounds, $\alpha$-Al was selectively etched in anhydrous 1-butanol under an argon atmosphere at $117^{\circ} \mathrm{C}$ for approximately 4 hours, and $\beta$ - Sn was selectively etched in the solution with $5 \% \mathrm{NaOH}$ and $3.5 \%$ orthonitrophenol at $80^{\circ} \mathrm{C}$ for approximately 6 hours. Intermetallic crystals were collected and placed on a stub for further study by analytical SEM.

### 4.2.2 DSC analysis

Figure 4.2 shows a typical heating and cooling curve of a $\mathrm{Sn}-5 \mathrm{Ag}$ ball from DSC to demonstrate the method used to determine the nucleation temperature of the $\mathrm{Ag}_{3} \mathrm{Sn}$ phase. In this case, the heating rate was $20 \mathrm{~K} / \mathrm{min}$ and the cooling rate was $1.2 \mathrm{~K} / \mathrm{min}$. On both heating and cooling, one large peak at lower temperature and one small peak at higher temperature can be seen. The small peak is hotter than the eutectic temperature and is associated with the melting or solidification of primary $\mathrm{Ag}_{3} \mathrm{Sn}$. The nucleation point of primary $\mathrm{Ag}_{3} \mathrm{Sn}$ is the temperature at which latent heat release first occurs on cooling, but it is difficult to determine accurately. Therefore, the onset temperature for primary $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation was determined by the extrapolation method shown in the inset in Figure 4.2.


Figure 4.2 A typical heating (20K/min) and cooling (1.2K/min) curve from one $\mathrm{Sn}-5 \mathrm{Ag}$ solder ball, with the onset temperature for eutectic melting and $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation determined by the extrapolation method.

For high heating and cooling rates in DSC, there can be a lag between the recorded temperature and the real temperature of thermal events due to heat transfer through the DSC pan. In order to check for the extent of such lag, five heating rates ( $0.05,0.2,1.2,5,20 \mathrm{~K} / \mathrm{min}$ ) were applied to the same
solder ball and the heating curves in Figure 4.3 were recorded. The onset of melting was determined by the same extrapolation method as in Figure 4.2. Figure 4.3 focusses on the onset of eutectic melting since there is a large peak and there is negligible barrier for eutectic melting so, in theory, the onset temperature should be constant for all heating rates. It was found in Figure 4.3 that the onset temperature for eutectic melting at all five heating rates differs by less than $1^{\circ} \mathrm{C}$. This is substantially smaller than the effects discussed in this Chapter and, therefore, the influence of the lag in data recording can be ignored.


Figure 4.3 The heating curves of eutectic melting in a Sn-5Ag ball at different heating rate.

### 4.3 Results

### 4.3.1 Solidification twinning in the four IMCs

### 4.3.1.1 $\mathrm{Al}_{3} \mathrm{Ti}$

### 4.3.1.1.1 Single crystal of $\mathrm{Al}_{3} \mathrm{Ti}$

In Al-0.8Ti alloy cooled at $1.2 \mathrm{~K} / \mathrm{min}$, all $\mathrm{Al}_{3}$ Ti solidified as plate-like single crystals. A typical $\mathrm{Al}_{3} \mathrm{Ti}$ plate extracted from $\mathrm{Al}-0.8 \mathrm{Ti}$ alloy is shown in Figure 4.4. At this slow cooling rate, crystals grew into large size ( $>1 \mathrm{~mm}$ ) with high aspect ratio (thin plate-like shape). EBSD examination confirms that the main facet is $\{001\}$ with multiple $\{100\}$ edge facets. The thin direction of the plate is the long direction of the tetragonal unit cell.


Figure 4.4 (a) Single $\mathrm{Al}_{3}$ Ti crystal extracted from slow cooled AI-0.8Ti with large $\{001\}$ facet and $\{100\}$ edges. (b) EBSD pattern from the $A I_{3} T i$ crystal in (a). (c) $\{001\}$ and $\{100\}$ pole figure of the crystal in (a) with the unit cell wireframe showing the orientation.

### 4.3.1.1.2 Cyclic twinning in $\mathrm{Al}_{3}$ Ti with combined cubic symmetry

In arc-melted ( $\sim 5 \mathrm{~K} / \mathrm{s}$ ) Al-0.8 Ti alloy, $\mathrm{Al}_{3} \mathrm{Ti}$ crystals were much smaller ( $\sim 20 \mu \mathrm{~m}$ ) and, with EBSD examination, none were single crystals. Twinned $\mathrm{Al}_{3} \mathrm{Ti}$ crystals consisted of three perpendicular plates penetrating each other, as shown in Figure 4.5(a). The EBSD IPF-Y map in Figure 4.5(b) shows there are three orientations inside the crystal and the main facet of each plate is $\{001\}$. The three orientations are at $90^{\circ}$ to each other rotated about the $<100>$ directions, causing every two of them to share a common $\{100\}$ plane which is parallel to the $\{001\}$ of the third one, as shown in pole figures in Figure 4.5(c). Together the three orientations form an overall cubic symmetry. Such triple twinning is obvious from the 3D morphology of extracted $\mathrm{Al}_{3}$ Ti crystals, as shown in Figure 4.5(d)-(f). The cubic orientation is plotted in Figure 4.5(f), surrounded by the three tetragonal unit cells corresponding to the three orientations in Figure 4.5(d). The three tetragonal unit cells are the three variants of one orientation relationship with a cubic unit cell. The unit cells of $\mathrm{Al}_{3} \mathrm{Ti}$ in $\mathrm{DO}_{22}$ is plotted in Figure $4.5(\mathrm{~g})$, as well as the related cubic $\mathrm{L1} 1_{2}$ structure and the disordered FCC solid solution [236]. Compared to the large $\mathrm{Al}_{3} \mathrm{Ti}$ plates from slow cooling in Figure 4.4, the twinned $\mathrm{Al}_{3} \mathrm{Ti}$ crystals from arc melting are over 50 times smaller and the twins produce a blocky equiaxed shape.


Figure 4.5 Triple twinning in $\mathrm{Al}_{3}$ Ti from arc-melted Al-0.8Ti alloy. (a) $\mathrm{Al}_{3}$ Ti crystal in cross section with three plates penetrating into each other. (b) EBSD IPF-Y map of the crystal in (a) showing three orientations inside the crystal, together with their unit cell wireframes. (c) $\{001\}$ and $\{100\}$ pole figures of the three orientations showing they are $90^{\circ}$ to each other. (d) An extracted $\mathrm{Al}_{3} \mathrm{Ti}$ crystal from arcmelted Al-0.8Ti alloy with the same triple twinning in (a)-(c). (e) $70^{\circ}$ tilt view of the extracted crystal in (d). (f) The unit cell wireframes of the three orientations in (d) forming a combined cubic symmetry. The cubic orientation is plotted in the centre of the three tetragonal unit cells. (g) Unit cell of $\mathrm{Al}{ }_{3} T i$ in $D O_{22}, L 1_{2}$ and disordered FCC solid solution structure.

### 4.3.1.2 $\mathrm{Ag}_{3} \mathrm{Sn}$

### 4.3.1.2.1 Single crystal of $\mathrm{Ag}_{3} \mathrm{Sn}$

When solidified at $0.05 \mathrm{~K} / \mathrm{min}$, all $\mathrm{Ag}_{3} \mathrm{Sn}$ in $\mathrm{Sn}-5 \mathrm{Ag}$ solder balls were single crystals. Figure 4.6(a) shows a typical $\mathrm{Ag}_{3} \mathrm{Sn}$ single crystal cooled at $0.05 \mathrm{~K} / \mathrm{min}$, and Figure $4.6(\mathrm{~b})$ is the EBSD phase map of the solder ball. There is only one orientation in the large $\mathrm{Ag}_{3} \mathrm{Sn}$ plate, and its Kikuchi pattern is shown in Figure 4.6(c). The $\{001\}$ pole figure and the unit cell wireframe in Figure 4.6(d) indicate that the main facet of the primary $\mathrm{Ag}_{3} \mathrm{Sn}$ plate is $\{001\}$. Figure 4.6(e) is a large $\mathrm{Ag}_{3} \mathrm{Sn}$ plate extracted from the $\mathrm{Sn}-5 \mathrm{Ag}$ solder ball cooled at $0.05 \mathrm{~K} / \mathrm{min}$. The EBSD IPF-Z map indicates that it is a single crystal with its $\{001\}$ nearly parallel to the z-axis. The Kikuchi pattern from its top surface is shown in Figure 4.6(g). The \{001\} pole figure and the unit cell wireframe confirm the $\{001\}$ is the main facet of the $\mathrm{Ag}_{3} \mathrm{Sn}$ plate with $\{100\}$ and $\{010\}$ being the edges.


Figure 4.6 (a) Optical microscope image of an $\mathrm{Ag}_{3} \mathrm{Sn}$ single crystal in a $\mathrm{Sn}-5 \mathrm{Ag}$ solder ball cooled at $0.05 \mathrm{~K} / \mathrm{min}$. (b) EBSD phase map of the cross section in (a). Red is $\mathrm{Ag}_{3} \mathrm{Sn}$ and blue is $\mathrm{B}-\mathrm{Sn}$. (c) The Kikuchi pattern from the $\mathrm{Ag}_{3} \mathrm{Sn}$ in (a). (d) \{001\} pole figure with unit cell wireframes of the $\mathrm{Ag}_{3} \mathrm{Sn}$ orientation in (a). (e) SEM image of an $\mathrm{Ag}_{3} \mathrm{Sn}$ crystal extracted from a $\mathrm{Sn}-5 \mathrm{Ag}$ solder ball cooled at $0.05 \mathrm{~K} / \mathrm{min}$. (f) EBSD IPF-Z map of the crystal in (e). (g) The Kikuchi pattern from the $\mathrm{Ag}_{3} \mathrm{Sn}$ in (e) with Euler angles. (h) $\{001\}$ pole figure with unit cell wireframes of the $\mathrm{Ag}_{3} \mathrm{Sn}$ orientation in (e).

### 4.3.1.2.2 Cyclic twinning in $\mathrm{Ag}_{3} \mathrm{Sn}$ with combined hexagonal symmetry

Compared to the single crystals from $0.05 \mathrm{~K} / \mathrm{min}$ cooling rate, most $\mathrm{Ag}_{3} \mathrm{Sn}(70 \%)$ were found to be twinned at $1.2 \mathrm{~K} / \mathrm{min}$. Figure 4.7 shows a typical example of three twinned $\mathrm{Ag}_{3} \mathrm{Sn}$ plates. The polarised optical micrograph reveals three different colours of the three plates, indicating that each one of them corresponds to a different crystallographic orientation (Figure 4.7(a)). Three $\mathrm{Ag}_{3} \mathrm{Sn}$ orientations were measured by EBSD mapping but, as shown in the IPF-X map in Figure 4.7(c), there is a heavy misindexing problem between the three orientations in this map. According to the morphology analysis of the $\mathrm{Ag}_{3} \mathrm{Sn}$ single crystal under the same cooling rate in Figure 4.6, the main facet of each plate is $\{001\}$. Therefore, the corresponding orientation for each plate can be assigned, as plotted next to the plate in Figure 4.7 (c). There is a cyclic twinning relationship between the three $\mathrm{Ag}_{3} \mathrm{Sn}$ orientations by a $60^{\circ}$ rotation about the common $<100>$ direction, and the three twinned orthorhombic orientations form a combined hexagonal symmetry, as shown in Figure 4.7(d). Pole figures of the three twinned orientations are plotted in Figure 4.7(e) showing the shared <100> direction with three $\{001\}$ facets being at $60^{\circ}$ to each other. In terms of the atomic arrangement, Figure 4.7(f) is the hcp lattice (grey) superimposed with the three orthorhombic unit cells with Sn and Ag atoms coloured in blue and orange. The whole hcp lattice can be occupied by the three twinned $\mathrm{Ag}_{3} \mathrm{Sn}$ unit cells with chemically ordered atomic arrangement and small lattice distortion (as will be discussed later). Figure $4.7(\mathrm{~g})$ is a comparison between the orthorhombic $\mathrm{Ag}_{3} \mathrm{Sn}$ unit cell and the disordered hcp structure. The OR between the orthorhombic and hap unit cells is: $\{001\}_{\text {ortho }}| |\{1 \overline{1} 00\}_{\mathrm{hcp}}$, with $<100>_{\text {ortho }}| |<0001>_{\text {hcp }}$, and the three measured orthorhombic orientations correspond to the three variants of this OR.


Figure 4.7 Cyclic twinning of $\mathrm{Ag}_{3} \mathrm{Sn}$ in $\mathrm{Sn}-5 \mathrm{Ag}$ solder balls. (a) Polarised optical microscope image of twinned $\mathrm{Ag}_{3} \mathrm{Sn}$ crystals in a $\mathrm{Sn}-5 \mathrm{Ag}$ solder ball cooled at $1.2 \mathrm{~K} / \mathrm{min}$. (b) EBSD phase map of the cross section in (a). Red is $\mathrm{Ag}_{3} \mathrm{Sn}$ and blue is $8-S n$. (c) EBSD IPF-X map of the $\mathrm{Ag}_{3} \mathrm{Sn}$ crystals superimposed on the optical microscope image with unit cell wireframes plotted next to each plate. (d) A combined hexagonal symmetry formed by the three $\mathrm{Ag}_{3} \mathrm{Sn}$ unit cell wireframes from (c). The growth direction is highlighted based on the colour of the plates in (a). (e) <100> and \{001\} pole figures of the three cyclic twinned $\mathrm{Ag}_{3} \mathrm{Sn}$ orientations. (f) HCP lattice (grey) superimposed with ordered Ag (blue) and Sn (orange) atoms from three cyclic twinned $\mathrm{Ag}_{3} \mathrm{Sn}$ unit cells. (g) Unit cell of $\mathrm{DO}_{a}-\mathrm{Ag}_{3} \mathrm{Sn}$ and disordered HCP structure.

### 4.3.1.3 $\mathrm{Al}_{45} \mathrm{Cr}_{7}$

### 4.3.1.3.1 Single crystal of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$

In $\mathrm{Al}-1 \mathrm{wt} \% \mathrm{Cr}$ alloy solidified at $1.2 \mathrm{~K} / \mathrm{min}$, about $40 \%$ of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ were single crystals with hexagonal rod-like shape, as shown in Figure 4.8. Figure 4.8(a) is a transverse sectioned plane of an $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ rod embedded inside mounting resin. The EBSD IPF-Z map (Figure 4.8(b)) confirms that it is a single crystal, and the pole figure (Figure 4.8(c)) shows that the three main facets are (001)(magenta), (110)(red) and $(11 \overline{1})$ (blue), and the long direction is [1 $\overline{1} 0]$. Figure $4.8(\mathrm{~d})$ shows another $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ single crystal extracted from the alloy with the same shape. Figure $4.8(\mathrm{e})$ is a geometric model of the crystal morphology plotted using the (001), (110) and (11 $\overline{1}$ ) planes, and the pole figure in Figure $4.8(f)$ shows the long direction of this crystal is almost in the plane of the paper. The unit cell orientation is also plotted with the long [1 $\overline{1} 0$ ] direction highlighted.


Figure 4.8 (a) A transverse cross section of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ rod with the main facets indexed as (001)(magenta),
 facets, (001), (110) and (11 $\overline{1})$, and the [1 $\overline{1} 0]$ long direction of the crystal in (a), together with the unit cell wireframe with long direction highlighted. (d) A typical $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystal extracted from Al-1Cr alloy, with three main facets and long direction indexed. (e) A schematic illustration of the crystal morphology with (001), (110) and (111) facets coloured in magenta, red and blue, respectively. (f) Pole figure of the three main facets, (001), (110) and (11 $\overline{1})$, and the [1 $\overline{1} 0]$ long direction of the crystal in (d), together with the unit cell wireframe with long direction highlighted.

### 4.3.1.3.2 Two types of twinning in $\mathrm{Al}_{45} \mathrm{Cr}_{7}$

The remaining $60 \%$ of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals solidified at $1.2 \mathrm{~K} /$ min were twinned. Some twinned $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals contained two types of twinning in the same rod, as shown in Figure 4.9. Figure 4.9(a) is a transverse cross section of a long rod-like crystal with re-entrant corners. There are four orientations in this crystal, as shown in the EBSD orientation map in Figure 4.9(b). The Kikuchi patterns from these four domains are given in Figure 4.9(c)-(f), and it is clear that they share some similarities and some obvious differences. In Figure $4.9(\mathrm{~g})$ the four orientations share a common $<110>$ long direction that is almost perpendicular to the sectioning plane. Between grain $1 \& 2(3 \& 4)$ the common $\{110\}$ plane is the interface, and it is indicated (red) in Figure 4.9(a). The twin is a $180^{\circ}$ rotation about the common <110> axis. Such twinning can also be observed directly in the extracted crystal (Figure 4.9(i)) with the clear $\{110\}$ interface. Figure $4.9(\mathrm{~h})$ and (j) shows another type of twinning: between grain $1 \& 4(2 \& 3)$ there is a common $<101>$ direction with the common $\{11 \overline{1}\}$ plane being the interface, and the twinning can be seen as a $70.9^{\circ}$ rotation about the common <101> direction. The interface is also indicated in Figure 4.9(a) in blue. Such twinning with its interface can also be seen in the extracted crystals (Figure 4.9(j)).


Figure 4.9 (a) A transverse cross section of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ long rod-like crystal. (b) The orientation map of the crystal in (a) showing four orientations. (c)-(f) The Kikuchi pattern corresponding to the Orientation 1,2,3 and 4 in (b). (g) The Type 1 twinning: $180^{\circ}$ [1 $\left.\overline{1} 0\right]$ (110) between $1 \& 2$ and $3 \& 4$. (h) The Type 2 twinning: $70.9^{\circ}[101]$ (111) between $1 \& 4$ and $2 \& 3$. (i) A typical extracted $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystal with Type 1 twinning. The (110) interface is indexed. (j) A typical extracted $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystal with Type 2 twinning. The (11 $\overline{1})$ interface is indexed.
$\mathrm{Al}_{45} \mathrm{Cr}_{7}$ is an icosahedral quasicrystal approximant and contains distorted Cr -centred icosahedron building blocks in its unit cell, as shown in Figure 4.10(a). The twinning can be understood from the pseudo-icosahedral symmetry of this phase. An OR between $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and an icosahedron is plotted in Figure 4.10(a) with the monoclinic unit cell aligned so that its [101] is pointing out of the paper. It can
be seen that the $i(5), i(3)$ and $i(2)$ axes are approximately parallel with the pseudo-i(5), pseudo-i(3) and pseudo-i(2) axes in $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ whose indices are labelled on the plot.


Figure 4.10 (a) Orientation relationship between $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and iQC: the Cr1 icosahedral building block in $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ is parallel to the icosahedron in iQC. The $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ is aligned so that one of the pseudo-fivefold directions, [101], is pointing out of the paper and one of the pseudo-twofold directions, [010], is pointing east. (b) The atom configuration at the junction of the four domains in Figure 4.9(b). Each domain is shaded in the same colour as in Figure 4.9(b). The interfaces are highlighted and indexed. A Cr-centred icosahedron is formed at the centre of the four domains. (c) Pole figures of the twofold and fivefold axes of the icosahedron in (b). (d) Pole figures of the pseudo-fivefold and pseudo-twofold directions of the four $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ orientations in Figure 4.9(b).

Assuming the OR plotted in Figure 4.10(a), Figure 4.10(b) shows the atom configuration at the interfaces for all four orientations in Figure 4.9(b). Note that the orientation of the icosahedrons are different in (a) and (b): an $i(5)$ is perpendicular to the paper in (a) to display the OR in a simple crystallographic way, while an $i(2)$ is nearly perpendicular to the paper in (b) to be parallel to the measured rod axis [1 $\overline{1} 0]$. At the centre of the four domains is a shared common Cr -centred icosahedron, indicating they all have the same OR to that icosahedron. The fivefold and twofold axes of this icosahedral orientation are plotted in Figure 4.10(c). For comparison, the pseudo-fivefold directions of $\left.\mathrm{Al}_{45} \mathrm{Cr}_{7}(<101\rangle,<207\right\rangle,<152>$ and $\left.\langle 15 \overline{4}\rangle\right)$ from the four orientations are plotted in Figure 4.10(d) and they are all near-parallel to each other, and near-parallel to the fivefold axes of the
icosahedron orientation in Figure 4.10(b). The same is true for all the pseudo-twofold directions $(<010\rangle,<110\rangle,<102\rangle,<123\rangle,<233\rangle,<150\rangle,<021\rangle,<126\rangle$ and $<10 \overline{4}\rangle$ ), and the common [1 $\overline{1} 0$ ] long direction is one of the pseudo-twofold directions. Among all 30 variants of the OR, only these four orientations share this common elongated direction. This OR between the icosahedron and $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ is an icosahedron-on-icosahedron OR with the Cr 1 -centred distorted icosahedron in $\mathrm{Al}_{45} \mathrm{Cr}_{7}$, which is at the centre of the centrosymmetric $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ unit cell. In past work, $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ has been studied in coexistence with its parent icosahedral quasicrystal after reheating quasicrystals up to $450^{\circ} \mathrm{C}$, and the measured $O R$ between the iQC and $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ was the same as that deduced in Figure 4.10 [125].

The same twinning geometry and the resulting re-entrant corners were observed in numerous slow cooled $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals in this work. Further examples are shown in Figure 4.11, with the common <110> long direction highlighted with triangles.


Figure 4.11 EBSD Euler angle map of the $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals with four twinned orientations, and their corresponding pole figures for <110> directions, together with the colour scheme for $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ Euler angle map.
4.3.1.3.3 Multiple twinning in $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ forming combined icosahedral symmetry In arc-melted ( $\sim 5 \mathrm{~K} / \mathrm{s}$ ) $\mathrm{Al}-1 \mathrm{wt} \% \mathrm{Cr}$ alloy, the $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ were much smaller with a more complicated shape. There was no long preferred direction and they never grew as single crystals. Figure 4.12(a) shows a typical $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystal after arc-melting. EBSD revealed 12 orientations in the cross section, as shown in the EBSD Euler angle map in Figure 4.12(b). Figure 4.12(c) shows the enlarged area near the crystal centre, and due to the limit of the EBSD step size, there is a high rate of unindexed points near the complex centre. Multiple twinned boundaries exist between certain orientations and the twin laws are either one of the two types of twinning discussed with Figure 4.10 previously, indicating shared <101> (pseudo-fivefold) or <110> (pseudo-twofold) directions. Figure 4.12(d) plots all the <101> and <110> directions of the 12 measured orientations. Note that there are only six different <101> spots in the pole figure for the 12 orientations because some of them are shared, the same for the <110> directions. It is highlighted in the <110> pole figure that orientation 1-4, 5-8 and 8-11 share common <110> directions respectively, which means every group of the four orientations are in the same OR as in Figure 4.9-Figure 4.11. The unit cell wireframes of the 12 orientations are plotted in Figure 4.12(e) and they are arranged in the same way as they are distributed geometrically inside the crystal. Figure 4.12(g) shows the Cr1-centred icosahedron building block in the unit cell of orientation 3, and all the other 11 orientations share the same orientation of the Cr 1 icosahedron in their unit cells. A standard icosahedron with the same orientation is also plotted in Figure 4.12(g), with pole figures of its $i(5)$ and $i(2)$ plotted in Figure 4.12(f). The comparison between pole figures in Figure 4.12(d) and (f) shows that all 12 orientations form a combined icosahedral symmetry, and they all share the same OR to this single icosahedral orientation: the <101> direction is parallel to one of the fivefold axes and two <110> directions are parallel to two twofold axes. There are in total 30 possible (i.e. calculated) $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ orientation variants with respect to a single icosahedron orientation in this OR, and the empty circles in the $<110>$ pole figure in Figure 4.12 (d) belong to the missing orientations not present in this cross section. It seems likely that all 30 twinned orientations are present in the full 3D crystal although this could not be confirmed in this work.


Figure 4.12 (a) The cross section of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ in arc-melted Al-1Cr. (b)-(c) EBSD Euler angle map of the crystal in (a) showing in total 12 orientations. The colour scheme is the same as in Figure 4.11. (c) is the enlarged Euler angle map at the crystal centre in (b). (d) Pole figure of the <101> and <110> directions of all 12 orientations in (b). (e) The unit cell wireframes of the 12 orientations in (b). (f) Pole figures of the fivefold and twofold axes of the standard icosahedron in (g). (g) The Cr1 icosahedral building block in the unit cell of orientation 3 in (b), and a standard icosahedron with the same orientation.

Figure 4.13 is a $3 \mathrm{D} \mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystal extracted from arc-melted $\mathrm{Al}-1 \mathrm{Cr}$ alloy. As indexed by the number, EBSD shows there are four orientations on the surface (2-2' and 3-3' share the same orientations).

Figure 4.13(b) are the Kikuchi patterns from the four orientations with many similarities and clear differences to each other. The <101> and <110> pole figures plotted in Figure 4.13(c) show that every
two of the four orientations $(1 \& 2,2 \& 3,3 \& 4)$ share the $180^{\circ}$ [1 $\left.\overline{1} 0\right]$ twinning relationship. All <101> and <110> directions from the four orientations partially form a combined icosahedron symmetry with a small deviation (the angle between two [110] and [1 $\overline{1} 0$ ] are $33.46^{\circ}$ instead of $36^{\circ}$ ), in comparison with the fivefold and twofold axes from a standard icosahedron. Figure 4.13(e) are the unit cell wireframes of the four $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ orientations with the standard icosahedron in the orientation of Figure 4.13(d). The four monoclinic unit cells are arranged spatially according to the parallelism between their <101> and the $i(5)$ of the icosahedron, and such distribution is consistent with their real geometry in Figure

### 4.13(a).



Figure 4.13(a) Extracted $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystal from arc-melted Al-1Cr alloy with four orientations on the top surface. (b) The Kikuchi pattern from the four orientations in (a). (c) <101> and <110> pole figures of the four orientations in (a). (d) Pole figues of $\mathrm{i}(5)$ and $\mathrm{i}(2)$ of an icosahedral orientation. (e) Unit cell wireframes of the four $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ orientations centred with the icosahedral orientation in (d).

Compared to the long ( $\sim 800 \mu \mathrm{~m}$ ) rod-like shape from slow cooling, $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ has a much smaller size ( $\sim 60 \mu \mathrm{~m}$ ) with a more blocky morphology through arc-melting. Figure 4.14 shows EBSD Euler angle maps of other $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals from the arc-melted $\mathrm{Al}-1 \mathrm{Cr}$ alloy, each containing multiple twinned orientations with the same combined icosahedral symmetry. The corresponding icosahedral orientations are plotted below, where all $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ orientations in each crystal share the same OR to the plotted icosahedrons. Similar to Figure 4.14, pole figures confirmed that all the pseudo-fivefold <101> and pseudo-twofold $<110>$ directions of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ are parallel to the fivefold and twofold axes of the icosahedrons. Geometrically, the twin boundaries are commonly coincident with edges and re-entrant corners of the crystals, indicating that the twinned domains, cooperatively and competitively, attain their final forms through the growth advantages of these geometric features.


Figure 4.14 EBSD Euler angle maps of the $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals from arc-melted Al-1Cr alloy with multiple twinned orientations forming icosahedral symmetry, with pole figures for the pseudo-fivefold (<101>) and pseudo-twofold (<110>) directions plotted below. The corresponding icosahedral orientations are plotted too, with pole figures for the fivefold and twofold axes. The colour scheme for the Euler angle map is the same as in Figure 4.11.

### 4.3.1.4 $\mathrm{Al}_{13} \mathrm{Fe}_{4}$

### 4.3.1.4.1 Single crystal of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$

For $\mathrm{Al}-3 \mathrm{wt} \%$ Fe alloy solidified at $1.2 \mathrm{~K} / \mathrm{min}$, about $40 \%$ of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ were single crystals with large ( $\sim 600 \mu \mathrm{~m}$ ) hexagonal rod-like shape. Two types of single crystal growth crystallography were found for $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, one with $<010>(\sim 70 \%)$ in the long rod direction and the other with $<001>$ ( $\sim 30 \%$ ) in the long rod direction, as overviewed in Figure 4.15 and Figure 4.16 respectively. For the first type, the crystal in Figure 4.15(a) has its long directions almost perpendicular to the paper, and the example in Figure 4.15(d) has its long direction near-parallel to the paper. The EBSD IPF-Z map in Figure 4.15(b) confirms only one orientation in the transverse cross section in Figure 4.15(a). Pole figures in Figure 4.15(c) and (f) show that the three main facets are $\{001\}($ red $),\{100\}$ (blue) and $\{\overline{2} 01\}$ (orange), and the long direction is $\langle 010\rangle$. The unit cell wireframes are also plotted in Figure 4.15(c) and (f).


Figure $4.15 \mathrm{Al}_{13} \mathrm{Fe}_{4}$ single crystals from slow cooling with <010> long direction. (a) A transverse cross section of an $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ hexagonal rod. (b) EBSD IPF-Z map of the crystal in (a). (c) Pole figure of the $\{001\}(\mathrm{red}),\{100\}($ blue ) and $\{\overline{2} 01\}$ (orange) planes, and the $<010>$ direction, together with the unit cell wireframe. (d) Extracted $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal with <010> long direction, with an illustration of the crystal morphology based on the growth habits. (e) $70^{\circ}$ tilt view of the crystal in (d), with the illustration of morphology in (a) tilted by $70^{\circ}$. (f) Pole figure of the \{001\}(red), \{100\}(blue) and \{201\}(orange) planes, and the <010> direction, together with the unit cell wireframe.

The second $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ single crystal growth morphology had <001> long direction, as in the example in

Figure 4.16. Figure 4.16(a) and (d) show two $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystals with their long direction perpendicular
and parallel to the paper. Pole figures in Figure 4.16(c) and (d) show that the main facets are $\{110\}$ (green) and $\{100\}$ (blue), and the long direction is <001>.


Figure $4.16 \mathrm{Al}_{13} \mathrm{Fe}_{4}$ single crystals from slow cooling with <001> long direction. (a) A transverse cross section of an $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ hexagonal rod. (b) EBSD Euler angle map of the crystal in (a). (c) Pole figure of the $\{110\}\left(\right.$ green ) and \{100\}(blue) planes, and the <001> direction. (d) Extracted $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal with <001> long direction, with a geometric model of the crystal morphology based on the growth habits. (e) $70^{\circ}$ tilt view of the crystal in (d), with the illustration of morphology in (d) tilted by $70^{\circ}$. (f) Pole figure of the $\{110\}$ (green) and $\{100\}$ (blue) planes, and the <001> direction for the orientation in (d).

### 4.3.1.4.2 <001>\{100\} twinning in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$

Around $60 \%$ of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystals were twinned for rods with either <010> or <001> long direction. Figure 4.17(a) shows an $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal with <010> long direction and nearly symmetrical morphology with a re-entrant corner. The EBSD IPF-Y map in Figure 4.17(b) shows two orientations in this crystal and the interface passes through the re-entrant corner. Kikuchi patterns from the two orientations are shown in Figure 4.17(c) and (d) with multiple near-parallel bands and zone axes, and some clear differences. The pole figure in Figure 4.17(e) shows that the two orientations share the common <010> long direction perpendicular to the paper, and the main facets on both sides are consistent with Figure 4.15. This is one of the three types of twinning reported previously in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ [233]: $180^{\circ}$ rotation around the <001> axis with $\{100\}$ being the interface (i.e. $\{100\}$ twinning). The twinning relationship is plotted using the two unit cell wireframes in Figure 4.17(e).


Figure $4.17 \mathrm{Al}_{13} \mathrm{Fe}_{4}\{100\}$ type twinning in $a<010>$ long rod from slow cooling. (a) A transverse cross section of a twinned $\mathrm{Al}_{13} F e_{4}$ rod with $\langle 010>$ long direction. The main facets are indexed. (b) EBSD IPF$Y$ map of the crystal in (a) showing two orientations with interface passing through the re-entrant corner. (c)-(d) The Kikuchi pattern from the two orientations in (b). (c) Pole figures of the main facets and long direction of the crystal in (a) showing the common \{100\} plane as the interface. The unit cell wireframes are also plotted showing the twinning relationship. (f) The transformation from $\mathrm{Al}_{13} F e_{4}$ monoclinic unit cell into pseudo-orthorhombic unit cell. (g) EBSD IPF-Y map of the crystal in (a) indexed with the orthorhombic structure. (h) Pole figure of the \{101\} planes and <010> direction of the two orthorhombic orientations in (g), with the unit cell wireframes and the twinning relationship between the orthorhombic unit cells.
$\mathrm{Al}_{13} \mathrm{Fe}_{4}$ has a pseudo-orthorhombic symmetry [237]. The transformation from the monoclinic unit cell into the pseudo-orthorhombic unit cell is plotted in Figure 4.17(f) with four monoclinic unit cells aligning along their $c_{m}$ axis. The angle between the new $a_{0}$ and $c_{0}$ is changed from $89.60^{\circ}$ to be exactly $90^{\circ}$ after the transformation. The transformation matrix for crystallographic planes is:

$$
\left(\begin{array}{l}
a \\
b \\
c
\end{array}\right)_{\text {orthorhombic }}=\left(\begin{array}{lll}
1 & 0 & 0 \\
0 & 1 & 0 \\
1 & 0 & 4
\end{array}\right)\left(\begin{array}{l}
a \\
b \\
c
\end{array}\right)_{\text {monoclinic }}
$$

Equation 4.1

Figure $4.17(\mathrm{~g})$ shows the EBSD IPF-Y map of the twinned $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal in (a) indexed with the orthorhombic structure. There are two orthorhombic orientations corresponding to the two monoclinic orientations in Figure 4.17(b), showing that the pseudo-orthorhombic symmetry does not cause the $\{100\}$ type twinning in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$. After transformation, the $\{100\}$ and $\{\overline{2} 01\}$ planes in the monoclinic unit cell merge into $\{101\}$ planes in the orthorhombic unit cell, as shown in pole figure in Figure 4.17 (h). It has been mentioned previously that the atomic structure on these two planes, $\{100\}$ and $\{\overline{2} 01\}$, are similar in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ [238]. For the orthorhombic unit cell, the twinning becomes a $36^{\circ}$ rotation around the common <010> direction and the twin plane becomes $\{101\}$.

The same twinning was also observed in the $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ rods with <001> long direction, as shown in Figure 4.18. Figure 4.18(a) is a typical cross section of an $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ hexagonal rod. The IPF-X map of this crystal is plotted in Figure 4.18(b), and there are two orientations with a sharp interface parallel to the facets. There are both strong similarities and some clear differences between their Kikuchi patterns in Figure 4.18(c) and (d). Similar to Figure 4.16, the main facets for twinned $\mathrm{Al}_{13} \mathrm{Fe}_{4}<001>$ rods are $\{100\}$ and $\{110\}$. Pole figures of the $\{100\}$ (blue) and $\{110\}$ (green) planes and $<001>$ directions for the two orientations are plotted in Figure 4.18(e), together with their unit cell wireframes. It is clear that the two orientations share the common <001> long direction, and the $\{100\}$ and $\{110\}$ facets are all parallel to each other, which are highlighted in Figure 4.18(a), together with the $\{100\}$ interface. Between the twinned orientations, it is a $180^{\circ}$ rotation around the common <001> direction, which is the same twin type as in Figure 4.17. The $\{100\}$ interface is highlighted in the unit cell wireframes, as well as the common $\{110\}$ planes and <001> direction.


Figure $4.18 \mathrm{Al}_{13} \mathrm{Fe}_{4}\{100\}$ type twinning in a <001> long rod from slow cooling. (a) A typical cross section of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ hexagonal rod. (b) The IPF-X map of the crystal in (a). (c)-(d) Selected Kikuchi patterns of the two orientations in (b). (e) Pole figure of the <001> direction and \{100\} and \{110\} planes of the two orientations in (b), and their unit cell wireframes.

### 4.3.1.4.3 Cyclic twinning in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ with combined decagonal symmetry

In the arc-melted ( $\sim 5 \mathrm{~K} / \mathrm{s}$ ) Al-3wt\% Fe alloy, $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ became much smaller ( $\sim 50 \mu \mathrm{~m}$ ) with more twinned orientations. The long direction was $\langle 010>$ and the shape was more complicated with multiple facets. It was confirmed here by EBSD that all $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystals after arc-melting were multi-twinned forming an overall decagonal symmetry, as shown in Figure 4.19. Figure 4.19(a) is a cross section of a typical $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal with multiple re-entrant corners from the arc-melted alloy, and Figure 4.19(b) shows the EBSD pattern quality map where the crystal is divided into many regions with a common origin and sharp interfaces. The orientation map in Figure 4.19(c) shows that there are seven monoclinic orientations in this cross-section of the crystal and their unit cell wireframes are plotted in Figure 4.19(d), together with three other undetected orientations to form the whole decagonal ring. Note that the colours in Figure 4.19(c) and (f) are manually chosen to separate different orientations without any meaningful indication of how the unit cells are oriented in space. The real orientations are shown by the unit cell wireframes in Figure 4.19(d) and (g). All ten monoclinic orientations share a common $<010>$ direction, which is the pseudo-tenfold axis in the $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal structure. All three types of twinning known in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ [233] are observed in this crystal: the $\{100\}$ pole figure shows between $2 \& 3,4 \& 5$ and $6 \& 7$ it is the $\{100\}$ twinning; the $\{\overline{2} 01\}$ pole figure shows between $1 \& 2$ and $3 \& 4$ it is the $\{\overline{2} 01\}$ twinning; and the $\{001\}$ pole figure shows between $3 \& 6$ and $4 \& 7$ it is the $\{001\}$ twinning.

Considering the pseudo-orthorhombic symmetry discussed with Figure 4.17 (f), the crystal was also indexed with the orthorhombic unit cell and the orientation map is shown in Figure 4.19(f). There are in total five orthorhombic orientations all at $36^{\circ}$ to each other, forming a decagonal symmetry along the <010> direction (Figure 4.19(g)). Comparing the pole figures in Figure 4.19(e) and (h), the $\{100\}$ and $\{\overline{2} 01\}$ merge into one family, $\{101\}$, in the orthorhombic structure and the two corresponding twinning types become one, with $\{101\}$ being the twin interface. The $\{001\}$ twinning disappeared in the orientation map due to the same orthorhombic orientations for $3 \& 6$ and $4 \& 7$, respectively,
indicating that this twinning is caused by the pseudo-orthorhombic symmetry of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$. As for the
monoclinic $\{100\}$ and $\{\overline{2} 01\}$ twinning, it is related to the pseudo-decagonal symmetry.


Figure 4.19 Multiple twinning in arc-melted $\mathrm{Al}_{13} \mathrm{Fe}_{4}$. (a) SE-SEM image of a cross section. (b) EBSD pattern quality map of the crystal in (a). (c) Orientation map of the crystal in (a) showing seven monoclinic orientations. (d) Monoclinic unit cell wireframes (with three orientations missing) forming a decagonal ring. (e) Pole figures of $\{100\},\{\overline{2} 01\},\{001\}$ and $<010>$ for the seven monoclinic orientations. (f) The orientation map of the crystal in (a) indexed with orthorhombic unit cell. 3\&6 and 4\&7 correspond to the same orthorhombic orientations. (g) The five orthorhombic unit cells in (f) forming a complete decagonal ring with every orientation occurring twice on opposite sides. (h) Pole figures of $\{101\},\{001\}$ and <010> for the five orthorhombic orientations. (i) The atomic configuration of the $\mathrm{Al}_{13} \mathrm{Fe}_{4}\{010\}$ plane in monoclinic structure forming the decagonal ring in (d). (j) The atomic configuration of the $\{010\}$ plane in orthorhombic structure forming the decagonal ring in ( $g$ ), with every orthorhombic orientation corresponding to two monoclinic orientations. Note that the colours in (c) and (f) are manually chosen to separate different orientations without any meaningful indication of how the unit cells are oriented in space. The real orientations are shown by the unit cell wireframes in (d) and (g).

A glide-reflection model in $\{100\}-\{\overline{2} 01\}$ twinning was first proposed by Black [234] and later confirmed by high resolution electron microscopy [233, 239]. By applying such mechanism to all ten monoclinic orientations a complete ring can be formed with $\{100\}$ and $\{\overline{2} 01\}$ being the interfaces, as shown in Figure 4.19 (i) [240]. The ten unit cell wireframes are plotted and numbered with comparison to the ones above. The atomic arrangement shows that the ten monoclinic unit cells form a decagonal structure with certain glides at the interface.

Figure 4.20 shows the same decagonal twinned symmetry in an extracted $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal, showing the 3D morphology of the cyclic twinned crystal. There are multiple facets along the common <010> direction, and EBSD mapping shows that the five facets on top correspond to five monoclinic or orthorhombic orientations, respectively (Figure 4.20(b) and (c)). The five orthorhombic unit cells are plotted in Figure 4.20(e), with pole figures showing the common <010> direction and five common \{101\} planes.


Figure 4.20 The extracted $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal with cyclic twinning forming decagonal symmetry. (a) $70^{\circ}$ tilt view of an extracted $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ from arc-melted AI-3Fe. (b) EBSD Euler angle map indexed with monoclinic structure superimposed on (a). (c) EBSD Euler angle map indexed with orthorhombic structure superimposed on (a). (d) Top view of the crystal in (a) with the <010> long direction highlighted. (e) $<010>$ and $\{101\}$ pole figures of the five orthorhombic orientations in (c) showing $36^{\circ}$ rotation along <010> (decagonal symmetry).

### 4.3.1.5 Summary of measured twin types

The results of solidification twinning in $\mathrm{Al}_{3} \mathrm{Ti}, \mathrm{Ag}_{3} \mathrm{Sn}, \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ measured at low and 'high' cooling rates are summarised in Table 4.3, including the percentage of twinned crystals, the measured twin type and the number of twin variants are also listed in the brackets at high cooling rate.

For slow cooling ( $1.2 \mathrm{~K} / \mathrm{min}, 0.02 \mathrm{~K} / \mathrm{s}$ for the Al -bearing IMCs and $0.05 \mathrm{~K} / \mathrm{min}, 0.0008 \mathrm{~K} / \mathrm{s}$ for $\mathrm{Ag}_{3} \mathrm{Sn}$ ), all $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{Ag}_{3} \mathrm{Sn}$ crystals were single crystals with $\{001\}$ being the main facets. In $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ crystals, two types of twinning were observed among $60 \%$ and there were up to four orientations in the twinned crystals. In $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, only one of the three reported twin types was observed and there were only two orientations measured in the twinned crystals.

At higher cooling rates ( $\sim 5 \mathrm{~K} / \mathrm{s}$ for the Al -bearing IMCs and $0.33 \mathrm{~K} / \mathrm{s}$ for $\mathrm{Ag}_{3} \mathrm{Sn}$ ), all IMCs were cyclic twinned. For $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{Ag}_{3} \mathrm{Sn}$, both were triple twinned forming combined cubic and hexagonal symmetry, respectively. For $\mathrm{Al}_{45} \mathrm{Cr}_{7}$, the twin types remained the same as at low rate but grew along multiple common <110> directions from the twinned orientations; the number of all possible twinned orientations can be up to 30 . For $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, all three twin types were observed within each crystal with up to 10 possible orientations in the twinned crystal. Furthermore, compared to the two possible growth directions (<010> and <001>) observed in slow cooling, $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ only grew along <010> in arcmelted samples.

Table 4.3 The growth twinning of the four IMCs from different cooling rates

| IMCs | Slow-cooled ( $0.05 \mathrm{~K} / \mathrm{min}$ for $\mathrm{Ag}_{3} \mathrm{Sn}$ and $1.2 \mathrm{~K} / \mathrm{min}$ for $\mathrm{Al}_{3} \mathrm{Ti}, \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ ) |  |  | Fast-cooled (20K/min for $\mathrm{Ag}_{3} \mathrm{Sn}$ ) or Arcmelted ( $\sim 5 \mathrm{~K} / \mathrm{s}$ for $\mathrm{Al}_{3} \mathrm{Ti}^{2}, \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ ) |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
|  | Percentage of twins | Twin type | Number of variants observed | Percentage of twins | Twin type | Number of variants observed |
| $\mathrm{Al}_{3} \mathrm{Ti}$ | 0\% | - | - | 100\% | $90^{\circ}<100>$ | 3(3) |
| $\mathrm{Ag}_{3} \mathrm{Sn}$ | 0\% | - | - | 100\% | $60^{\circ}<100>$ | 3(3) |
| $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ | ~60\% | $\begin{aligned} & 180^{\circ}[1 \overline{1} 0](110) \\ & 70.9^{\circ}[101](11 \overline{1}) \end{aligned}$ | 4 | 100\% | $\begin{gathered} 180^{\circ}[1 \overline{1} 0](110) \\ 70.9^{\circ}[101](11 \overline{1}) \end{gathered}$ | 12(30) |
| $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ | ~60\% | 180 ${ }^{\circ}$ [001](100) | 2 | 100\% | $\begin{aligned} & 180^{\circ}[001](100) \\ & 180^{\circ}[102]\{\overline{201\}} \\ & 180^{\circ}[100]\{001\} \\ & \hline \end{aligned}$ | 7(10) |

### 4.3.2 The role of cooling rate and undercooling

It has been widely reported previously that cooling rate has a significant influence on how deeply the melt can be undercooled prior to nucleation. It has been observed in many systems, including Al [241] and $\operatorname{Sn}[242,243]$ alloys, that the higher the cooling rate, the deeper the undercooling that can be achieved in the melt. In order to examine the relationship between undercooling and cooling rate and to attempt to decouple them, $\mathrm{Ag}_{3} \mathrm{Sn}$ was chosen for thermal analysis in DSC due to its low nucleation temperature in $\mathrm{Sn}-5 \mathrm{Ag}$ alloy (liquidus temperature ${ }^{\sim} 245^{\circ} \mathrm{C}$ ) compared to the other three IMCs (liquidus temperature $>700^{\circ} \mathrm{C}$ ) and the relative ease with which the melt undercools with respect to $\mathrm{Ag}_{3} \mathrm{Sn}$.

### 4.3.2.1 DSC study of $\mathrm{Ag}_{3} \mathrm{Sn}$

Cooling curves for $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation at different cooling rates are plotted in Figure 4.21. It is clear that the onset temperature for $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation decreases with increasing cooling rates. The mean nucleation temperature for $\mathrm{Ag}_{3} \mathrm{Sn}$ from over 10 balls for each cooling rate are plotted in grey in the histogram in Figure 4.22(a). For each cooling rate, 10 samples with a range of undercoolings were polished to examine the microstructure of $\mathrm{Ag}_{3} \mathrm{Sn}$ by SEM imaging and EBSD. The results are indicated by the red (single crystal) and blue (twinned crystal) circles in Figure 4.22(a) with respect to their $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation onset temperature. At low cooling rate ( $0.05 \mathrm{~K} / \mathrm{min}$ ), all $\mathrm{Ag}_{3} \mathrm{Sn}$ were single crystals. With increasing cooling rate ( $0.2,1.2$ and $5 \mathrm{~K} / \mathrm{min}$ ), more $\mathrm{Ag}_{3} \mathrm{Sn}$ grew as twinned crystals which tended to form at lower temperature compared to the single crystals, i.e. the twinned crystals formed with deeper undercooling. At the highest cooling rate $(20 \mathrm{~K} / \mathrm{min})$, all $\mathrm{Ag}_{3} \mathrm{Sn}$ formed as twinned crystals.


Figure 4.21 The cooling curves of Sn-5Ag balls at different cooling rate.

For $\mathrm{Ag}_{3} \mathrm{Sn}$, the mean undercooling at different cooling rates was obtained from Figure 4.22(a) assuming that the liquidus temperature for $\mathrm{Ag}_{3} \mathrm{Sn}$ in $\mathrm{Sn}-5 \mathrm{Ag}$ is $245^{\circ} \mathrm{C}$ (using the Thermo-Calc TCSLD3.2 database). Figure 4.22(b) quantifies the relationship between the twinning frequency and undercooling: the deeper the undercooling, the more likely that $\mathrm{Ag}_{3} \mathrm{Sn}$ grows as a twinned crystal. In order to visualise the nucleation temperature data, Figure 4.22 (c) shows box plots for all the nucleation onset temperatures collected from the five cooling rates. We can see that although, for each cooling rate, there is a wide range between the minimum and maximum value, the median and the mean value from each group give a clear trend that with the increasing cooling rate, the onset temperature for $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation decreases.


Figure 4.22 (a) Histogram of the mean nucleation temperature for $\mathrm{Ag}_{3} \mathrm{Sn}$ at different cooling rate, superimposed with the nucleation temperature of $\mathrm{Ag}_{3} \mathrm{Sn}$ from 10 individual samples in red (single crystal) and blue (twinned crystal) circles with corresponding microstructure.(b) The percentage of twinning $\mathrm{Ag}_{3} \mathrm{Sn}$ with respect to the mean undercooling from the five cooling rate in (a). (c) Box plot of all the $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation temperature obtained at the five cooling rate.

In Figure 4.22(c), the range of $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation temperatures at each cooling rate indicates the stochastic nature of the nucleation event in these small ( $\sim 500 \mu \mathrm{~m}$ diameter) balls. Figure 4.23 further confirms the stochastic nature of $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation through cyclic melting-cooling experiments. Figure 4.23(a) shows the cooling curve of $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation from a $\mathrm{Sn}-5 \mathrm{Ag}$ solder ball through 10 successive melting-cooling cycles with $5 \mathrm{~K} /$ min cooling rate. It is clear that the nucleation onset for $\mathrm{Ag}_{3} \mathrm{Sn}$ varies from cycle to cycle. Figure $4.23(b)$ is the measured onset temperature for $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation from three samples through the 10 cycles. It can be seen that the $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation temperature is rather random with respect to the cycle number, suggesting that the nucleation of $\mathrm{Ag}_{3} \mathrm{Sn}$ at each cycle is independent and stochastic. However, although the individual nucleation event appears to be stochastic, the whole group of statistical data in Figure 4.22(c) still reveal a clear relationship between the undercooling of $\mathrm{Ag}_{3} \mathrm{Sn}$ and cooling rate: the higher the cooling rate, the deeper the undercooling that can be achieved in the melt.


Figure 4.23 The stochasticity of $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation. (a) The cooling curve of $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation from a Sn 5 Ag solder ball through 10 successive melting-cooling cycles with cooling rate at $5 \mathrm{~K} / \mathrm{min}$. (b) $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation temperature from three samples through the 10 successive melting-cooling cycles.

The relationship between the measured undercooling for $\mathrm{Ag}_{3} \mathrm{Sn}$ and cooling rate are plotted in Figure 4.24: the mean undercooling increases with cooling rate with a near-linear increase of $\ln \Delta T_{c}$ with respect to $\ln \Delta \dot{T}$, as shown in the inset plotted using logarithmic coordinates at the right bottom corner in Figure 4.24. This relationship is consistent with past work on other systems [244-246].


Figure 4.24 The relationship between mean undercooling for $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleation and cooling rate. ( $a=18.6, k=0.17$ for the fitting curve)

### 4.3.3 Summary

It has been found that crystals of $\mathrm{Al}_{3} \mathrm{Ti}$ (tetragonal), $\mathrm{Ag}_{3} \mathrm{Sn}$ (orthorhombic), $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ (monoclinic) and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ (monoclinic) tend to form cyclic twins with overall cubic, hexagonal, icosahedral and decagonal symmetry, respectively, at higher cooling rate. For $\mathrm{Ag}_{3} \mathrm{Sn}$, DSC experiments at different cooling rate show that such cyclic twinning tends to form when $\mathrm{Ag}_{3} \mathrm{Sn}$ nucleates at lower temperature (i.e. deeper undercooling). It has also been confirmed that the mean nucleation temperature decreases with increasing cooling rate, i.e. the higher the cooling rate, the deeper the undercooling that is likely to be achieved in the melt. Therefore, it appears that the cyclic twinning forms due to the undercooling in the melt introduced by the faster cooling rate. It is interesting to note, however, that the cooling rates and undercoolings required to trigger cyclic twinning in this work are relatively modest and much less than would exist in rapid solidification approaches. The formation mechanisms for the cyclic twinning in the four IMCs are discussed in the next section.

### 4.4 Discussion

Following Buerger [247], twins are often classified by their origin into growth twins, transformation twins and mechanical twins. Growth twins refer to crystallisation from a gas or liquid and include twin formation both (i) at the crystal nucleation stage and (ii) during crystal growth. In their review on the twinning of crystals, Hahn and Klapper [248] give two geometric features that are signatures of twinning at the nucleation stage: (1) all twin domains appear to originate from one point near the centre of the twinned crystal; and/or (2) the twin domains have roughly the same size. These features are clearly evident for the four IMCs solidified at the higher cooling rates in this work. For example, examining the $\mathrm{Al}_{3} \mathrm{Ti}$ in Figure 4.5, $\mathrm{Ag}_{3} \mathrm{Sn}$ in Figure 4.7, $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ in Figure 4.12-Figure 4.14, and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ in Figure 4.19, it appears that in every twinned crystal all domains point back to a common centre (which is unlikely to be in these cross sections), indicating a shared origin. Thus, it is likely that twinning initiated at the crystal nucleation stage or in the very early stages of growth.

In each IMC studied here, the multiple-twinned orientations have the combined symmetry of the 'parent' structure to which the IMCs are superstructures or approximants: FCC, HCP, iQC or dQC. Thus, it is likely that a metastable phase with this higher symmetry (crystalline or quascisytalline) formed first in the undercooled melt and then nucleated and/or transformed into the lower-symmetry stable structure with multiple orientation variants. This is similar to the hypothesis proposed by Senechal [249], that twin formation during nucleation is likely to be caused by a metastable modification with a structure existing for very small dimensions which is different from the macroscopic stable phase. After the nucleus reaches a critical size where the translation symmetry becomes decisive, it will collapse into a twinned crystal of the stable phase with lower symmetry.

Since these IMCs have a group-subgroup relationship with their parent phase, the number of orientation variants is given by the ratio of the point group order of the parent phase to the point group order of the child phase [248, 250], listed as h/l in Table 4.4. Looking back at Figure 4.5(f), Figure 4.7(f), Figure 4.12, Figure 4.19 and Table 4.3, it can be confirmed that the number of orientation variants observed is consistent with the ratio in Table 4.4, considering that, for $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ the cyclic twin
grows radially in three dimensions, and the 2D sections only revealed a plane containing 12 of the 30 variants.

Table 4.4 Group-subgroup relations for the four parent structure

| IMCs | Point <br> group | Order of point <br> group (I) | Parent <br> structure | Point <br> group | Order of point <br> group $(\mathrm{h})$ | Ratio h/I |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| $\mathrm{Al}_{3} \mathrm{Ti}$ | $4 / \mathrm{mmm}$ | 16 | FCC | $\mathrm{m} \overline{3} \mathrm{~m}$ | 48 | 3 |
| $\mathrm{Ag}_{3} \mathrm{Sn}$ | mmm | 8 | HCP | $6 / \mathrm{mmm}$ | 24 | 3 |
| $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ | $2 / \mathrm{m}$ | 4 | iQC | m $\overline{3} \overline{5}$ | 120 | 30 |
| $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ | $2 / \mathrm{m}$ | 4 | dQC | $10 / \mathrm{mmm}$ | 40 | 10 |

The formation of a multiply twinned crystal at or shortly after the nucleation stage could occur in various ways:
(A) it is possible that the nucleus itself is twinned, similar to the suggestions in Ref. [251].
(B) Alternatively, a metastable phase of high symmetry could nucleate and then transform into the stable phase to produce a multiply twinned seed crystal, with multiple orientation domains resulting from multiple variants of the orientation relationship. This is similar to many solid-state transformations involving a group-subgroup relation that produce domain twins when low symmetry crystals form from high symmetry parent phases. Examples include monoclinic $\eta^{\prime}-\mathrm{Cu}_{6} \mathrm{Sn}_{5}$ from $\eta$ hexagonal $\mathrm{Cu}_{6} \mathrm{Sn}_{5}$ [252]; monoclinic $\eta^{\prime}-\mathrm{Al}_{8} \mathrm{Fe}_{3}$ from orthorhombic $\eta-\mathrm{Al}_{5} \mathrm{Fe}_{2}$ [253]; and tetragonal $\mathrm{L1}_{0^{-}}$ FePd from cubic A1-(Fe,Pd) [254]. The difference in the present case is that the 'solid-state' transformation occurs when only a very small fraction of solid exists and most of crystallisation is yet to occur. Here, the formation of all orientation variants is likely to minimise lattice strain. For example, in $\mathrm{Al}_{3} \mathrm{Ti}$ with lattice parameters given in Figure 4.5(g), the length of a in tetragonal $\mathrm{Al}_{3} \mathrm{Ti}$ is shorter than that in both cubic structures, while the half length of c (4.29Å) is longer than a in both cubic structures. Due to this tetragonal distortion, the solid phase transformation of a cubic structure into a single tetragonal orientation would involve contraction along the $a$ and $b$ directions, and expansion along the c direction. In comparison, through triple twinning, the c direction of one tetragonal orientation is parallel to the $a$ and $b$ directions of the other two orientations, which cancels out most of the
contraction and expansion in the lattice. $\mathrm{Ag}_{3} \mathrm{Sn}$ has a small orthorhombic distortion, with $\frac{2 c}{b}=1.72$ which is $0.7 \%$ less than the value $(\sqrt{3})$ of the HCP parent structure (Figure $4.7(\mathrm{~g})$ ) and the formation of cyclic twinned $\mathrm{Ag}_{3} \mathrm{Sn}$ cancels out most of the strain in the lattice. Similar effects are likely for $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ transforming from an iQC or dQC.
(C) Alternatively, the metastable phase could act as a nucleant particle for the stable phase with multiple variants of a nucleation OR. This is similar to heterogeneous nucleation on certain inoculant particles. For example, there are two orientation variants when FCC-AI nucleates on the (0001) facet of hexagonal $\mathrm{TiB}_{2}$ [229], and six orientation variants when $\mathrm{Al}_{3}$ Ti nucleates on the (0001) of $\mathrm{TiB}_{2}$ [255]. There are equivalent examples with peritectic reactions $L+S 1 \rightarrow S 2$, if S1 is a higher symmetry parent phase of S 2 with a group-subgroup relation, as would be the case for $\mathrm{L}+\zeta-\mathrm{Ag} \rightarrow \mathrm{Ag}_{3} \mathrm{Sn}$ at high Ag content since $\zeta$-Ag is HCP. For all four IMCs studied here, the nucleation barrier on the high symmetry parent phases is expected to be small due to the small lattice disregistry. For example, $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{Ag}_{3} \mathrm{Sn}$ differ from their parent phases only by chemical ordering and a small distortion (Figure 4.5(g) and Figure $4.7(\mathrm{~g})$ )), and $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ are likely to be similarly closely related to an iQC and dQC.

Some combination of mechanisms (A), (B) and (C) may also be feasible noting that, at very small dimensions, the differences between these mechanisms may not be clear cut.

Cooling rate had a significant influence on solidification twinning in this study. At sufficiently high cooling rate, all crystals were 'fully cyclic twinned' with all orientation variants present in all four IMCs studied. At low cooling rate, $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{Ag}_{3} \mathrm{Sn}$ were all single crystals, and $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ were either single crystals or 'partially twinned' where only a subset of the orientation variants were present (Table 4.3). The DSC experiments on $\mathrm{Ag}_{3} \mathrm{Sn}$ in Figure 4.24 showed that the role of increasing cooling rate is mostly to deepen the nucleation undercooling and, given that this relationship has been reported widely for other systems, it is expected that the increasing cooling rate also deepened the nucleation undercooling of $\mathrm{Al}_{3} \mathrm{Ti}_{1} \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$. Based on this, it is likely that the formation of single crystals at low cooling rate is due to the stable IMCs nucleating first in the melt (and not a
metastable phase). For the fully cyclic twinned crystals at the higher cooling rates, it is likely that a metastable phase formed first and nucleated/transformed into the stable phase with all orientation variants. It is then interesting to consider why, at low cooling rate, some $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ were partially twinned with only a subset of the orientation variants (Figure 4.9, Figure 4.11, Figure 4.17 and Figure 4.18). One possibility is that the extent of twinning depends on the size of the metastable high symmetry phase at the moment when the stable lower-symmetry phase forms; the higher the cooling rate and/or deeper the undercooling, the larger size the metastable phase reaches before the stable phase begins growing. For nucleation on the high-symmetry phase, a larger particle has more surface area on which nucleation events could occur increasing the chances of multiple OR variants nucleating. For the transformation of the high symmetry phase into domains of the lower-symmetry phase, the larger the particle the more domains it is likely to break up into. For a large enough crystal/quasicrystal of the high symmetry phase, all OR variants would form.

Twinning during nucleation or the early stage of growth also has an influence on the subsequent crystal growth. $\mathrm{Ag}_{3} \mathrm{Sn}$ and $\mathrm{Al}_{3} \mathrm{Ti}$ grow as plates as single crystals. When they are cyclic twinned, they can grow as an equiaxed shape which can more easily fill 3D space. Similarly, $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ grows as rods as single crystals. When $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ is cyclic twinned, it grows as a more equiaxed shape that is more easily able to fill 3D space. The geometric features formed by twinned crystals, such as re-entrant corners, facilitate atomic attachment and, therefore, it is favourable to retain the twinned orientations during crystal growth.

It has been observed previously that metastable phases with the parent structure of the four IMCs in Table 4.4 can form during rapid solidification, which involves considerably higher cooling rates than those studied here. In Al-2Ti and Al-5Ti alloys rapidly solidified by melt spinning, metastable cubic $\mathrm{L1}_{2^{-}}$ $\mathrm{Al}_{3} \mathrm{Ti}$ has been observed to coexist with the FCC solid solution containing up to $4 \mathrm{wt} . \% \mathrm{Ti}$ [256]. The same $\mathrm{LI}_{2}$ structure has also been observed in $\mathrm{Al}_{3} \mathrm{Zr}$ and $\mathrm{Al}_{3} \mathrm{Hf}$ through rapid solidification, and all the cubic phases transformed into the corresponding stable tetragonal phases after reheating [257, 258].

An iQC phase has been confirmed in a rapidly solidified Al-Cr alloy through X-ray [114, 259], electron [115, 116] and neutron [117] diffraction methods. After reheating the iQC metastable phase transformed into crystalline $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ with the fivefold and threefold rotational twins of $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ [125]. The tenfold twins of $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ have also been observed previously in coexistence with the $\mathrm{Al}-\mathrm{Fe}$ decagonal quasicrystals in rapidly solidified Al-Fe alloys [260]. Since this past work has shown that these metastable phases can occur in similar alloy compositions at higher cooling rate, it seems reasonable that they may also form at the nucleation stage at the moderate cooling rates in this work but do not grow to a significant size before the stable phase forms.

To explore this further, calculations were performed using Thermo-Calc with the TCSLD3.2 and TCTI2.0 databases for the $\mathrm{Ag}-\mathrm{Sn}$ and $\mathrm{Al}-\mathrm{Ti}$ systems respectively. Metastable liquidus lines were calculated by suppressing the stable $\mathrm{IMCs}\left(\mathrm{Ag}_{3} \mathrm{Sn}\right.$ and $\left.\mathrm{Al}_{3} \mathrm{Ti}\right)$ from the calculations. Figure 4.25 compares the DSC information with the stable and metastable phase diagram of the $\mathrm{Ag}-\mathrm{Sn}$ system. The plot of DSC results in Figure 4.25 is the same as in Figure 4.22(a). The plot is shown here to compare with the thermodynamic calculations. If cyclic twinned crystal growth occurs when the HCP phase nucleates first in the melt, the cyclic twinned nucleation temperature must be below the metastable HCP liquidus line. The calculated metastable HCP liquidus temperature is close to the highest measured temperature at which cyclic twinning was observed, which is reasonably consistent with this interpretation. Figure 4.26 shows stable and metastable phase diagrams in the AI-Ti system. Here, the metastable liquidus lines of the $\mathrm{A} 1-\mathrm{FCC}$ phase and the metastable $\mathrm{L1}_{2}-\mathrm{Al}_{3} \mathrm{Ti}$ superstructure are shown. The $\mathrm{L1}_{2}$ phase liquidus line is significantly closer to the stable $\mathrm{DO}_{22}-\mathrm{Al}_{3} \mathrm{Ti}$ liquidus and is, therefore, more likely to have nucleated than disordered FCC. According to the calculations, an undercooling of $\sim 60 \mathrm{~K}$ is required for the $\mathrm{L} 1_{2}$ phase to become metastable in an AI-3Ti melt. This is a significantly deeper undercooling than the ${ }^{\sim} 15 \mathrm{~K}$ required for HCP to be metastable in a $\mathrm{Sn}-5 \mathrm{Ag}$ melt, which is consistent with a higher cooling rate being required to trigger cyclic twinning in $\mathrm{Al}_{3} \mathrm{Ti}$ than in $\mathrm{Ag}_{3} \mathrm{Sn}$. However, it was not possible to measure nucleation temperatures in $\mathrm{Al}-3 \mathrm{Ti}$ in this work so it was not possible to fully confirm this interpretation.


Figure 4.25 The comparison between the DSC measurement and the stable and metastable phase diagram of the Ag-Sn system from Thermo-Calc TCSLD3.2 database.


Figure 4.26 The stable and metastable phase diagrams in the AI-Ti system from Thermo-Calc TCTI2.0 database.

The iQC and dQC phases are not included in the thermodynamic databases used so similar metastable phase diagram calculations were not conducted. However, past papers have discussed the competitive nucleation of quasicrystals versus crystalline phases. It was first proposed by Frank that icosahedral short-range order is favoured in undercooled metallic melts [133]. As reviewed in Chapter 2, according to classical nucleation theory [261], the nucleation barrier for heterogeneous nucleation is:

$$
\Delta G^{*}=\frac{16 \pi}{3} \cdot \frac{\gamma_{s l^{3}}}{\Delta G^{2}} \cdot f(\theta)
$$

Equation 4.2

Where $\Delta G$ is the Gibbs free energy difference between the solid and liquid phase, $\gamma_{s l}$ is the solid-liquid interfacial energy, and $f(\theta)$ is the geometric factor for heterogeneous nucleation.

Various authors [262,263] have shown that the nucleation barrier, $\Delta G^{*}$, for an iQC is lower compared to a crystalline phase in an undercooled melt. Through undercooling experiments it was confirmed that an iQC has lower interfacial energy with the melt compared to the crystalline compounds containing polytetrahedral building blocks [262]. If the S-L interfacial energy of the metastable phase is lower than that of the more stable phase, the metastable phase can be stabilised at small size by the Gibbs-Thomson effect. Therefore, a metastable icosahedral structure, and possibly an iQC phase, is likely to form in the undercooled melt. Similar arguments have been made by Rappaz et al.[28]

According to the literature [262], the S-L interfacial energy for the Al-Fe decagonal quasicrystal ( $\sim 0.112$ $\left.\mathrm{J} / \mathrm{m}^{2}\right)$ is also lower than the stable $\mathrm{Al}_{13} \mathrm{Fe}_{4}\left(\sim 0.159 \mathrm{~J} / \mathrm{m}^{2}\right)$, indicating that the nucleation barrier can also be lower for a decagonal quasicrystal than $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ in an undercooled melt (Eq. 4.2).

For $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystal from arc-melting, such as that in Figure 4.19, the decagonal symmetry formed by the cyclic twinning indicates that it was caused by a decagonal quasicrystal. As illustrated in Figure 4.19(i), it has been suggested that decagonal quasicrystals transform directly into monoclinic $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ [240]. However, there are two features which suggest that the measured seven monoclinic $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ orientations may not have grown directly from a decagonal quasicrystal: (i) in the orientation map in Figure 4.19(c), the same orientations (except 3) have been observed twice on both sides, which should
not happen if a decagonal quasicrystal directly nucleates/transforms into ten monoclinic orientations; and (ii) whilst most orientations form simple segments emanating from the crystal centre, the interfaces between $3 \& 6$ and $4 \& 7$ are quite different and might not have grown from the same centre. This issue with $3 \& 6$ and $4 \& 7$ disappears in the orthorhombic orientation map (Figure 4.19(f)), suggesting the $\{001\}$ twinning may have formed through a different mechanism relating to its pseudoorthorhombic symmetry.

There is a proposed high-temperature $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ phase which has the same orthorhombic structure we studied above [237]. The geometrical feature of the sector twins is that the orientation domains share a common origin near the centre of the cross section. When the decagonal structure nucleates and/or transforms into the five orthorhombic orientations with $36^{\circ}$ to each other at high temperature, the five orthorhombic unit cells duplicate on the opposite side around the shared centre to retain the decagonal symmetry and form sharp $\{101\}$ interfaces emanating from the crystal centre (Figure 4.19(j)). Thus, the arrangement of the twin domains is consistent with an orthorhombic phase growing from a decagonal phase first and then transforming into the monoclinic phase. A similar phenomenon was observed in NiZr droplet with a single decagonal seed growing into five orthorhombic orientations in an undercooled melt through electrostatic levitation, forming tenfold twins with sharp $\{110\}$ interfaces [230]. Further decreasing the temperature makes the $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ orthorhombic phase transform into the stable monoclinic structure and each orthorhombic orientation breaks down into two monoclinic ones, forming $\{001\}$ twinning inside the grain with different geometry. Theoretically there should be 10 monoclinic orientations, but in reality there is a chance that one orthorhombic orientation transforms into only one monoclinic orientation, and/or the other monoclinic orientations may not have been sectioned in this 2D map.

### 4.5 Conclusions

In this chapter, a detailed study of solidification twinning in four intermetallic compounds, $\mathrm{Ag}_{3} \mathrm{Sn}, \mathrm{Al}_{3} \mathrm{Ti}$, $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, has been conducted, combining SEM imaging, EBSD and DSC. The following main conclusions can be drawn:

1. In slow cooling ( $1.2 \mathrm{~K} / \mathrm{min}$ for $\mathrm{Al}_{3} \mathrm{Ti}^{2} \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, and $0.05 \mathrm{~K} / \mathrm{min}$ for $\mathrm{Ag}_{3} \mathrm{Sn}$ ), crystals grew into large plates $\left(\mathrm{Ag}_{3} \mathrm{Sn}\right.$ and $\left.\mathrm{Al}_{3} \mathrm{Ti}\right)$ or long rods $\left(\mathrm{Al}_{45} \mathrm{Cr}_{7}\right.$ and $\left.\mathrm{Al}_{13} \mathrm{Fe}_{4}\right)$ with high aspect ratio. All $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{Ag}_{3} \mathrm{Sn}$ were single crystals with their main facets being \{001\}. Around $60 \% \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystals were twinned, with two twin types for $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and only one twin type for $\mathrm{Al}_{13} \mathrm{Fe}_{4}$. For $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ the long direction was $<1 \overline{1} 0>$, and for $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ it was $<010>$ or $<001>$.
2. Compared to slow cooling, $\mathrm{Al}_{3} \mathrm{Ti}^{2}, \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ from higher cooling rate grew into much smaller size with lower aspect ratio. All crystals were twinned with more complicated morphologies. There were more twinned orientations observed in each crystal and two additional twin types were measured in $\mathrm{Al}_{13} \mathrm{Fe}_{4}$.
3. Twin boundaries were found to be commonly coincident with edges and re-entrant corners which gives growth advantage to attain the final twin form.
4. The multiple-twinned orientations in the four IMCs form the combined pseudo-symmetries of their parent structure, and the total number of the twinned variants equals the ratio of the point group order between its parent structure and the IMC.
5. The combined parent symmetry formed by the twinned orientations, and the geometrical features of their corresponding domains indicate that a metastable phase with high symmetry is likely to form first in the undercooled melt at higher cooling rate and then nucleate/transform into the stable low-symmetry crystal. In $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, there were indications that this may occur in a three stage process: (i) a decagonal structure forms first in the melt, (ii) an orthorhombic phase nucleates/transforms on/from this seed and then (iii) transforms into the stable monoclinic phase.
6. The solidification orientation relationships between the stable crystals and their corresponding metastable parent phases are:
$\mathrm{Al}_{3} \mathrm{Ti}:\{001\}_{\mathrm{A} 13 \mathrm{Ti}}| |\{001\}_{\mathrm{FCC} / L 12}$, with $<100>_{\mathrm{Al} 3 \mathrm{Ti}}| |<100>_{\mathrm{FCC} / L 12} ;$
$\mathrm{Ag}_{3} \mathrm{Sn}:\{001\}_{\mathrm{Ag} 3 \mathrm{Sn}}| |\{1 \overline{1} 00\}_{\mathrm{hcp}}$, with $\left.\langle 100\rangle_{\mathrm{Ag} 3 \mathrm{Sn}}| |<0001\right\rangle_{\mathrm{hcp}} ;$
$\mathrm{Al}_{45} \mathrm{Cr}_{7}:<101>_{\mathrm{A} 145 \mathrm{Cr} 7}| | i(5)$ and $\langle 110\rangle_{\mathrm{A} 145 \mathrm{Cr} 7}| | i(2) ;$
$\mathrm{Al}_{13} \mathrm{Fe}_{4}:\langle 010\rangle_{\text {mono }}| |<010>_{\text {orth }}| | d(10)$, and $<001>_{\text {mono }}| |<101>_{\text {orth }}| | d(2)$.

## Chapter 5 Solidification ORs between equiaxed neighbouring grains in

## Al and Mg alloys

### 5.1 Introduction

So far we have seen different OR formation mechanisms during solidification. Between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$, ORs can be formed through nucleation and pushing \& engulfment processes. Twinning ORs between different domains inside an intermetallic crystal $\left(\mathrm{Al}_{3} \mathrm{Ti}, \mathrm{Ag}_{3} \mathrm{Sn}, \mathrm{Al}_{45} \mathrm{Cr}_{7}\right.$ and $\left.\mathrm{Al}_{13} \mathrm{Fe}_{4}\right)$ can form due to the nucleation and/or solid transformation from a metastable parent structure. In this Chapter, the formation of preferred interfaces in equiaxed solidification is explored, building from past work that has shown a significant above-random population of $60^{\circ}$ grain boundaries in FCC phases after equiaxed solidification. Kurtuldu et al. measured large amounts of $60^{\circ}$ twinning grain boundaries and showed that clusters of these grains form overall icosahedral symmetry after equiaxed solidification in $\mathrm{Al}-\mathrm{Zn}$ and $\mathrm{Au}-\mathrm{Ag}-\mathrm{Cu}$ alloys with addition of 1000 ppm Cr and 200 ppm Ir , respectively [23, 24]. According to Kurtuldu et al., this is most likely due to the nucleation of the FCC phase from icosahedral quasicrystals formed in the undercooled melt. In this Chapter, we investigate the formation mechanism for preferred grain boundaries after equiaxed solidification of different Al and Mg alloys. The alloy systems were selected based on the following criteria:

1. Equiaxed grains are formed during solidification.
2. Alloys with and without grain refiner additions.
3. Alloys with potential icosahedral nucleation activity based on past work [23].
4. Alloys with different grain size (coarse and refined) and shape (dendritic and globular).
5. Alloys that solidify with different crystal structure (FCC and HCP) to test the generality of the findings.

Based on the criteria above, three cast Al alloys (Al-20wt.\%Zn, Al-15wt.\%Cu and $\mathrm{Al}-6 \mathrm{wt} . \% \mathrm{Cu}$ inoculated with 1wt.\% Al-5Ti-B master alloy) and two cast Mg alloys (Mg-9wt.\%Al-0.7wt.\%Zn inoculated with $\mathrm{FeCl}_{3}$ powder and $\mathrm{Mg}-9 \mathrm{wt} . \% \mathrm{Al}-0.7 \mathrm{wt} . \% \mathrm{Zn}$ inoculated with $\mathrm{Al}_{4} \mathrm{C}_{3}$ particles) were
studied. Note that these alloys all form fully-equiaxed microstructures during solidification under gravity casting conditions due to their high solute content and, in the case of the inoculated alloys, due to the presence of heterogeneous nucleant particles. This Chapter has three main aims: (i) to compare the solidification texture with ideal random texture for both FCC and HCP structures, (ii) to identify the preferred grain boundaries and ORs between the neighbouring grains, and (iii) to explain the origin of the observed solidification ORs.

### 5.2 Methods

### 5.2.1 Sample preparation

Five cast alloys were prepeared in this study: Al-20wt.\% Zn, Al-15wt.\% Cu, Al-6wt.\%Cu with $1 \mathrm{wt} . \% \mathrm{Al}-$ 5Ti-B master alloy, $\mathrm{Mg}-9 \mathrm{wt} . \% \mathrm{Al}-0.7 \mathrm{wt} . \% \mathrm{Zn}$ with $\mathrm{FeCl}_{3}$ and $\mathrm{Mg}-9 \mathrm{wt} . \% \mathrm{Al}-0.7 \mathrm{wt} . \% \mathrm{Zn}$ with $\mathrm{Al}_{4} \mathrm{C}_{3}$. CP Al ingot, 99.9\% Zn ingot, Al-50wt.\% Cu master alloy and Al-5Ti-1B rods supplied by the London and Scandinavian Metallurgical Company were used for the casting of Al alloys. The composition for CP Al is listed in Table 4.2. The alloys were heated to $750^{\circ} \mathrm{C}$ in a BN-coated clay-bonded graphite crucible in a resistance furnace. After holding for 4 hours, the melt was stirred with an $\mathrm{Al}_{2} \mathrm{O}_{3}$ rod and then poured into the steel mould with BN coating pre-heated to $300^{\circ} \mathrm{C}$. Three Al alloys were cast in steel moulds with three different shapes as shown in Figure 5.1: (a) inner height 100 mm and inner diameter 20 mm for $\mathrm{Al}-20 \mathrm{wt} . \% \mathrm{Zn}$, (b) inner height 110 mm and inner diameter 85 mm for $\mathrm{Al}-15 \mathrm{wt} . \% \mathrm{Cu}$ and (c) inner height 60 mm and inner diameter 50 mm for $\mathrm{Al}-6 \mathrm{Cu}$ with $1 \mathrm{wt} . \% \mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ master alloy.


Figure 5.1 Three types of steel mould used in this study to cast Al alloys. (a) inner height 100 mm and inner diameter 20 mm for Al-20wt.\% Zn, (b) inner height 110 mm and inner diameter 85 mm for Al$15 \mathrm{wt} . \% \mathrm{Cu}$ and (c) inner height 60 mm and inner diameter 50 mm for Al-6Cu with $1 \mathrm{wt} . \%$ Al-5Ti-1B master alloy.

For the casting of Mg-9wt.\%Al-0.7wt.\%Zn, AZ91 with composition listed in Table 5.1 was used and two grain refiners were added in this study: $\mathrm{FeCl}_{3}$ powder and $\mathrm{Al}_{4} \mathrm{C}_{3}$ powder. For the $\mathrm{FeCl}_{3}$ addition, the melt was held at $725^{\circ} \mathrm{C}$ for 1 hour. Next, 1.0 wt. \% of anhydrous $\mathrm{FeCl}_{3}$ powder wrapped in Al foil was plunged into the melt and stirred for 30 s with a BN-coated steel rod. After being held for 20 minutes, samples of the melt were poured at $700^{\circ} \mathrm{C}$ into a $200^{\circ} \mathrm{C}$ Cu mould coated with a thin film of BN . For
the $\mathrm{Al}_{4} \mathrm{C}_{3}$ addition, powder with $24 \mu$ m mean grain size and $99+\%$ purity was used. The $\mathrm{AZ91}$ melt was first held at $650{ }^{\circ} \mathrm{C}$ for 1 hour. Next, $3.5 \mathrm{wt} . \%$ of $\mathrm{Al}_{4} \mathrm{C}_{3}$ powder wrapped in Al foil was added to the melt and stirred for 1 h with a BN-coated stainless steel stirrer incorporated into the furnace. Samples of the melt were then poured at $650^{\circ} \mathrm{C}$ into a $200^{\circ} \mathrm{C}$ stainless steel mould coated with BN .

Table 5.1 The composition of AZ91 used in this work

| Element | Mg | Al | Zn | Mn | Fe | Cu | Ni | Si |
| :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: | :---: |
| Composition (wt. \%) | Bal. | 8.97 | 0.74 | 0.15 | 0.002 | 0.002 | 0.003 | 0.01 |

Cast alloys were cut into small samples and metallographic polishing was carried out with colloidal silica by standard preparation methods. For EBSD characterisation, Ar-ion milling on a Gatan PECSII instrument was applied with 2 kV accelerated beam at an incidence angle of $4^{\circ}$ for 40 min . For EBSD investigation, a Zeiss Sigma field emission gun SEM fitted with a Bruker e-FlashHR EBSD detector was used. Bruker Esprit 2.0 software was applied to analyse the misorientation across grain boundaries and the orientation relationship between grains. MTEX 5.2 .7 toolbox within MATLAB ${ }^{\text {TM }} 9.2$ (Mathworks, USA) [206] was used to process EBSD data. The threshold for the misorientation inside a grain was set to be $5^{\circ}$.

Due to the eutectic mixture between the $\alpha-\mathrm{Al}$ dendrite arms in $\mathrm{Al}-15 \mathrm{Cu}$ cast alloy, EBSD maps were reconstructed by MTEX to form Al-Al grain boundaries as shown in Figure 5.2 so as to examine the orientation relationships between neighbouring $\alpha$-Al grains.


Figure 5.2 Reconstruction of $\alpha-A I$ dendritic EBSD mapping by MTEX. (a) EBSD IPF-Z map of $\alpha-A /$ dendrites in Al-15Cu alloy. (b) IPF-Z map of $\alpha-A l$ dendrites in (a) plotted by MTEX. (c) Reconstruction of the EBSD mapping in (b) forming grain boundaries between neighbouring $\alpha-A /$ grains by MTEX.

### 5.2.2 DFT calculations of interfacial energies

In order to compare the interfacial energy at different grain boundaries measured in this work, DFT calculations were performed for Al symmetric interfaces using the Vienna Ab Initio Simulation Package (VASP) framework [207]. A planewave basis set and projector augmented wave (PAW) pseudopotentials [208] were used. The generalised gradient approximation (GGA) in the formalism of Perdew-Burke-Ernzerhof (PBE) was chosen for the exchange and correlation energy functional [209]. All parameters were converged to satisfy a criterion of $10^{-4} \mathrm{eV}$ for Al in its pure form, where $3 \mathrm{~s}^{2} 3 \mathrm{p}^{1}$ electrons were treated explicitly (they are not included in the core when forming the pseudopotentials). It was determined that an energy cutoff of $350 \mathrm{eV}, k$ point density of $\sim 0.025 \AA^{-1}$ and Methfessel Paxton smearing width of 0.1 eV [210] were sufficient and were kept consistent for the calculations.

Four interfaces were constructed as shown in Figure 5.3 superimposed with the Al unit cell wireframes. The $\{111\}$ twin boundary is formed by $70.5^{\circ}$ tilt along $<110>$, and further tilt in the same direction forms $\{112\}\left(109.5^{\circ}\right),\{113\}\left(129.5^{\circ}\right)$ and $\{114\}\left(141.1^{\circ}\right)$ twin boundaries. Reversely, the $\{114\}$ twin boundary can also be formed by tilting in the opposite direction by $38.9^{\circ}$, and further tilt in this direction forms $\{113\}\left(50.5^{\circ}\right),\{112\}\left(70.5^{\circ}\right)$ and $\{111\}\left(109.5^{\circ}\right)$ twin boundaries. Particularly, for $\{111\}$ and $\{112\}$ twins, they have the same tilt angle but in opposite directions. However, no matter which direction the unit cell is tilted to, the orientation relationship, as well as the misorientation angle, between the two unit cells is the same for the two interfaces. A more direct illustration of this is shown in Figure 5.4.


Figure 5.3 Four symmetric interfaces for DFT calculation: <110> \{111\}, <110> \{112\}, <110> \{113\} and <110> \{114\}.

In Figure 5.4(a) the formation of a series of symmetric interfaces through tilting along $<110>$ is plotted. With increasing tilt angle, the common planes between the two cubic unit cells change. For $38.9^{\circ}$ tilt angle, the common planes between two unit cells are $\{221\}$ and $\{114\}$, and for $141.1^{\circ}$ tilting, the orientation relationship stays the same, as well as the common planes. Similarly, for $50.5^{\circ}\left(129.5^{\circ}\right)$ tilting, the common planes are $\{332\}$ and $\{113\}$ and for $70.5^{\circ}\left(109.5^{\circ}\right)$ tilting the common planes are $\{111\}$ and $\{112\}$, indicating the orientation relationship between two cubic unit cells is symmetric along the tilt angle from $0^{\circ}$ to $180^{\circ}$, and the actual variation range is from $0^{\circ}$ to $90^{\circ}$. Moreover, for any tilt angle between $0^{\circ}$ and $90^{\circ}$, there are two sets of common planes that can give a coincident site lattice at the interface. For example, at $70.5^{\circ}$ tilt angle, $\{111\}$ and $\{112\}$ can both form symmetric interfaces with the same OR between two unit cells. From an energy perspective, the symmetric interfaces
usually have lower interfacial energy than the asymmetric ones, and between the two possible symmetric interfaces, the one with lower interfacial energy is favoured.

The interfacial energy of the symmetric boundaries along the $<110>$ tilt angle has been measured in previous literature [264], and the results are shown in Figure 5.4(b), together with the DFT calculation result from this work. The energy landscape is plotted with the interfaces chosen in two ways referred to Figure 5.4(a). As the first row of the unit cell wireframes tilts in Figure 5.4(a), the interfaces change from $\{221\},\{332\},\{111\},\{112\},\{113\}$ to $\{114\}$, and the top figure in Figure $5.4(b)$ plots the interfacial energy along this sequence. The blue marks refer to the DFT calculations from this work. As for the second row in Figure $5.4(\mathrm{a})$, the sequence is reversed from $\{114\}$ to $\{221\}$ with increasing tilt angle, and the corresponding energy trend is reversed too in the bottom figure in Figure 5.4(b). In Figure 5.4(c) the two energy curves in Figure 5.4(b) are superimposed and, for two possible symmetric interfaces at the same tile angle, the lower energy one is chosen to describe the energy landscape. Figure $5.4(\mathrm{~d})$ plots the energy landscape for the symmetric interfaces along the tilt angle varying from $0^{\circ}$ to $90^{\circ}$ from Figure 5.4(c). The two local energy minima correspond to the $50.5^{\circ}\{113\}$ twinning and $60^{\circ}\{111\}$. Note that for an FCC unit cell, $60^{\circ}$ rotation about a $\{111\}$ plane is the same as $70.5^{\circ}$ tilting along <110>, as will be shown later.


Figure 5.4 (a) Tilting an Al unit cell along $a<110>$ direction from $0^{\circ}$ to $180^{\circ}$, forming two symmetric interfaces at certain tilt angles: $\{221\}$ and $\{114\}$ at $38.9^{\circ}\left(141.1^{\circ}\right),\{332\}$ and $\{113\}$ at $50.5^{\circ}\left(129.5^{\circ}\right)$, $\{111\}$ and $\{112\}$ at $70.5^{\circ}\left(109.5^{\circ}\right)$. (b) Interfacial energy of the symmetric boundaries tilting along <110> from $0^{\circ}$ to $180^{\circ}$ in two ways of choosing the interface. The black curves are from Ref. [264] and the blue marks are from the DFT calculation in this study. (c) Superimposition of the two energy curves in (b), showing the interfacial energy for two possible symmetric interfaces from $0^{\circ}$ to $180^{\circ}$. (d) The lower interfacial energy comparing two possible interfaces from $0^{\circ}$ to $90^{\circ}$ in (c).

The interfacial energies of symmetric tilt boundaries in Mg have been calculated by DFT in previous work and those calculated values were used here (i.e. no DFT calculations were performed on Mg in this work). Figure 5.5(a) and (d) plot the tilt of the Mg unit cell along the $<1 \overline{1} 00>$ and $<11 \overline{2} 0>$ directions forming different common planes. For example, clockwise tilting along $<1 \overline{1} 00>$ by $56.9^{\circ}, 94.5^{\circ}, 116.8^{\circ}$ and $145.8^{\circ}$ gives parallel $\{11 \overline{2} 6\},\{11 \overline{2} 3\},\{11 \overline{2} 2\}$ and $\{11 \overline{2} 1\}$ planes, respectively. And the interfacial energy calculated by DFT [265] for the symmetric interfaces in Mg is plotted in Figure 5.5(b). Reversely, these four parallel planes can also be formed by anti-clockwise tilting $123.1^{\circ}, 85.5^{\circ}, 63.2^{\circ}$ and $34.2^{\circ}$, and the interfacial energy is also plotted reversely for such tilting in Figure 5.5(c). The same illustration
for tilting along the $<11 \overline{2} 0>$ direction and the calculated interfacial energy from previous literature [266, 267] are shown in Figure 5.5(d)-(f).


Figure 5.5 (a) Tilting of $M g$ unit cell along <1 $\overline{1} 00>$ direction from $0^{\circ}$ to $180^{\circ}$ in clockwise and anticlockwise directions, forming symmetric interfaces at certain tilt angles: \{11 $\overline{2} 6\}$ at $56.9^{\circ}\left(123.1^{\circ}\right)$, $\{11 \overline{2} 3\}$ at $94.5^{\circ}\left(85.5^{\circ}\right),\{11 \overline{2} 2\}$ at $116.8^{\circ}\left(63.2^{\circ}\right)$ and $\{11 \overline{2} 1\}$ at $145.8^{\circ}\left(34.2^{\circ}\right)$. (b) Interfacial energy of the symmetric boundaries tilting along $<1 \overline{1} 00\rangle$ direction from $0^{\circ}$ to $180^{\circ}$ in clockwise direction. (c) Interfacial energy of the symmetric boundaries tilting along <1100> direction from $0^{\circ}$ to $180^{\circ}$ in anticlockwise direction. (d) Tilting of Mg unit cell along $\langle 11 \overline{2} 0\rangle$ direction from $0^{\circ}$ to $180^{\circ}$ in clockwise and anti-clockwise directions, forming symmetric interfaces at certain tilt angles: \{1103\} at $64.0^{\circ}\left(116.0^{\circ}\right)$, $\{1 \overline{1} 02\}$ at $86.3^{\circ}\left(93.7^{\circ}\right),\{1 \overline{1} 01\}$ at $123.9^{\circ}\left(56.1^{\circ}\right)$ and $\{2 \overline{2} 01\}$ at $150.1^{\circ}\left(29.9^{\circ}\right)$. (e) Interfacial energy of the symmetric boundaries tilting along $\langle 11 \overline{2} 0\rangle$ direction from $0^{\circ}$ to $180^{\circ}$ in clockwise direction. (f) Interfacial energy of the symmetric boundaries tilting along $\langle 11 \overline{2} 0\rangle$ direction from $0^{\circ}$ to $180^{\circ}$ in anticlockwise direction.

Comparing Figure $5.5(\mathrm{~b})$ and (c) (or Figure $5.5(\mathrm{e})$ and (f)), there are two possible symmetric interfaces for any tilting angle from $0^{\circ}-90^{\circ}$. The lower part of the two energy curves is picked to describe the energy preference for different tilting angle, as shown in Figure 5.6(a) and (b). For tilting along the $<1 \overline{1} 00>$ direction, there are three local energy minima at $0^{\circ}, 34.2^{\circ}$ and $63.2^{\circ}$, the latter two corresponding to the $<1 \overline{1} 00>\{11 \overline{2} 1\}$ and $<1 \overline{1} 00>\{11 \overline{2} 2\}$ twins. For tilting along the $<11 \overline{2} 0>$ direction, there are five local energy minima at $0^{\circ}, 29.9^{\circ}, 56.1^{\circ}, 64.0^{\circ}$ and $86.3^{\circ}$, and the latter four correspond to the $<11 \overline{2} 0>\{2 \overline{2} 01\},<11 \overline{2} 0>\{1 \overline{1} 01\},<11 \overline{2} 0>\{1 \overline{1} 03\}$ and $<11 \overline{2} 0>\{1 \overline{1} 02\}$ twins, respectively.


Figure 5.6 The energy landscape of $M g$ symmetric interfaces tilting along (a) <1 $\overline{1} 00>$ direction and (b) $<11 \overline{2} 0>$ direction.

### 5.3 Results and discussion

### 5.3.1 FCC Al alloys

### 5.3.1.1 Preferred grain boundaries in cast Al alloys

Figure $5.7(\mathrm{a})$ shows a typical EBSD IPF-Z map of the cast Al-20Zn alloy. Only one phase (FCC $\alpha-\mathrm{Al}$ ) is measured and the grains are equiaxed with grain size between $300-400 \mu \mathrm{~m}$. Figure $5.7(\mathrm{~b})$ shows the misorientation frequency collected from 9 EBSD maps containing 4425 pairs of neighbouring $\alpha-\mathrm{Al}$ grains. The Mackenzie curve is also plotted in Figure 5.7(b) showing the ideal misorientation frequency for uniform untextured FCC crystals. Compared to the Mackenzie curve, there are some preferences at certain grain boundary angles in the cast alloy. Figure 5.7 (c) plots the frequency bars above the Mackenzie curve; it is clear that the preferred grain boundaries are at low angle $\left(10^{\circ}-20^{\circ}\right)$ and at $50^{\circ}-$ $60^{\circ}$.


Figure 5.7 The solidification texture of cast Al-20wt.\% Zn ((a)-(c)), Al-15wt.\% Cu ((d)-(f)) and Al-6wt.\% Cu with $1 \mathrm{wt} . \%$ Al-5Ti-1B ((g)-(i)). (a)(d)(g) EBSD IPF-Z map of $\alpha$-Al grains in (a) Al-20wt.\% Zn, (d) Al$15 w t . \% \mathrm{Cu}$ and (g) Al-6wt.\% Cu with 1 wt.\% Al-5Ti-1B. (b)(e)(h) Misorientation frequency at $\alpha$-Al grain boundaries superimposed with the Mackenzie curve for (b) Al-20wt.\% Zn, (e) reconstructed Al-15wt.\% Cu EBSD maps and (h) Al-6wt.\% Cu with 1 wt.\% Al-5Ti-1B. (c)(f)(i) The fraction bars above the Mackenzie curve in (b), (e) and (h).

Similar results were measured in cast $\mathrm{Al}-15 \mathrm{Cu}$ and $\mathrm{Al}-6 \mathrm{Cu}$ refined with $1 \mathrm{wt} . \% \mathrm{Al}-5 \mathrm{Ti}-\mathrm{B}$ master alloy, as shown in Figure 5.7(d)-(f) and (g)-(i). The data were collected from 3413 pairs of neighbouring $\alpha$-Al grains in $\mathrm{Al}-15 \mathrm{Cu}$ and 43972 pairs of neighbouring $\alpha-\mathrm{Al}$ in $\mathrm{Al}-6 \mathrm{Cu}$ with $1 \mathrm{wt} \% \mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ master alloy. Figure $5.7(\mathrm{~d})$ and $(\mathrm{g})$ are the EBSD IPF-Z maps for $\alpha$-Al grains in the two alloys. It is clear that significant grain refinement is achieved with the addition of the master alloy: for Al-15Cu the coarse $\alpha-\mathrm{Al}$ dendritic grains are about 500-700 $\mu \mathrm{m}$ and between the dendrite arms are filled with $\alpha-\mathrm{Al}+\theta-\mathrm{Al}_{2} \mathrm{Cu}$ eutectic, while for $\mathrm{Al}-6 \mathrm{Cu}$ cast alloy refined with $\mathrm{TiB}_{2}$, the $\alpha-\mathrm{Al}$ grains are around $70 \mu \mathrm{~m}$. For both $\mathrm{Al}-\mathrm{Cu}$ cast alloys there is a preference for low angle $\left(10^{\circ}-20^{\circ}\right)$ and $50^{\circ}-60^{\circ}$ boundaries compared to the Mackenzie curve, as shown in Figure $5.7(\mathrm{e})$-(f) and (h)-(i), similar to the measurements for cast Al20Zn.

Closer examination at the high angle boundaries in the three cast Al alloys revealed that many of them are consistent with twin boundaries. Two types of twinning are observed: $60^{\circ}\{111\}$ twins and $50.5^{\circ}$ $\{113\}$ twins. Figure 5.8 shows examples of the two types of twinning in Al-20Zn alloy. For the $60^{\circ}\{111\}$ twin, it is a $60^{\circ}$ rotation on the common $\{111\}$ plane forming three parallel $<110>$ directions in the common $\{111\}$ plane. For the $50.5^{\circ}\{113\}$ type of twin, it is $50.5^{\circ}$ rotation about the common <110> axis forming a common $\{113\}$ plane. The common planes and directions are highlighted in the measured pole figures and in the unit cell wireframes plotted from the Euler angles for the two types of twinning. The traces of the interface between the two grains in Figure 5.8(a) and (b) are nearly perpendicular to the common plane normal in the pole figures (highlighted in dotted lines), indicating that for the two types of twinning the interfaces are likely to be the common $\{111\}$ and $\{113\}$ planes, respectively.


Figure 5.8 Preferred boundaries with twinning orientation relationship. (a) IPF-X map of two $\alpha$-Al grains with $60^{\circ}\{111\}$ twinning. The common $\{111\}$ plane and three common $\langle 110>$ directions on the plane are marked in pole figures. The unit cell wireframes of the two orientations are plotted with the common \{111\} plane highlighted. (b) IPF-X map of two $\alpha-A l$ grains with $50.5^{\circ}\{113\}$ twin. The common \{113\} plane and common <110> direction on the plane are marked in pole figures. The unit cell wireframes of the two orientations are plotted.

### 5.3.1.2 Al grain clusters with icosahedral symmetry

In the three cast Al alloys, it was found that $60^{\circ}\{111\}$ twinning sometimes happened multiple times in adjacent grains. This was explored using the approach of Kurtuldu et al. [23, 24]. Figure 5.9 shows a typical example of multiple $60^{\circ}\{111\}$ twinning between five $\alpha$-Al grains from Al-20Zn. In Figure 5.9(a) five grains are labelled and coloured with respect to their Euler angles. There is a nearly common $\{111\}$ plane with three nearly common $<110>$ directions on the plane between $1 \& 2,2 \& 3,3 \& 4,4 \& 5$ and $5 \& 1$. All five orientations share a nearly common $\langle 110\rangle$ direction which is highlighted in the red triangle in Figure 5.9(b)-(f). Figure 5.9(g) plots the unit cell wireframes for the five orientations. In each of the cubic unit cells, there is a tetrahedron formed with $\{111\}$ being the faces and $<110>$ being the edges. Translating all five tetrahedra along the common $<110>$ direction with the five common $\{111\}$ planes between every two of them being the interfaces, a pentagonal bipyramid is formed with small gaps because the angle between two $\{111\}$ planes in a cubic unit cell is $70.5^{\circ}$ instead of $72^{\circ}$. Figure $5.9(\mathrm{~h})$ shows all five common $\{111\}$ planes form a fivefold symmetry in space, with the common <110> direction for all five orientations lying on the plane. The same fivefold symmetry was revealed between the equiaxed $\alpha$-Al grains in $\mathrm{Al}-20 \mathrm{Zn}-0.1 \mathrm{Cr}$ alloy by Kurtuldu [23]. Furthermore, from the pentagonal bipyramid in Figure $5.9(\mathrm{~g})$ it is clear to see that, between two Al unit cells, the $60^{\circ}\{111\}$ twin can also be seen as a $70.5^{\circ}$ rotation about the common $<110>$ direction.


Figure 5.9 Continuous $60^{\circ}\{111\}$ twin forming fivefold symmetry. (a) Five $\alpha-A l$ grains from Al-20wt. $\%$ Zn coloured according to their Euler angle. (b)-(f) Pole figures of every two of the five grains with $60^{\circ}$ $\{111\}$ twin. The common \{111\} plane and three common $\langle 110\rangle$ directions on the plane are marked. All five grains share a common <110> direction highlighted in the red triangle. (g) Five tetrahedra from the cubic unit cells of the five grains forming a pentagonal bipyramid with small gaps. The fivefold axis is the common [110] direction in the red triangles in (b)-(f). The interface between every two tetrahedra is the common \{111\} plane. (h) Pole figures of the common (111) planes and [110] directions forming combined fivefold symmetry.

The fivefold symmetry formed by the continuous $60^{\circ}\{111\}$ twinning was also observed in the two AlCu alloys. Figure 5.10 shows six $\alpha$-Al grains from $\mathrm{Al}-6 \mathrm{Cu}$ refined with $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ master alloy. There are five main orientations (the misorientation between 3 and $3^{\prime}$ is $11.9^{\circ}$ ) that have the $60^{\circ}$ twinning orientation relationship between every two of them. All five cubic unit cells share a nearly common <110> direction (highlighted in the triangles in (b)) and fivefold symmetry about this direction is formed with five nearly common $\{111\}$ planes between every two of the five orientations. Translating to align along the common <110> direction, all five tetrahedra extracted from the cubic unit cells form a pentagonal bipyramid with small gaps. Note that the colours in Figure 5.10(a) are manually chosen to separate different orientations without any meaningful indication of how the unit cells are oriented in space. The real orientations are indicated by the pole figures in Figure 5.10(b).


Figure 5.10 Continuous $60^{\circ}<110>\{111\}$ twinning of the refined $\alpha$-Al grains forming fivefold symmetry. (a) Five $\alpha$-Al grains from Al-6wt.\% Cu with 1 wt.\% Al-5Ti-1B refiner. (b) Pole figures of five $60^{\circ}<110>$ $\{111\}$ twinning. Five common \{111\} planes are marked. All five grains share a common $<110>$ direction highlighted by a triangle. (c) Five tetrahedra from the cubic unit cells of five grains forming a pentagonal bipyramid with certain gaps, with pole figures of the common (111) planes and [110] directions. Note that the colours in (a) are manually chosen to separate different orientations without any meaningful indication of how the unit cells are oriented in space. The real orientations are indicated by the pole figures in (b).

Figure 5.11 shows a more complicated situation with multiple fivefold axes formed by eight adjacent $\alpha$-Al grains in Al-15Cu cast alloy. Similar to Figure 5.10(a), the colours in Figure 5.11(a) are chosen to separate different orientations without any meaningful information about the real orientations. The Euler angles for the real orientations are marked in the Kikuchi patterns for all eight grains in Figure 5.11(b). Figure 5.11 (c) and (d) shows two fivefold axes formed by grain 1-5 and $4-8$ respectively. For each five-grain group, they share a nearly common [110] direction with five nearly common $\{111\}$ planes forming a fivefold symmetry about this direction. Similar to what was shown above, two pentagonal bipyramids can be constructed based on the five orientations in each group. Furthermore, the two pentagonal bipyramids are part of a full icosahedron and all eight tetrahedra can form a similar icosahedron with certain gaps between each other compared to a standard one with the same orientation, as shown in Figure 5.11(e). The OR between the FCC phase and the icosahedron is similar to Ref. [24]: one of the $\{111\}|\mid i(3)$ (the faces of the icosahedron) and three <110> || three $i(5)$ (the corners of the icosahedron),


Figure 5.11 Neighbouring $\alpha-A l$ dendrites with continuous $60^{\circ}<110>\{111\}$ twin forming icosahedron symmetry. (a) Eight $\alpha$-Al grains from Al-15wt.\% Cu. (b) Kikuchi patterns from the eight $\alpha$-Al grains with Euler angles marked at the bottom. (c) Pole figures of the common (111) planes and [110] directions of grains 1-5 forming combined fivefold symmetry, with the five tetrahedra forming a pentagonal bipyramid. (d) Pole figures of the common (111) planes and [110] directions of grains 4-8 forming combined fivefold symmetry, with the five tetrahedra forming a pentagonal bipyramid. (e) Two pentagonal bipyramids from (c) and (d) together with two extra tetrahedra forming an icosahedron with certain gaps, in comparison with a standard icosahedron with the same orientation.

In order to identify the clusters of local aluminium grains with combined icosahedral symmetry and study the prevalence of these grain clusters, an algorithm was developed using a MATLAB code within the MTEX toolbox to process the EBSD data. The basic principle of the algorithm is searching for all grain boundaries with the $60^{\circ}\{111\}$ twinning relationship ( $5^{\circ}$ tolerance for the $\{111\}$ common plane and three $<110>$ common directions in the common $\{111\}$ plane), filtering out the grain clusters containing more than 3 grains with the twinning boundaries, and identifying the parent icosahedron orientation. With that icosahedron orientation, all the grains contacting the cluster are then examined for the OR. The cluster keeps growing until all the grains contacting its boundary do not share the OR with the icosahedron orientation. One of the results obtained from the algorithm is shown in Figure 5.12. Figure 5.12(a) is the IPF-Z map of the $\alpha-\mathrm{Al}$ in $\mathrm{Al}-6 \mathrm{Cu}$ refined with $\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B}$ master alloy. In Figure 5.12(b) the AI clusters with icosahedral symmetry are highlighted with colour based on the IPF-Z colour scheme for the icosahedron symmetry. Figure 5.12 (c) and (d) show the colour scheme for $m \overline{3} m$ symmetry (including FCC) and $m \overline{3} \overline{5}$ icosahedral symmetry, respectively. In Figure 5.12(c) the inverse pole figure for FCC is constricted within the [001], [101] and [111] directions, and in Figure 5.12(d) the inverse pole figure for icosahedron symmetry is constricted by twofold, threefold and fivefold axes.

In Figure 5.12(c), there are 54 clusters formed by at least 3 neighbouring AI grains with icosahedral symmetry. According to the IPF-Z map, the icosahedrons have no preferred orientations and their distribution is also near-random in space. These clusters only contain less than $3 \%$ (224 out of 7646) of $\alpha$-Al grains in the whole map. Thus, while it was relatively easy to find $\alpha$-AI grain clusters related by
twin ORs and combined fivefold symmetry (e.g. Figure 5.10), they are rare when all grains are considered.

Kurtuldu et al. measured an above-random population of the $60^{\circ}\{111\}$ twin boundaries between equiaxed $\alpha$-Al grains in $\mathrm{Al}-20 \mathrm{wt} . \% \mathrm{Zn}$ alloy with $0.1 \mathrm{wt} . \% \mathrm{Cr}$ addition [23]. They proposed this was due to the formation of Cr-centred icosahedral quasicrystals (iQC) in the undercooled melt followed by the nucleation of $\alpha-A I$ on the iQC with multiple variants of the OR which produced a high amount of twin boundaries with fivefold symmetry. In the case of the three Al alloys studied here (Al-20Zn, $\mathrm{Al}-15 \mathrm{Cu}$, and $\mathrm{Al}-6 \mathrm{Cu}+\mathrm{Al}-5 \mathrm{Ti}-1 \mathrm{~B})$, it is unlikely that the preferred twin ORs measured between neighbouring $\alpha-$ Al grains are caused by nucleation on iQCs for the following reasons:
(i) Only a small proportion of grains, $\sim 3 \%$, belong to such grain clusters.
(ii) The above-random proportion of $50^{\circ}<111>\{113\}$ twin boundaries (Figure 5.7) cannot be explained by the nucleation of $\alpha-\mathrm{Al}$ on a simple icosahedron.
(iii) In the case of Al-6Cu refined with the Al-5Ti-B master alloy, the $\alpha$-Al nucleation mechanism is well established: heterogeneous nucleation occurs on $\mathrm{TiB}_{2}$ particles (or on an $\mathrm{Al}_{3} \mathrm{Ti}$ or similar layer on the $\mathrm{TiB}_{2}$ particles) at low undercooling.


Figure 5.12 Clusters of $\alpha$-Al equiaxed grains with icosahedron symmetry. (a) EBSD IPF-Z map of AI-6Cu with 1 wt.\% Al-5Ti-1B grain refiners containing $7646 \alpha$-Al grains. (c) Clusters of 3 or more $\alpha$-Al grains highlighted from (a) with icosahedron symmetry identified by the algorithm. The clusters are coloured according to the IPF-Z colour key of the icosahedron symmetry. (b) IPF colour key of AI with $m \overline{3} m$ symmetry. (d) IPF colour key of icosahedron with $m \overline{3} \overline{5}$ symmetry.

### 5.3.1.3 <110> tilt angle preference between equiaxed $\alpha$-Al grains

According to the DFT calculation in Figure 5.4(d), there are three local energy minima for tilt boundaries along <110> $\alpha-\mathrm{Al}: 0^{\circ}, 50.5^{\circ}$ and $70.5^{\circ}$ where the latter two correspond to $\{113\}$ and $\{111\}$ twins, respectively. In order to explore the preferred ORs between neighbouring $\alpha$-Al grains from an energy perspective, the comparison between the interfacial energy and the occurrence frequency of tilt angle along $<110>$ is shown in Figure 5.13. All grain boundaries with $<110>$ common axes between neighbouring $\alpha$-Al grains were examined for the three cast Al alloys. The deviation angle between the common <110> directions from two unit cells was set to be less than $5^{\circ}$. For the <110> tilt grain boundaries in the three cast alloys, there are three preferred tilt angles in Figure 5.13: low angle below $10^{\circ}, \sim 50^{\circ}$ and $\sim 70^{\circ}$. The three peaks are a good match to the three local interfacial energy minima. Figure 5.14 shows the comparison of the tilt angle frequency along $<110>$ between experimental (from Al-20Zn) and simulated untextured $\alpha-\mathrm{Al}$ orientations. The large simulated dataset contains $30584 \alpha-$ Al orientations with 89280 pairs of AI-Al neighbouring grains. There is barely any preference for a particular tilt angle in the simulation except the contrary to the experiment results: it is unlikely to form $60^{\circ}\{111\}$ twinning ORs between random orientations. All of these indicate that the tilting preference along $<110>$ in the cast Al alloys is likely to be attributed to the minimisation of interfacial energy.

According to the study of the solidification OR between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ in Chapter 3, second phase particles can rotate on the growth front to lower the interfacial energy. In the case of equiaxed solidification, 3D stochastic modelling has shown that grain movement can be activated by convection and sedimentation/buoyancy [268]. When two grains come into contact in the mushy zone, the formation of a stable solid-solid interface requires a new grain boundary to have lower energy than the two solid-liquid interfaces it replaces $\left(\gamma_{S-s}<2 \gamma_{S-L}\right)$ and contacting crystals that do not meet this criterion are expected to be separated by a liquid film [157, 158, 269]. Although the solid-liquid interfacial energy is anisotropic and is a function of temperature and interface composition [270], the typical S-L interfacial energy for Al is set to be $0.1 \mathrm{~J} / \mathrm{m}^{2}$ as in Ref.[157]. The simplified $2 \gamma_{S-L}$ value is
plotted as horizontal lines on Figure 5.13(a) and Figure 5.14(a), suggesting that only the solid-solid interfaces below the line would be stable and any other tilt angles would have a liquid film separating the grains. Therefore, it is possible that when grains are separated by liquid films, rotation may be relatively easy but, once rotation brings a pair of grains to a favourable orientation relationship (e.g. a $60^{\circ}\{111\}$ twin), they coalesce to form a grain boundary and further relative rotation becomes more difficult and less likely, so these grains become bonded together whereas other grains can keep rotating until they form a favourable OR with their neighbour. Due to the limited time available and the multiple competing neighbours around each grain, most grains will never reach a favourable OR with their neighbours, but the results indicate it is sufficiently common to give a significantly aboverandom proportion of special boundaries at the end of equiaxed solidification.


Figure 5.13 The occurrence frequency for $\alpha$-Al grain boundaries at various tilting angle along <110> for (a) Al-20wt.\% Zn, (b) Al-6wt.\% Cu with 1 wt.\% Al-5Ti-1B additions, (c) Al-15wt.\% Cu and (d) untextured simulation.


Figure 5.14 Comparison of the tilting frequency along <110> between experimental (Al-20Zn) and simulated untextured $\alpha-A l$ orientations

### 5.3.2 HCP Mg alloys

### 5.3.2.1 Preferred grain boundaries in cast Mg alloys

Between equiaxed HCP Mg grains, there were also preferred misorientations at certain angles. Figure 5.15 shows such grain boundary preference for two cast Mg-9wt.\%Al-0.7wt.\%Zn alloys refined with the addition of $\mathrm{FeCl}_{3}$ and $\mathrm{Al}_{4} \mathrm{C}_{3}$. From the IPF-Z map plotted by MTEX in Figure $5.15(\mathrm{a})$ and (d), the Mg grains are equiaxed in both alloys. Certain grain boundaries are preferred in the misorientation frequency histograms superimposed with the Mackenzie curve (Figure $5.15(b)$ and (e)). Such preference is more obvious after subtracting the Mackenzie curve, as shown in Figure 5.15(c) and (f). Compared to the random uniform texture, the $\mathrm{Mg}-\mathrm{Mg}$ grain boundaries at low angle ( $\sim 10^{\circ}$ ), $\sim 30^{\circ}, \sim 60^{\circ}$ and $\sim 90^{\circ}$ have higher frequency in $\mathrm{Mg}-9 \mathrm{Al}-0.7 \mathrm{Zn}$ alloys with both refiners.


Figure 5.15 The solidification texture of cast Mg-9Al-0.7Zn with $\mathrm{FeCl}_{3}((a)-(c))$ and $\mathrm{Al}_{4} \mathrm{C}_{3}((d)-(f))$. (a)(d) EBSD IPF-Z map of cast Mg-9Al-0.7Zn with (a) $\mathrm{FeCl}_{3}$ and (d) $\mathrm{Al}_{4} \mathrm{C}_{3}$. (b) (e) Misorientation frequency at $\alpha$ Mg grain boundaries superimposed with the Mackenzie curve for Mg-9Al-0.7Zn with (b) $\mathrm{FeCl}_{3}$ and (e) $\mathrm{Al}_{4} \mathrm{C}_{3}$. (c)(f) The misorientation fraction above the Mackenzie curve in (b) and (e).

With closer examination of the grain boundaries at the preferred angles, it was found that most of the preferred misorientation angles are associated with twin orientation relationships in HCP alloys. For example, Figure $5.16(\mathrm{a})$ and (b) show the $34^{\circ}<1 \overline{1} 00>\{11 \overline{2} 1\}$ twin and the $63^{\circ}<1 \overline{1} 00>\{11 \overline{2} 2\}$ twin, and Figure 5.16 (c) and (d) show the $86^{\circ}<1 \overline{2} 10>\{10 \overline{1} 2\}$ twin and the $56^{\circ}<1 \overline{2} 10>\{10 \overline{1} 1\}$ twin. All $\alpha-\mathrm{Mg}$ grains in Figure 5.16 are coloured with respect to the IPF-Y colour scheme. In Figure 5.16(a) two hexagonal unit cells share a common $<1 \overline{1} 00>$ axis and a common $\{11 \overline{2} 1\}$ plane. The trace of the interface between these two grains is nearly perpendicular to the plane normal of the common $\{11 \overline{2} 1\}$, indicating that the interface is likely to be the common $\{11 \overline{2} 1\}$ plane. The same match has also been found between the trace of interface in the EBSD map and the common plane normal in the pole figures in Figure 5.16(b) and (d), indicating the interfaces between the $\alpha-\mathrm{Mg}$ grains are likely to be the common plane. In Figure 5.16(c) the interface between the two grains comprises multiple crystallographic planes, and part of the interface is likely to be the common $\{10 \overline{1} 2\}$ plane. It can also be seen in Figure 5.16 that, although most of the interfaces with the twinned orientation relationships are likely to be the common planes, the $\alpha-\mathrm{Mg}$ grains do not have simple straight grain boundaries which will unavoidably form interfaces with other crystallographic planes as well.


Figure 5.16 Preferred boundaries with twinning orientation relationship in Mg-9Al-0.7Zn. The twin axes are <1 $\overline{1} 00>((a)$ and (b)) and $<1 \overline{1} \overline{2} 0>((c)$ and (d)), respectively. Four types of twin orientation relationships are plotted: (a) $34^{\circ}<1 \overline{1} 00>\{11 \overline{2} 1\}$ twin, (b) $63^{\circ}<1 \overline{1} 00>\{11 \overline{2} 2\}$ twin, (c) $86^{\circ}<11 \overline{2} 0>\{1 \overline{1} 02\}$ twin and (d) $56^{\circ}<11 \overline{2} 0>\{1 \overline{1} 01\}$ twin. The common directions and planes are marked in pole figures. The grains are plotted by EBSD IPF-Y map and unit cell wireframes are plotted based on the Euler angle.

### 5.3.2.2 Mg grain clusters with combined icosahedron symmetry

Similar to $\alpha-A I$, the local $\alpha-\mathrm{Mg}$ grains may form a combined icosahedron symmetry. However, unlike the simple OR between $\alpha$-Al and the icosahedron, according to Singh et al. [156], 5 ORs have been measured between $\alpha-\mathrm{Mg}$ and icosahedral quasicrystals. Figure 5.17 shows an example where five Mg orientations (the misorientation between grain 2 and $2^{\prime}$ is $1.97^{\circ}$ ) with continuous $34^{\circ}<1 \overline{1} 00>\{11 \overline{2} 1\}$ twins form a fivefold symmetry, and all five orientations share the same OR to an icosahedron orientation. However, grain 1 and $2^{\prime}$ do not share any grain boundary with the other four grains. In Figure $5.17(b)$ all five orientations share a nearly common $\{1 \overline{1} 00\}$ plane, and the plane normal is parallel to one of the six $i(5)$ of an icosahedron. Five basal planes are nearly at $36^{\circ}$ to each other and parallel to the five $i(2)$ which are all perpendicular to the $i(5)$. Therefore, the OR can be written as: $\{0001\}|\mid i(2)$ with one of the $\{1 \overline{1} 00\}| \mid i(5)$ (OR2 in Ref. [156]). Figure 5.17(c) illustrates such ORs between the five hexagonal unit cells and a rhombic triacontahedron which is one of the polyhedrons with icosahedral symmetry. In the rhombic triacontahedron, the plane normals of all faces are $i(2)$ and the vectors from the centre to the corners are $i(3)$ or $i(5)$. The colours in Figure 5.17(a) do not contain any meaningful information of how the unit cells are oriented in space. The real orientations are indicated by the unit cell wireframes in Figure 5.17(c).


Figure 5.17 Continuous <1 $\overline{1} 00>\{11 \overline{2} 1\}$ twin forming fivefold symmetry. (a) Six $\alpha-M g$ grains with five main orientations in Mg-9AI-0.7Zn. (b) \{0001\} and <1 $\overline{1} 00>$ pole figures of the five orientations. Between every two of them it is $34^{\circ}$ rotation along the common <1 $\overline{1} 00>$. Pole figures of $i(2)$ and $i(5)$ of a standard icosahedron are also plotted, with a simple OR to the $\alpha-M g$ : $\{0001\}$ || i(2) with two $\{1 \overline{1} 00\}$ I/ i(5). (c) Five hexagonal unit cells with their basal plane parallel to five facets of a rhombic triacontahedron, and the common \{1100\} parallel to an i(5). Note that the colours in (a) are manually chosen to separate different orientations without any meaningful information of how the unit cells are oriented in space. The real orientations are indicated by the unit cell wireframes in (c).

Similarly, other twinned neighbouring $\alpha-\mathrm{Mg}$ grains can also be translated into icosahedral symmetry, but it requires Mg grains to have different ORs to the icosahedron. Because of the high symmetry of an icosahedron and in total 48 variants of the 50Rs, it is difficult to identify the relevant grain clusters considering a random Mg orientation could potentially be in one of the 5 reported ORs to the icosahedron.

Similar to the AI-6Cu inoculated with $\mathrm{TiB}_{2}$ particles, for $\mathrm{Mg}-9 \mathrm{Al}-0.7 \mathrm{Zn}$ refined with $\mathrm{Al}_{4} \mathrm{C}_{3}$ particles it is commonly acknowledged that HCP $\alpha-\mathrm{Mg}$ nucleates heterogeneously on carbides, which indicates that the measured solidification ORs between neighbouring $\alpha-\mathrm{Mg}$ grains is unlikely to be caused by nucleation on an iQC. Similarly, although the nucleation mechanism for the Elfinal process (Mg-9AI0.7 Zn refined with $\mathrm{FeCl}_{3}$ ) remains unknown, the fact that it shows the same preference as $\mathrm{Mg}-9 \mathrm{Al}-$ 0.7 Zn refined with $\mathrm{Al}_{4} \mathrm{C}_{3}$ additions indicates such preferred solidification ORs are also unlikely to be caused by nucleation on iQC.

### 5.3.2.3 $<1 \overline{1} 00>$ and $<11 \overline{2} 0>$ tilt angle preference between equiaxed $\alpha-\mathrm{Mg}$ grains

The tilt angle preference was investigated between $\alpha-\mathrm{Mg}$ grains along <1 $\overline{1} 00>$ and $<11 \overline{2} 0>$ directions. For tilting along $<1 \overline{1} 00>$ directions, there are three local energy minima at $0^{\circ}, 34.2^{\circ}$ and $63.2^{\circ}$ (Figure 5.6), the latter two corresponding to $<1 \overline{1} 00>\{11 \overline{2} 1\}$ and $<1 \overline{1} 00>\{11 \overline{2} 2\}$ twins. After examining the grain boundaries between equiaxed $\alpha-\mathrm{Mg}$ grains in cast $\mathrm{Mg}-9 \mathrm{Al}-0.7 \mathrm{Zn}$ with $\mathrm{FeCl}_{3}$ and $\mathrm{Al}_{4} \mathrm{C}_{3}$ additions, the occurrence frequency of different tilt angles along the common <1 $\overline{1} 00>$ (deviation angle is set to be less than $5^{\circ}$ ) is shown in Figure $5.18(\mathrm{~b})$ and (c). There are three preferred tilt boundaries along $<1 \overline{1} 00>$ at (i) low angles less than $10^{\circ}$, (ii) near $34^{\circ}$ and (iii) near $63^{\circ}$, which is a good match to the calculated energy preference.

For tilting along $<11 \overline{2} 0>$ direction, there are five local energy minima at $0^{\circ}, 29.9^{\circ}, 56.1^{\circ}, 64.0^{\circ}$ and $86.3^{\circ}$ (Figure 5.6), and the latter four correspond to the $<11 \overline{2} 0>\{2 \overline{2} 01\},<11 \overline{2} 0>\{1 \overline{1} 01\},<11 \overline{2} 0>\{1 \overline{1} 03\}$ and $<11 \overline{2} 0>\{1 \overline{1} 02\}$ twins, respectively. The five local energy minima also match the occurrence frequency of the tilting angle along $<11 \overline{2} 0>$ for both cast Mg-9Al-0.7Zn alloys, as shown in Figure 5.18(d)-(f).

As discussed in section 5.3.1.3, grain interaction and movement are likely to happen between $\alpha-\mathrm{Mg}$ grains during equiaxed solidification to optimise interface. Here for two cast Mg alloys, the good match between the occurrence frequency of tilt grain boundaries along $\langle 1 \overline{1} 00>$ and $<11 \overline{2} 0\rangle$ directions and their interfacial energy preference indicates that $\alpha-\mathrm{Mg}$ grains in the two cast alloys are also likely to move during solidification to optimise their interface. The calculated solid-liquid interfacial energy for $\mathrm{Mg}\{0001\},\{1 \overline{1} 00\}$ and $\{11 \overline{2} 0\}$ planes are $88.4,90.1,90.8 \mathrm{~mJ} / \mathrm{m}^{2}$ [271], indicating the anisotropic range for the $\gamma_{S-L}$ of HCP Mg is relatively small compared to faceted crystals [270]. The $\gamma_{S-L}$ value for Mg is set to be $0.09 \mathrm{~J} / \mathrm{m}^{2}$ and $2 \gamma_{S-L}$ is plotted as horizontal lines in Figure $5.18(\mathrm{a})$ and (d). Similar to $\alpha-\mathrm{Al}$, when two Mg grains come into contact with an OR below the horizontal line, then a solid-solid interface is favoured to replace the two solid-liquid interfaces. Otherwise there will be a thin liquid film between the neighbouring grains and rotation is likely to happen to reach an OR with local energy minima. Consequently, a significantly above-random proportion of special boundaries forms at the end of equiaxed solidification.

Therefore, for the special twinning ORs between neighbouring grains produced by grain movement and rotation in cast Al and Mg alloys, it is geometrically possible to form icosahedral symmetry without any iQC-mediated nucleation occurring. These two mechanisms can both lead to grain clusters with the same icosahedral symmetry. Hence, it requires extra caution than simple grain boundary examination to differentiate between grain clusters nucleating from iQC and grain clusters formed by movement and rotation to minimise the interfacial energy.


Figure 5.18 The interfacial energy and occurrence frequency for $\alpha-M g$ grain boundaries at various tilting angle along $\langle 1 \overline{1} 00\rangle$ (a)-(c) and $\langle 11 \overline{2} 0\rangle$ (d)-(f). (a) The interfacial energy tilting from $0^{\circ}$ to $90^{\circ}$ along <1100>. (b)-(c) The occurrence frequency of various tilting angle along <1 $\overline{1} 00>$ for Mg-9Al-0.7Zn with $\mathrm{FeCl}_{3}(b)$ and $\mathrm{Al}_{4} \mathrm{C}_{3}$ (c) additions. (d) The interfacial energy tilting from $0^{\circ}$ to $90^{\circ}$ along $<11 \overline{2} 0>$. (e)(f) The occurrence frequency of various tilting angle along $<11 \overline{2} 0>$ for $\mathrm{Mg}-9 \mathrm{Al}-0.7 \mathrm{Zn}$ with $\mathrm{FeCl}_{3}(e)$ and $\mathrm{Al}_{4} \mathrm{C}_{3}(f)$ additions.

### 5.4 Conclusions

A study of the solidification texture of (i) equiaxed $\alpha$-Al grains in three cast Al alloys and (ii) equiaxed $\alpha-\mathrm{Mg}$ grains in $\mathrm{Mg}-9 \mathrm{Al}-0.7 \mathrm{Zn}$ cast with two grain refiner additions has been conducted, combining experiment (EBSD) and simulation (DFT calculations). The main conclusions can be drawn as follows:

- For equiaxed $\alpha-A l$ grains with different shape (globular and dendritic) and size (coarse and refined), there is a significant above-random proportion of grain boundaries with misorientation at $10^{\circ}$ to $20^{\circ}$ and $50^{\circ}$ to $60^{\circ}$.
- For equiaxed $\alpha-\mathrm{Mg}$ grains refined with $\mathrm{FeCl}_{3}$ and $\mathrm{Al}_{4} \mathrm{C}_{3}$, there is a significant above-random proportion of grain boundaries at around $10^{\circ}, 30^{\circ}, 60^{\circ}$ and $90^{\circ}$.
- Clusters of grains with twin boundaries were observed in both cast Al and Mg alloys forming fivefold symmetry in space. Clusters of $\alpha$-Al grains with icosahedron symmetry were identified with a simple OR (\{111\} || i(3) with three <110> || i(5)).
- Through DFT calculation the preferred boundaries with the observed twinning ORs correspond to local interfacial energy minima for both FCC $(\mathrm{Al})$ and $\mathrm{HCP}(\mathrm{Mg})$ structures.
- There are two possible coherent interfaces when tilting along the certain directions (<110> for Al and $<1 \overline{1} 00>$ and $<11 \overline{2} 0>$ for Mg ). Although the exact interface between two grains was not identified in this work, statistical EBSD data treatment and local twinned grain morphologies showed that the lower energy interface is likely to form.
- The tilting preference obtained from large EBSD datasets gives a good match to the theoretically calculated interfacial energy minima. It is likely that the preferred special grain boundaries are formed due to the interaction and movement of grains in the mushy zone to lower the interfacial energy.
- More broadly, during equiaxed solidification, grains are likely to rotate when they contact each other and optimise their interface, forming a solidification texture with a preference for low energy interface orientations instead of being totally random.
- It has been found here that clusters of grains related to each other with icosahedral symmetry exist even in Al alloys cast with Al-5Ti-1B grain refiner where nucleation almost certainly occurred on $\mathrm{TiB}_{2}$ rather than on an iQC . This geometrical situation is likely to occur when there is an above-random proportion of low energy grain boundaries. This highlights the difficulty in differentiating between grain clusters coming from iQC-mediated nucleation and grain clusters formed by grain rotation to minimise interfacial energy.


## Chapter 6 Conclusions and future work

### 6.1 Conclusions

This thesis has developed a deeper understanding of the formation mechanisms of preferred orientation relationships during alloy solidification. Two main mechanisms were identified. Mechanism (i) involves ORs formed by heterogeneous nucleation on either intentionally added nucleant particles such as $\mathrm{Al}_{3} \mathrm{Ti}$ on $\mathrm{TiB}_{2}$ in Chapter 3, or on metastable precursor phases that led to cyclic twin ORs between the variants of $\mathrm{Al}_{3} \mathrm{Ti}, \mathrm{Ag}_{3} \mathrm{Sn}, \mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ in Chapter 4. Mechanism (ii) involves the movement and rotations between two contacting grains/particles to lower the interfacial energy. This included ORs created by pushing and engulfment between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ in Chapter 3, and preferred twin ORs between equiaxed neighbouring grains with both FCC and HCP crystal structures in Chapter 5.

There is intensive ongoing research into the grain refinement of alloys by inoculant additions that contain growth restricting solute and numerous heterogeneous nucleant particles. There can be more than one OR formed between growing crystals and nucleants, and multiple mechanisms can generate ORs during solidification, making it difficult to assign each orientation relationship to a formation mechanism. In this work new approaches were developed to link ORs to their formation mechanism using a model system ( $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ ). Three reproducible ORs were explored between $\mathrm{Al}_{3} \mathrm{Ti}$ and $\mathrm{TiB}_{2}$ and they were formed by nucleation and pushing \& engulfment processes:

$$
\begin{align*}
& \{112\}_{\mathrm{Al3Ti}} \|\{0001\}_{\mathrm{TiB2} 2} \text { with }<\overline{2} 01>_{\mathrm{Al} 3 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB} 2}  \tag{OR1}\\
& \{001\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB2} 2} \text { with }<110>_{\mathrm{A} 13 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB} 2}  \tag{OR2}\\
& \{100\}_{\mathrm{Al} 3 \mathrm{Ti}} \|\{0001\}_{\mathrm{TiB2} 2} \text { with }<010>_{\mathrm{A} \mid 3 \mathrm{Ti}} \|<11 \overline{2} 0>_{\mathrm{TiB} 2} \tag{OR3}
\end{align*}
$$

The nucleation OR was identified by growing a relatively large $\mathrm{TiB}_{2}$ crystal and solidifying multiple small $\mathrm{Al}_{3} \mathrm{Ti}$ crystals on one (0001) facet of $\mathrm{TiB}_{2}$. Pushing and engulfment ORs were investigated by statistical analysis of EBSD measurements, density functional theory (DFT) calculations of interface energies, and
imaging of cross-sections of $\mathrm{TiB}_{2}$ particles being pushed and engulfed by $\mathrm{Al}_{3}$ Ti facets. The lowest energy OR was formed by nucleation as well as by pushing/engulfment. The higher energy ORs, formed by pushing and engulfment, correspond to local interfacial energy minima and can be explained by rotation of $\mathrm{TiB}_{2}$ particles on $\mathrm{Al}_{3} \mathrm{Ti}$ facets during pushing.

To date a wide range of studies on growth twinning of various crystals have been reported. In this work, four IMCs were chosen that are related to different parent structures to study their twinning behaviour and the effect of cooling rate on the formation of multiple twinning ORs during solidification: $\mathrm{DO}_{22}-\mathrm{Al}_{3} \mathrm{Ti}$, a tetragonal superstructure derived from $\mathrm{FCC} ; \mathrm{DO}_{\mathrm{a}}-\mathrm{Ag}_{3} \mathrm{Sn}$, an orthorhombic superstructure derived from HCP; monoclinic $\mathrm{Al}_{45} \mathrm{Cr}_{7}$, an icosahedral quasicrystal approximant; and monoclinic $\mathrm{Al}_{13} \mathrm{Fe}_{4}$, a decagonal quasicrystal approximant. It was found that these IMCs tend to grow into large single crystal plates $\left(\mathrm{Al}_{3} \mathrm{Ti}\right.$ and $\left.\mathrm{Ag}_{3} \mathrm{Sn}\right)$ and rods $\left(\mathrm{Al}_{45} \mathrm{Cr}_{7}\right.$ and $\left.\mathrm{Al}_{13} \mathrm{Fe}_{4}\right)$ at slow cooling rate. Twinned $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ and $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ crystals were also observed at slow cooling with up to 4 and 2 orientations, respectively. Twin boundaries were found to be commonly coincident with edges and re-entrant corners which gives growth advantage to attain the final twin form. More twinned orientations in the four IMCs were obtained with additional twin types (for $\mathrm{Al}_{13} \mathrm{Fe}_{4}$ ) at higher cooling rate. It is believed that the deeper undercooling induced by higher cooling rate favours the nucleation of metastable phases and/or the formation of short-range order with high symmetry in melt, which then nucleated/transformed into stable phases with all orientation variants. The cyclic twin ORs between the stable IMC variants form combined symmetry of their corresponding parent structure, and the ORs between the stable IMCs and their corresponding parent structure are:

$$
\begin{aligned}
& \mathrm{Al}_{3} \mathrm{Ti}:\{001\}_{\mathrm{Al} 3 \mathrm{Ti}}| |\{001\}_{\text {ccp }} \text {, with }\langle 100\rangle_{\mathrm{Al} 3 \mathrm{Ti}}| |\langle 100\rangle_{\text {ccp }} ; \\
& \mathrm{Ag}_{3} \mathrm{Sn}:\{001\}_{\mathrm{Ag} 3 \mathrm{~S}}| |\left\{1 \overline{1}^{0} 00\right\}_{\mathrm{hcp}}, \text { with }\left\langle 100>_{\mathrm{Ag} 3 \mathrm{~S}}\right||<0001\rangle_{\mathrm{hcp}} ; \\
& \mathrm{Al}_{45} \mathrm{Cr}_{7}:<101>_{\mathrm{A} \mid 45 \mathrm{Cr} 7}| | i(5) \text { and }<110>_{\mathrm{Al} 45 \mathrm{Cr} 7}| | i(2) ; \\
& \left.\mathrm{Al}_{13} \mathrm{Fe}_{4}:<010\right\rangle_{\text {Al13Fe4 }}| | d(10) \text {, and }\langle 001\rangle_{\text {Al13Fe4 }}| | d(2) \text {. }
\end{aligned}
$$

In past work, it has been reported that the nucleation of FCC phases from icosahedral quasicrystals formed in undercooled melt can produce a significantly above-random population of $60^{\circ}$ twinning grain boundaries in the FCC phase, forming overall icosahedral symmetry after equiaxed solidification. In this work, with the combination of EBSD analysis and DFT calculation, the formation mechanisms for the preferred grain boundaries with special twin ORs between equiaxed neighbouring grains in both FCC $(\alpha-\mathrm{Al})$ and HCP phases $(\alpha-\mathrm{Mg})$ were identified. A significant above-random proportion of $60^{\circ}$ $\{111\}$ and $50.5^{\circ}\{113\}$ twin ORs between neighbouring FCC Al grains were found and clusters of Al grains with multiple $60^{\circ}\{111\}$ twins forming similar icosahedral symmetry were identified. The OR between the FCC AI grains cluster and an icosahedron is the same as the reported nucleation OR between FCC and iQC:
$\{111\}_{\mathrm{AI}}| | i(3)$ with three in-plane $\left\langle 110>_{\mathrm{Al}}\right| \mid i(5)$

However, such clusters only contain a small proportion ( $\sim 3 \%$ ) of $\alpha$-Al grains and the $50.5^{\circ}\{113\}$ twins cannot be produced from this simple icosahedron OR. Furthermore, in the case of $\mathrm{Al}-6 \mathrm{Cu}$ refined with the Al-5Ti-B master alloy, the nucleation mechanism is well established: heterogeneous nucleation occurs on $\mathrm{TiB}_{2}$ particles (or on an $\mathrm{Al}_{3} \mathrm{Ti}$ or similar layer on the $\mathrm{TiB}_{2}$ particles) at low undercooling. Similarly, an above-random population of $34^{\circ}<1 \overline{1} 00>\{11 \overline{2} 1\}$ twin, $63^{\circ}<1 \overline{1} 00>\{11 \overline{2} 2\}$ twin, $86^{\circ}<1 \overline{2} 10>$ $\{10 \overline{1} 2\}$ twin and $56^{\circ}<1 \overline{2} 10>\{10 \overline{1} 1\}$ twin between neighbouring grains were observed in HCP Mg with known inoculants (carbides) and clusters of Mg grains with multiple twins can also form local icosahedral symmetry with 5 different ORs to the icosahedron. This shows that the above-random proportion of low energy interfaces is not specific to FCC alloys but also occurs for HCP and, for both FCC and HCP, an above random proportion of twin ORs generates clusters of grains with pseudoicosahedral symmetry. Therefore, it is likely that the measured icosahedral symmetry was formed by the mechanisms that minimise the interfacial energy such as rotation towards low-energy twinned ORs instead of nucleation from iQC. Close examination revealed a good match between the measured tilt angle preference and calculated interfacial energy for both FCC AI and HCP Mg. This interpretation
was further supported by Chapter 3 showing that $\mathrm{TiB}_{2}$ can rotate on an $\mathrm{Al}_{3} \mathrm{Ti}$ growth front to lower the interfacial energy, and previous 3D stochastic modelling that has shown that grain movement can be activated by convection and sedimentation/buoyancy. It is likely that grains can move and rotate to optimise interfaces in the mushy zone and form a significantly above-random proportion of special boundaries at the end of equiaxed solidification. This work also highlights the difficulty in differentiating between grain clusters coming from iQC-mediated nucleation and grain clusters formed by grain rotation to minimise interfacial energy.

### 6.2 Suggestions for future work

This thesis as a whole studied the broad question of the formation mechanisms of solidification orientation relationships in $\mathrm{Al}, \mathrm{Sn}$ and Mg alloys. In order to explore this further, the following future work is recommended:

## In-situ Synchrotron X-ray Experiments

For detailed observation of the nucleation and subsequent growth of IMCs from metastable phases, and the movement and rotation of neighbouring grains in the mushy zone, synchrotron X-ray tomography combined with in-situ X-ray diffraction could provide useful information about the structure of metastable phases, crystal growth and the misorientation changes between contacting grains. This would require further advances in the time resolution of diffraction tomography experiments that are likely to be feasible within a few years.

## iQC-mediated nucleation of IMCs and FCC phases

In order to further explore the iQC-mediated nucleation, it is worth to consider other Al alloys and other FCC systems (Au, Ag etc.) which have the potential for formation of icosahedral quasicrystals and/or icosahedral short-range order. By comparing the FCC phase from iQC mediated nucleation with FCC-Al from movement and rotations during/after equiaxed solidification, useful information can be
gained in terms of differentiating these two formation mechanisms since both of them can produce an above-random proportion of $60^{\circ}\{111\}$ twin ORs between neighbouring FCC grains.

As for the cyclic twinned IMCs nucleating/transforming from icosahedral quasicrystals and/or icosahedral short-range order in the melt, the findings in this thesis with $\mathrm{Al}_{45} \mathrm{Cr}_{7}$ could potentially be applied into other systems. For example, $\alpha-\mathrm{Al}_{15}\left(\mathrm{Mn}, \mathrm{Fe}_{3}\right)_{3} \mathrm{Si}_{2}$ is often the primary IMC phase in the commonly used $\mathrm{Al}-\mathrm{Si}-\mathrm{Fe}-\mathrm{Mn}$ alloys and, similar to $\mathrm{Al}_{45} \mathrm{Cr}_{7}$, it contains Mn -centred icosahedral building blocks in its unit cell. Favouring and/or stabilising the formation of icosahedral quasicrystals and/or icosahedral short-range order could potentially be used to trigger more nucleation events and lower the size of $\alpha-\mathrm{Al}_{15}\left(\mathrm{Mn}, \mathrm{Fe}_{3}\right)_{3} \mathrm{Si}_{2}$, or cyclic twinning could be used to generate a more compact growth form, both of which could make this phase less deleterious to tensile ductility.

## Nucleation of $\beta$-Sn on metastable HCP structure

Similar to $\mathrm{Ag}_{3} \mathrm{Sn}$, cyclic twinning often has been observed in $\beta$-Sn forming combined hexagonal symmetry. The twinned domains appear to come out (i) from one nucleation event ('beach ball' structure) or (ii) solid state transformation ('interlacing' twin). It may be worth exploring if there is any evidence of a metastable phase forming before $\beta$-Sn nucleation, and how to stabilise the metastable phase for further examination. There is a known stable hexagonal phase at the Sn -rich side in Sn -In and $\mathrm{Sn}-\mathrm{Hg}$ phase diagram, so the addition of In may be a good option for further study.

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